Ultrafast Nonlinear Spectroscopy of Semiconducting Carbon Nanotubes

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by

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Abstract

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by

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Single-walled carbon nanotubes (SWNTs) are often considered the prototypical nanomaterial with their characteristic large aspect ratios, high tensile strength and size tunable physical properties. While their remarkable electrical and mechanical properties have been well studied, the optical properties of semiconducting SWNTs are continuously emerging with recently reported developments such as greatly enhanced fluorescence yields and highly efficient nanotube photodiodes. The scope of optoelectronic applications for SWNTs depends critically on a detailed understanding of their highly congested absorption features consisting of strongly bound excitonic ($E_{11}$, $E_{22}$, etc.), vibronic and dark state transitions. Until recently, carbon nanotubes consisted of highly inhomogeneous distributions of tube types that made advanced spectroscopic studies impractical. Enabled by samples highly enriched in specific tube types, we investigate carbon nanotubes photophysics in real-time by applying a wide range of techniques including transient absorption, photon echo and 2D Fourier transform spectroscopy. Through detailed analysis and simulation of these femtosecond nonlinear results, fundamental properties concerning excitonic structure, exciton-phonon interactions, and the dynamics of coherent excitons for these quasi one-dimensional nanomaterials are revealed.

Population relaxation dynamics in SWNTs are probed from the visible to mid-infrared regions using transient absorption or grating spectroscopy. Measurements in mid-IR region reveal a broad excited state absorption feature consistent with previously unobserved intra-excitonic transitions and bound vibrational states. Simulation of visible and near-IR transient absorption results suggest efficient exciton-exciton annihilation occurring by both one-dimensional diffusion or delocalized overlap of coherent excitons depending upon the timescale, state transitions, or temperature investigated (4.4 to 292 K). Throughout all the measurements reported, strong contributions from exciton-exciton scattering processes are evident.

The timescales for pure optical dephasing (and the corresponding homogeneous lineshape) were obtained through photon echo measurements. Surprisingly long room temperature dephasing times of 285 fs are reported, suggesting unusually weak exciton-phonon coupling and an inhomogeneously broadened absorption lineshape. At lower temperatures
the dephasing induced by SWNT optical phonons is mitigated, and we show how acoustic phonon processes and environmental disorder determines the absorption line-shape properties.

Professor Graham R. Fleming
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Selected publication references can be found in the headers of the dissertation chapters.
Chapter 1

Introduction

1.1 Background and Motivation

Figure 1.1. Schematic of a single-walled carbon nanotube with multiple optical excitations, highlighting the large length to width aspect ratio.

In 1991, Iijima et al. reported discovery of a cylindrical formation of carbon atoms whose physical structure spanned the molecular and crystalline divide. Quickly rising to forefront of nanomaterials research, carbon nanotubes continue to drive an expanding array of novel applications in diverse fields ranging from mechanical engineering to medical biology.

Nanotechnology exploits the novel material properties which arise when bulk condensed matter systems are shrunk down to small dimensions. With an unprecedented aspect ratio (see figure 1.1) that can exceed $10^7$, single-walled carbon nanotubes (SWNTs) behave as a one-dimensional (1D) material, possessing molecular-like confinement effects along the circumferential direction, and bulk-crystalline transport properties along the axial
coordinate. When these properties are combined, ubiquitous carbon atoms are transformed into a material which is more conductive than copper, stronger than steel and optically darker than our blackest absorbers.

Application oriented interest in nanotubes predates their discovery; for decades carbon fibers have been used to enhance material strength and rigidity. Later, it was mechanically confirmed that when pulled along it axis, carbon nanotubes have a tensile strength \( \sim 300 \) times greater than that of the strongest steel. Soon after, the electrical properties of carbon nanotubes were harnessed. Electrically, metallic SWNTs can behave like one-dimensional conduits for electrons with near zero effective resistance. These properties makes SWNTs ideally suited for fabricating nanocircuitry, and they are generally considered as one of most promising candidates to replace the silicon transistor as it approaches its fundamental size limitations.

Comparatively less explored, are the photoninc applications of SWNTs. Optically, semiconducting single-walled carbon nanotubes (s-SWNTs) absorb and emit light at a frequency tunable with the nanotube diameter. Synthetic nanotubes contain both metallic and semiconducting tubes across a broad distribution of diameters, as such, they are one of the most efficient know solar absorbers spanning the UV to the near-IR regions. The potential of this efficiency has yet to be harnessed for solar voltaic applications owing in part fundamental unanswered questions concerning photophysics of ensembles of semiconducting SWNTs. In this dissertation, we explore such unanswered questions as "what processes make-up a nanotube linear absorption spectrum", "what electronic and vibrational states are relevant to describe optical relaxation", and "how do multiple optical excitations interact with each other in a 1D confined system". In addressing these questions, time is used as our metric, whereby ultrafast spectroscopic processes are used to resolve dynamic processes on the femtosecond (\( 10^{-15} \) s) timescale in which they transpire.

**1.2 Organization of Dissertation**

Attracted by its elegantly simple molecular structure, and potential for optoelectronic applications carbon nanotubes remain an area of intense scientific investigation at the fundamental level. Beyond extensively reported transient absorption studies, application of nonlinear, time-resolved optical spectroscopy to carbon nanotubes is an unexplored area. After introducing the fundamental properties of carbon nanotubes and nonlinear spectroscopy (chapters 2 to 3), conventional pump probe measurement are extended into the mid-IR region in order to probe the electronic and vibrational structure (chapters 4 and 5). In chapter 6, multi-exciton generation processes in nanotubes are modeled to reveal how exciton-exciton annihilation processes depend strongly on the initial populated state, temperature and the applied beam fluence. A generalized stochastic approach to model the dynamics of multi-exciton states is also developed.

The coherent dynamics of SWNT excitons are difficult to access by conventional time-resolved techniques. In chapter 7, photon echo spectroscopy is introduced as a direct way
to determine the optical dephasing time associated with the loss of coherence from exciton-phonon scattering. Such exciton-phonon coupling also determines the homogeneous line-shape, which is measured for select SWNTs in chapter 8, by application of photo echo peakshift spectroscopy. Photon echo spectroscopy is also found to be a remarkably sensitive probe of exciton-exciton scattering processes which arise from the multiple exciton generation discussed in chapter 6. The unusually strong dependence of optical dephasing on photon fluence is theoretically modeled in chapter 9 by a non-perturbative technique accounting for up to 10th order interactions. The end result derives how exciton-exciton annihilation induces optical dephasing in SWNTs.

In chapter 10, the temperature dependence of the $E_{11}$ exciton-exciton annihilation rate is investigated to illustrate the importance of both diffusive and delocalized mechanisms for exciton annihilation. A strong correlation between intensity induced optical dephasing, and exciton-exciton population annihilation is also reported. In chapter 11, long pure optical dephasing times for SWNTs of 285 fs (294 K) are measured through a combination of transient absorption and photon echo spectroscopy, consistent with unusually weak room temperature exciton-phonon coupling. Cooling to 4.4 K results in only moderately longer pure dephasing times that scale predominately with the acoustic phonon population. The role of 1D exciton delocalization in exciton-phonon coupling processes is also discussed. Lastly in chapter 12, application of two-dimensional electronic spectroscopy to SWNTs is demonstrated to yield valuable, dynamic information about the $E_{22}$ homogeneous linewidth, phonon side-bands and $E_{22} \leftrightarrow E_{11}$ electronic coupling processes, revealing a rich, unexplored approach to obtain a holistic picture of SWNT exciton dynamics.

1.3 References


Chapter 2

Carbon Nanotubes

Figure 2.1. Structure of a (7,5)-type chiral single-walled carbon nanotube (SWNT), and its double-walled (DWNT) counterpart with an outer (17,6)-type shell.

2.1 Physical and Electronic Structure of Carbon Nanotubes

The novel electrical, mechanical and optical properties of carbon nanotubes are a direct consequence of their unusual structure. Structurally, a carbon nanotube can be described as a monolayer of graphite (graphene) rolled up into a cylinder along a lattice vector. The length of the cylindrical tube can be arbitrarily long, and is generally capped at the ends by two hemispherical sections of appropriately sized fullerene-like structures. The resulting
structure is termed a single-walled carbon nanotube (SWNT).[1] Alternatively, a SWNT can be enveloped in concentric cylindrical casings of graphene to form double or even multiple-walled carbon nanotubes (D/MWNTs, see figure 2.1).

The physical properties of carbon nanotubes are largely determined by their associated chiral vector \( \mathbf{C}_h \). \( \mathbf{C}_h \) is defined by the integral indices \((n, m)\) which span the the honeycomb Bravais lattice vectors \( \mathbf{a}_1, \mathbf{a}_2 \) for a graphene sheet,

\[
\mathbf{C}_h = n\mathbf{a}_1 + m\mathbf{a}_2 \equiv (n, m) \tag{2.1}
\]

and its magnitude provides the circumference of the corresponding nanotube.[1] To geometrically construct the carbon nanotube, the tip and stem of \( \mathbf{C}_h \) are connected, effectively rolling up the graphene sheet as shown in figures 2.2a and b. Accordingly, the chiral vector is also a direct measure of nanotube diameter \( d_t \), i.e.

\[
d_t = \frac{|\mathbf{C}_h|}{\pi} = \frac{a}{\pi} \sqrt{n^2 + m^2 + nm} \tag{2.2}
\]

where \( a \) is the magnitude of the (nonorthogonal) graphene Bravais lattice vectors, i.e. \( |\mathbf{a}_1| = |\mathbf{a}_2| = \sqrt{3}a_{CC} = 1.42 \times \sqrt{3} = 0.246 \text{ nm.}[2, 3, 4] \) It is also useful to define a chiral angle(\( \theta \)) of \( \mathbf{C}_h \) with respect to the \( \mathbf{a}_1 \) lattice vector[5],

\[
\cos \theta = \frac{\mathbf{C}_h \cdot \mathbf{a}_1}{|\mathbf{C}_h||\mathbf{a}_1|} = \frac{2n + m}{2\sqrt{n^2 + m^2 + nm}} \tag{2.3}
\]

which has range of \( 0 \leq \theta \leq 30^\circ \).

The vector \( \mathbf{C}_h \) defines not only the carbon nanotube circumferential direction, but also the translational vector \((\mathbf{T})\) along the nanotube that is required to form the complete unit cell. \( \mathbf{T} \) runs perpendicular to \( \mathbf{C}_h \) (see figure 2.2a), and can be similarly expressed in terms of the honeycomb lattice vectors as,

\[
\mathbf{T} = t_1\mathbf{a}_1 + t_2\mathbf{a}_2 \tag{2.4}
\]

\[
t_1 \equiv \frac{2m + n}{d_R}, \quad t_2 \equiv -\frac{2n + m}{d_R} \tag{2.5}
\]

where \( d_R \) is the greatest common divisor of \((2n + m)\) and \((2m + n)\).[1] For instance, this dissertation primarily examines the spectroscopy associated with nanotubes having a \( \mathbf{C}_h = (6,5) \), and a mean tube length of 600 nm. Using the \((6,5)\) chirality in equation 2.5, we obtain a \( \mathbf{T}=(16, -17) \), corresponding to a unit cell length of \( |\mathbf{T}| = |\mathbf{a}_1| \sqrt{n^2 + m^2 + nm}/d_R \approx 4.06 \text{ nm.} \) With this cell length, a \( \sim 600 \text{ nm long} \) tube would be composed of approximately 148 unit cells. Using the lattice geometry shown in figure 2.2a, we can further calculate the number of carbon atoms per unit cell \( (N) \) as,

\[
N = \frac{|\mathbf{C}_h \times \mathbf{T}|}{|\mathbf{a}_1 \times \mathbf{a}_2|} = \frac{2(m^2 + n^2 + nm)}{d_R} \tag{2.6}
\]

which for a \((6,5)\) SWNT is 364 atoms per unit cell.[1] Using a \( \sim 600 \text{ nm long} \) \((6,5)\) SWNT nanotube investigated here, we can expect 364 \( \frac{\text{atoms}}{\text{cell}} \times 148 \frac{\text{cells}}{\text{nanotube}} \approx 5.4 \times 10^4 \text{ carbon atoms} \)}
2.1.1 Graphene; the tight binding model

The complex network of bonding in a carbon nanotube derives from the much studied $\sigma$ and $\pi$ bonds associated with graphitic carbon. In the planar direction, the $\sigma$ bonds are $sp^2$ hybridized and form the main hexagonal network.[1] The $\pi$ bonding network of $p_z$ orbitals are oriented parallel to the graphene surface, and further give rise to van der Waals interactions that are ultimately responsible for phenomena such as bundling in carbon nanotubes and the characteristic inter-planer separation between graphene sheets.[6] When a sheet of graphene is constrained to the cylindrical formation of SWNT, strong $\pi$ bond interactions are expected because of steric interactions. In contrast, the planar $\sigma$ bonds are too far away from the Fermi level, and play only a minor role in the electrical and optical properties of SWNTs.[5] As a consequence, the electronic properties of graphene can be sufficiently modeled by applying the tight-binding approximation to obtain the band structure associated with the $\pi$ bonding.
network. Full details for this calculation are reported elsewhere (see [7, 5] for example). Briefly, the Schrödinger equation \( H\psi(k) = E(k)\psi(k) \), is solved for the eigenvalues \( E(k) \). The eigenfunctions are expressed as linear combination of Bloch functions, \( \varphi(k) \). In the tight binding approximation it is assumed that the Bloch functions can be written as linear combinations of the atomic orbitals (LCAO) to provide the wave functions associated with the perpendicular \( 2p_z \) orbitals for graphene.[8] Since the graphene unit cell only has 2 atoms per cell, in the solution to the above Schrödinger equation it is sufficient to diagonalize a \( 2 \times 2 \) matrix for interactions between the nearest neighbors only. The resulting eigenvalues, \( E(k) = E(k_x, k_y) \) provide the corresponding energy dispersion relations for the valence and conduction bands for graphene[5, 6]. The general form of the first Brillouin zone is shown in figure 2.3a. The regions of primary interest are at the so-called \( K \) high-symmetry points where the conduction and valence band intersect to make graphene a zero-band gap material. This region is magnified in figure 2.3a, revealing a cone-like intersection region that will ultimately dominate the electrical and optical properties graphene and carbon nanotubes alike.

### 2.1.2 The zone-folding approximation

To move from a two-dimensional graphene structure to a quasi-1D carbon nanotube one can naively imagine simply reducing the two-dimensional \( (k_x, k_y) \) Brillouin zone, into a 1D zone. In this case, the nanotube Brillouin zone is obtained by drawing 1D cutting lines through the regions of highest interaction, which in this case are about the \( K \) high-symmetry points of graphene, labeled in figure 2.3a. Along the \( z \)-axial direction, free particle behavior is assumed for an infinite length tube, which corresponds to a free particle reciprocal lattice vector \( k_z = 2\pi/|a_1| \). The circumferential direction however, is quantized according to the boundary condition that the wavefunction \( \psi(r + C_h) = \psi(r) \), which implies the circumferential reciprocal lattice vector \( (k_{x,y}) \) is also quantized as:

\[
  k_{x,y} = \frac{2\pi}{|C_h|} \cdot I = \frac{2}{d_t} \cdot I
\]

where \( I \) is an integer value.[1, 9] As a consequence, the corresponding nanotube Brillouin zone, consists of 1D cutting lines (figure 2.3a) of length \( 2\pi/|a_1| \) spaced at intervals of \( 2/d_t \) parallel to the tube axis. This approach known as the zone-folding approximation, allows one to read off the nanotube band structure for any given tube chirality by simply drawing the corresponding cuttings about the \( K \)-point region of the tight-binding band structure for graphene.[5, 9] This approximation neglects important complications which arise from the new cylindrical geometry as well as the strong influence of tube wall curvature, but nonetheless provides an excellent predictive model for the basic physical properties of carbon nanotubes (e.g., rough band gaps, semiconducting or metallic, etc.).
Figure 2.3. a. Graphene Brillouin zone; electronic and optical properties of SWNTs depend on band structure near the magnified cone-like intersections connecting the corresponding conduction and valence bands. b. SWNT electronic properties can be modeled in zone folding approximation on graphene shown by the cutting lines and for corresponding one-dimension density of states. For semiconducting tubes, these resulting van Hove singularities cause gaps to appear in the band structure.

2.1.3 Semiconducting and metallic nanotubes

Carbon nanotubes are either semiconducting or metallic, depending on the nanotube chirality. When the carbon nanotubes Brillouin zone cutting lines cross though the the $K$ symmetry point the nanotube will be metallic, with a zero band-gap much like graphene.[1, 4]

To account for the semiconducting case, we need to first define the coordinates in reciprocal space that take us from the $\Gamma$ high symmetry point (see figure 2.3a) to any of the six nearest $K$ high symmetry points of the graphene. Translating our original Bravais lattice vectors $a_1$ and $a_2$ into reciprocal space using Cartesian coordinates one obtains $k_1 = (k_x, k_y) = 4a\pi/\sqrt{3}(0, 1)$ and $k_2 = 4a\pi/\sqrt{3}(\frac{\sqrt{3}}{2}, -\frac{1}{2})$.[5] Using this geometry, it can be seen that the vector $K = \frac{1}{3}(k_1 - k_2)$ translates from $\Gamma$ to the $K$ high symmetry points. As a result, a nanotube will be metallic if $K$ is a reciprocal lattice vector of a particular tube with chiral vector $C_h$ [10], or alternatively,

\[ K \cdot C_h = 2\pi I = \frac{1}{3}(k_1 - k_2) \cdot (na_1 + ma_2) = \frac{2\pi}{3} (n - m). \]  \hspace{1cm} (2.8)

The above expression shows that in order for a cutting line to cross the $K$ point and acquire metallic behavior, the nanotube chirality will be $(n - m) = 3I$.[5] Additional criteria for metallicity can also be obtained by searching for the conditions on $k_z$ where the nanotube conduction and valence band meet. This condition can be evaluated by finding where the
translational vector crosses a $K$-high symmetry point, i.e.

$$K \cdot T = 2\pi k_z$$ \hfill (2.9)

which crosses $K$ when $K \cdot T = 0$ or when the continuous wavevector $k_z = 0$. Equation 2.9 can be evaluated through substitution with equation 3.5 to show that this criteria is satisfied for the so called armchair tubes ($n, n = m$) and select zig-zag ($n, m = 0$) tubes where $n$ is multiple of three, making them metallic within the zone folding approximation.\cite{6, 5} Using the rules obtained from equations 2.8 and 2.9, metallic tubes collectively represent approximately $\frac{1}{3}$ of all tube types possible.\cite{1} However their prevalence can be selectively controlled by synthetic and purification approaches. In this dissertation, only optical properties of semiconducting carbon nanotubes are considered, and all the samples have been enriched (up to 97%) in tube chiralities with a characteristic semiconducting band structure.\cite{11}

## 2.2 Carbon Nanotube Synthesis

Numerous synthetic techniques exist for carbon nanotubes, but they all rely on three basic requirements originally discovered by Iijima et al.; they are a source of carbon, high activation temperatures and surface catalysis to nucleate growth.\cite{12} Today, the primary synthetic routes can be grouped in three categories of plasma arc discharge, laser ablation, and chemical vapor deposition (CVD). These synthetic approaches differ primarily in their method of providing the activation energy required to make nanotube formation thermodynamically favorable.\cite{13, 14}

The arc-discharge route was the first reported method of nanotube synthesis, and relies on DC arc discharge between two graphite electrodes.\cite{12} The resulting carbon nanotubes accumulate at the device cathode. In absence of catalysts to mediate the reaction, only multi-walled carbon nanotubes are formed. By adding metallic catalysts at the anode and controlling the ambient gas, SWNTs can be preferentially formed. However, the arc-discharge method has a distinct drawback of producing highly bundled SWNT with extensively tangled morphologies.\cite{1}

To obtain samples highly concentrated is specific nanotube tube types, chemical vapor deposition (CVD) is the generally preferred method. CVD uses hydrocarbon gases and transition metal catalysts (e.g. Fe, Ni, Co) to provide a surface nucleation site for growth. The two most widely used CVD approaches are the HiPCO (High-Pressure carbon monoxide) and CoMoCAT (Cobalt Molybdenum CATalyst) methods. HiPCO technique uses Fe catalysts, and was the synthetic route used for many early spectroscopic measurements done in this field (e.g. \cite{15, 16}). For the work presented in chapters 4-12, the CoMoCAT method was preferred synthetic route due to its enhanced selectivity for specific nanotube chiralities such as the (6,5), (7,5) and (6,4) types (see figure 2.5). In particular, CoMoCAT technique can produces SWNTs with as little as 3% metallic tube content, compared to the ~30% common with other techniques. In CoMoCAT synthesis, a constant stream of carbon monoxide gas flows past bimetallic strips of cobalt-molybdenum catalyst particles supported
on SiO$_3$. Compared to the arc discharge approach, CoMoCAT operates at comparatively low temperature ranging from 500-1000° C.[14] After synthesis, a post processing method is used to remove residual catalyst particles, silica and amorphous carbon depositions. The end product is a black semi-crystalline fibrous powder that is highly enriched in semiconducting tubes.

2.3 Optical Properties

2.3.1 Electronic density of states

In contrast to bulk semiconductors, carbon nanotubes are a true quasi-1D nanomaterial, and the ensuing confinement effects greatly modify the electronic structure. To examine the behavior of the density of states ($n(E)$) under 1D confinement, we consider a particular nanotube subband and allow for free particle motion along the $z$-axis, and quantized energy eigenstates along the circumferential direction. The corresponding density of states in 1D can be evaluated from the textbook expression for the $i^{th}$ transition,

$$n_i(E) = \frac{2}{V} \int dk_z \delta(k_z - k_i) \left| \frac{\partial E(k)}{\partial k_z} \right|^{-1}$$  \hspace{1cm} (2.10)

where $V$ is the Brillouin zone volume.[8, 17] To evaluate the above partial derivative, we note that close to the Fermi level the cone-like graphene dispersion (see figure 2.3a) can be used to extract the SWNT band structure, which can further be approximated by a set of straight lines about the Fermi vector ($k_f$), i.e.

$$E(k) \propto \pm |k - k_f| = \sqrt{\Delta k_i^2 + \Delta k_z^2}$$  \hspace{1cm} (2.11)

where the $k$-dependence has been decomposed into their circumferential ($k_i$) and $z$ components($k_z$) about about the Fermi level.[5] This energy dispersion relation can then be used to evaluate the derivative in equation 2.10,

$$\left| \frac{\partial \sqrt{\Delta k_i^2 + \Delta k_z^2}}{\partial k_z} \right|^{-1} = \frac{|E(k)|}{\sqrt{E^2 - E_i^2}}$$  \hspace{1cm} (2.12)

where $E_i$ is the energy associated with the quantized $k_i$ wavevectors for the circumferential nanotube direction. The corresponding nanotube density of states is then obtained by substitution in equation 2.10 and integration over $k_z$,

$$n_i(E) \propto \int dk_z \delta(k_z - k_i) \frac{|E|}{\sqrt{E^2 - E_i^2}}$$  \hspace{1cm} (2.13)

$$\Rightarrow n_i(E) \propto \{ \begin{array}{ll} \frac{|E|}{\sqrt{E^2 - E_i^2}} & \text{if } E > E_i \\ 0 & \text{if } E < E_i \end{array} $$
revealing that the density of states diverges as $E \to E_i$ for each subband denoted by the quantum number $i$.[18, 19] In figure 2.3b, the density of states is plotted for $i = 1, 2$. The resulting divergence produces a van Hove singularity as $E \to E_i$, and the existence of finite band gap for semiconducting tubes. Using Fermi’s Golden Rule, the diverging density of states, $n_i(E)$ can be directly related to the electronic transition probability.[8] The net end result is a series of spectrally sharp optical transitions (denoted $E_{11}, E_{22}, \text{etc.}$) that dominate the optical absorption spectrum.[15, 20]

2.3.2 Linear absorption

The linear absorption spectrum of a typical sample of synthetic carbon nanotubes is shown in figure 2.4. In contrast to the sharp van Hove singularities predicted in the previous section, two broad peaks are observed corresponding to the first and second subband transitions in semiconducting carbon nanotubes. In their natural state, SWNTs have a tendency to bundle with neighboring tubes because of mutual van der Waals attraction.[1] These bundles of carbon nanotubes produce a broad absorption spectrum, and contain contributions from many different nanotube chiralities. The quantization condition along the circumferential tube direction from equation 2.7 shows that $k_{x,y} \propto 1/d_t$, and when substituted into the linear dispersion relation from equation 2.11, it is readily seen that energy gap for semiconducting tubes scales as,

$$E_g \propto \frac{1}{d_t}. \quad (2.14)$$

As a consequence, the observed spectral broadening in an ensemble measurement of many tube types, results predominately from the inverse energy gap dependence with tube diameter.[15] Such a broad linear absorption spectrum makes spectroscopy inherently difficult since each individual tube type has intrinsically different physical properties. To resolve this problem, and probe the optical properties of individually separated nanotubes, post-processing of synthetic carbon nanotubes is required.

2.3.3 Nanotube purification and sample characteristics

In comparison to extensively studied nanoscale systems like quantum dots and wells, the electronic and spectroscopic properties of semiconducting carbon nanotubes remains nebulous. A chief limiting factor for unambiguous results has been the need for highly individualized SWNTs samples, that are highly pure in a specific carbon nanotube chirality. The ability to isolate a single tube type from a bulk sample of carbon nanotubes is presently an unsolved synthetic problem. Fortunately, by applying post-processing techniques such as the one outlined below, the distribution of tube types can be sufficiently narrowed, so that a desired tube of $C_n = (n, m)$ can now be optically probed using on-resonant excitation.[21]

Synthetic carbon nanotubes are naturally sparingly soluble in water.[1] To dissolve and
Figure 2.4. Bulk synthetic nanotubes give broad and ambiguous linear absorptions features owing largely to nanotube bundling. Within the spectrum are comparatively sharp resonances corresponding to the chirality dependent ($C_h$) absorption.

to separate SWNT bundles, subsequent post-processing steps are required. While such bundles of carbon nanotubes retain their large tensile strength, the electronic properties are thought to be strongly perturbed as demonstrated for instance by the markedly lower photoluminescence yields of bundled carbon nanotubes.[22] In order to study the optical properties of SWNTs, it is necessary to separate the bundles into individualized tubes. This process is accomplished by sonicating the SWNTs, resulting in mechanical tube separation at the atomic level. Further aggregation among nanotubes can be prevented by introduction of stabilizing surfactant that forms micelles on the tube surface (see figure 2.3c).[23] As final step, ultracentrifugation is employed to remove remaining nanotube bundles and residual amorphous carbon. Upon comparing absorption spectra of bundled nanotubes (figure 2.4) to aqueous suspensions of individualized SWNTs (figure 2.5), comparatively sharp absorption resonances are apparent revealing the previously hidden van Hove singularity transitions ($E_{11}$, $E_{22}$, etc.) of different tube types. This process of nanotube individualization was first reported by O’Connell et al. in 2001, and provides nanotubes free from inter-tube coupling, that enabled the very first optical investigations on individual carbon nanotubes.[24, 23]

Individually separated SWNTs prepared by the CoMoCAT synthesis, give a highly structured linear absorption and fluorescence spectra, and the peaks of various tube types still overlap strongly as shown in figure 2.5. In 2006, Arnold et al. developed a density gradient approach that further narrowed the distribution of tube types for CoMoCAT synthesized SWNTs.[21] The resulting electronic properties yield distinct absorption peaks (see figure 2.6), which readily permit on-resonant excitation of one tube types to exclusion of all others. For instance, the dotted lines indicates typical laser pulse spectrum used in our spectroscopic
Figure 2.5. Linear absorption spectrum of aqueous samples of SWNTs in surfactants. Synthesis by the CoMoCAT CVD method preferentially produces semiconducting tubes with a much narrower chirality distribution than form HiPCO CVD synthesis. The relative abundances of the different tube types obtained from the CoMoCAT synthesis [(top right), courtesy of SouthWest Nanotechnologies]

studies, and it highlights the exclusive resonant excitation of the $E_{11}$ optical transitions for the (6,5) tube type.

The precise method for carrying out this density gradient enrichment is outlined in subsequent chapters. Briefly this technique exploits that nanotubes selectively coated in surfactants and bile salts will have a different inherent buoyancy in solution depending upon their nanotube chirality. Exploiting this principle, Arnold et al. demonstrated that after ultracentrifugation, the solution of nanotubes separates into spatially separated layers that are in enriched in specific tube types (shown in figure 2.6, right). Once extracted, these aqueous layers yield remarkably strong absorption, photoluminescence and nonlinear optical response for nanotubes of the (6,5) chirality.[21, 25] The recent availability of such high-purity samples has drastically changed the scope of spectroscopic characterization tools that can be applied with a sufficiently good signal-to-noise response.
Figure 2.6. Carbon nanotubes can be purified and enriched in the (6,5) chirality, to yield sharp transitions that can be resonantly excited with a laser pulse to exclusion of other tube types (shown). The enrichment process is done by density gradient separation (side inset, reproduced with permission from Arnold et al.[21]).

2.4 Semiconducting Single-Walled Carbon Nanotubes:

an Excitonic Picture

The ability to obtain individually separated SWNTs as demonstrated by O’Connell et al., gave rise to a period of intense study of nanotube photoluminescence.[23, 15, 26] Through comparison of the obtained two-dimensional SWNT fluorescence spectrum against established Raman scattering measurements, spectroscopic assignment of absorption peaks to specific tube chirality was finally made possible.[15] At the time of this work by Bachilo et al. in 2002, the zone-folding approximation on graphene was assumed sufficient and the band transitions were still modeled using 1D electron-hole van Hove singularity picture (see figure 2.3).[5] For this model to be sufficient, each subband transition \( n_i(E) \) must have equal energetic spacing because of the linear dispersion relation in equation 2.11 (about the \( K \) high symmetry points). However, after spectral assignment of the peaks by Bachilo et
al., it became clear that for semiconducting tubes \( E_{22}/E_{11} \neq 2 \), but rather \( \sim 1.7 \).[27, 15] This so called ”ratio problem” could not be explained by a one-electron model, and it was postulated that the discrepancy could be explained by many-body effects such as exciton formation originally suggested by the \textit{ab initio} calculations of Ando \textit{et al.} and Spataru \textit{et al.}[28, 29]

\section*{2.4.1 Experimental determination of the exciton binding energy}

Stable excitons are prevalent in wide variety of semiconducting systems from GaAs quantum wells to quantum dots. A stable exciton forms when electron-hole Coulombic attraction gives rise to an energetically favorable lower state. The corresponding energy separation with respect to the continuum state is known as the exciton binding energy (\( E_B \)). Typically binding energy for three-dimensional semiconductors like GaAs are small with \( E_B < 10 \text{ meV} \).[30] Such weakly bound excitons are not considered stable at room temperature since the system thermal energy exceeds the binding energy (\( E_B \geq k_B T \approx 25 \text{ meV at 294 K} \).[31]

Numerous experimental reports provided anecdotal evidence that stable excitons might exist in semiconducting SWNTs; these included the ratio problem reported in Bachilo \textit{et al.},[15] the weak absorption lineshape dependence with temperature by Htoon \textit{et al.},[26] and intensity-dependent decay dynamics reported by Ma \textit{et al.}[32] However, these reports only offered indirect support for exciton formation, and so despite strong theoretical predictions, the simpler 1D van Hove singularity model was generally preferred.

In 2005, two independent works by Wang \textit{et al.} and Ma \textit{et al.} reported a direct measurement of the exciton binding energy for semiconducting SWNTs that was in excess of 0.4 eV for the lowest \( E_{11} \) transition.[34, 33] Each respective work employed very different methodologies; Wang \textit{et al.} employed two-photon luminescence and Ma \textit{et al.} used spectrally resolved transient absorption. Shortly after, a more comprehensive study of binding energies of various tube types was reported by Maultzsch \textit{et al.}[35] In figure 2.7, the transient absorption work by Ma \textit{et al.} is briefly summarized. Using spectrally resolved transient absorption, the spectrum 50 fs after initial excitation reveals a salient transient peak that can be assigned to the impulsively populated electron-hole continuum (shown in green). Also observed was a secondary feature (shown in orange), that persists for 100s of ps and is assigned to the corresponding bound exciton state. The resulting energetic difference between transient peak gave a direct measurement for the (8,3) SWNT binding energy of 0.41 eV.[33] Such large binding energies are substantial fraction of the overall energy gap, and showed conclusively that the bright optical transitions observed correspond to stable exciton states.[34, 19, 36]

\section*{2.4.2 Properties of confined excitons}

Electrons and holes are the preferred carriers within the solid-state elementary excitation model.[37] In many systems such as semiconducting SWNTs however, the mutual Coulombic attraction between electron-hole pairs is sufficiently strong that they are best described by
Figure 2.7. Transient absorption spectrum after a 50 fs pump-probe delay time showing the respective peaks for the $E_{11}$ transition and a continuum state transition for the (8,3) type SWNT. This energetic peak separation defines the associated exciton binding energy as 0.41 eV. (the first panel is reproduced with permission from Ma et al. [33])

a composite quasi-particle, the exciton. Under such a strong Coulombic interaction the respective group velocities of the electron($v_e$) and hole($v_h$) necessarily become correlated in their respective bands such that,

$$v_e = v_h = \frac{1}{\hbar} \frac{\partial E(K_{cm})}{\partial K_{cm}}. \quad (2.15)$$

where $K_{cm}$ is the center of mass wavevector for the exciton and is defined as $(k_e - k_h)/2$.\[19, 36\] While both direct and indirect band gap transitions are common with uncorrelated electron-hole pairs, in the excitonic picture generally $\Delta K_{cm} \approx 0$ for all transitions because the particle motions must be correlated. Small deviations in this requirement for direct transitions at band minimum occur, but are generally no greater than that of the intrinsic momentum of the interacting photon.\[38\]

Depending upon the exciton spatial properties with respect to the host lattice, excitons can be generally divided into the two classifications of Frenkel and Mott-Wannier types.
Frenkel excitons are common in molecular solids, and are characterized by an effective exciton radius \( a_{\text{ex}} \) that is smaller than the lattice spacing.[39] Mott-Wannier excitons normally have smaller binding energies and have comparatively weak dielectric screening permitting a larger effective radius that can span many lattice sites.[17] For semiconducting SWNTs, the \( E_{11} \) exciton radius has been experimentally estimated to be 1-2 nm,[34] which is larger than tube diameter, and so they are generally classified at Mott-Wannier excitons.

The electronic properties of excitons can be roughly approximated by a two-particle Schrödinger equation with a Coulombic attractive potential.[37, 40] For SWNTs, the exciton properties in a dielectric environment can be estimated by a 1D model using the modified hydrogen-like Schrödinger equation shown below,

\[
\left( \frac{\hbar^2}{2\mu_{\text{ex}}} \frac{d^2}{dx^2} - \frac{e^2}{\epsilon |x|} \right) \psi_n(x) = E_n \psi_n(x)
\]

where \( \mu_{\text{ex}} \) is the electron-hole effective mass, \( \epsilon \) is the dielectric screening parameter, \( E_n \) is the minimum exciton energy, and \( \psi_n(x) \) is a hydrogenic-like wavefunction. The solutions are obtained in a similar fashion to the hydrogen atom, except for the treatment of the singularity which arises near \(|x| = 0\).[40] The resulting eigenvalues \( E_n \), provide an effective exciton binding energy, which allows the overall dispersion relation for excitons to be expressed as

\[
E_{n,\text{ex}}(K_{\text{cm}}) = E_g - \frac{Ry^*}{\left( \frac{n^2}{n^2 + \frac{d-3}{2}} \right)} + \frac{\hbar^2 K_{\text{cm}}^2}{2(m_e + m_h)}
\]

where \( E_g \) is the total band gap energy (i.e. \( E_c(0) - E_v(0) \)), and \( Ry^* = 13.6 \text{ eV} \left( \mu_{\text{ex}}/m_e \epsilon^2 \right) \) is the effective Rydberg energy.[37] Here, a parabolic exciton band dispersion has been assumed similar to the schematic depicted for the \( E_{11} \) band in figure 2.7. Using this model the effective exciton radius is obtained directly from hydrogen Bohr radius(\( a_B \)) augmented by \( \mu_{\text{ex}} \) and the dielectric screening coefficient \( \epsilon \),

\[
a_{\text{ex}} = \left( n + \frac{d-3}{2} \right)^2 \frac{m_e \epsilon}{\mu_{\text{ex}}} a_B.
\]

The resulting exciton radius varies markedly with system dimensionality(\( d \)), and with the dielectric constant of the nanotube and the local environment.[37, 39] For SWNTs, the dimensionality, \( d = 1 \) so we expect not only a larger exciton binding energy from enhanced Coulombic interactions, but also a larger exciton radius compared to solids of higher dimensionality as shown by equation 2.18. Notwithstanding the rough approximations made, this 1D hydrogenic model demonstrates how Mott-Wannier excitons with characteristic large radii of 1-2 nm[34] are realized in spite of the presence of remarkably large exciton binding energy.

### 2.4.3 Calculating electron-hole interaction

Long before conclusive experimental evidence for stable excitons in SWNTs, \textit{ab initio} treatments showed the effective band gap for semiconducting tubes depends strongly on
how the electron-hole interaction is treated.[41, 28] In 2004, the seminal work by Spataru et al. calculated the band structure for metallic and semiconducting tubes.[29] Full details of the theoretical methods employed are presented elsewhere.[19, 29] Briefly, the electronic structure was modeled as \( 2p_z \) orbitals from a folded Brillouin zone of graphene, and a density-functional theory (DFT) approach was used to find the SWNT electronic ground state. DFT provided the required ground state wavefunction, and eigenvalues were obtained by solving the Kohn-Sham equations.[29]

Since Coulomb interaction localizes the wavefunction in real space, for strongly bound excitonic systems \( \mathbf{k} \) is no longer a good quantum number, and a more sophisticated approach is required to obtain the coupled electron-hole excitation energy, \( \Omega_n \). Spataru et al. was able to explicitly include this electron-hole interaction using the powerful Bethe-Salpeter equation,

\[
(E(\mathbf{k}_c) - E(\mathbf{k}_v))\psi_n(\mathbf{k}_c, \mathbf{k}_v) + \sum_{\mathbf{k}_c', \mathbf{k}_v'} \langle \mathbf{k}_c, \mathbf{k}_v | K_{\text{eh}} | \mathbf{k}_c', \mathbf{k}_v' \rangle \psi_n(\mathbf{k}_c', \mathbf{k}_v') = \Omega_n \psi_n(\mathbf{k}_c, \mathbf{k}_v) \quad (2.19)
\]

where \( E(\mathbf{k}_v) \) and \( E(\mathbf{k}_c) \) are the quasi-electron and quasi-hole energies respectively, and \( |\mathbf{k}_v\rangle \) and \( |\mathbf{k}_c\rangle \) are the quasi-electron and quasi-hole states. \( K_{\text{eh}} \) is the electron-hole interaction kernel that contains both a repulsive Coulombic exchange term and an attractive screening contribution. Together, \( K_{\text{eh}} \) can effectively model electron-hole correlations through a two-particle Green’s function.[19, 42] In Spataru et al., solutions for \( \Omega_n \) were obtained, and for the (8,0) SWNT a binding energy of \( \sim 1 \) eV was reported after inclusion of electron-hole correlations.[29] This large exciton binding energy provided strong initial support for highly correlated electron-hole interactions in semiconducting SWNTs. From this work it was suggested that an enhanced Coulombic attraction between electron-hole pairs arises from confinement, dramatically altering effective band-gap to yield remarkable stable exciton states.[42, 29, 34]

### 2.5 Exciton Photophysics in Semiconducting Carbon Nanotubes

\textit{Ab initio} calculations predict the existence of not only optically bright excitons transitions, but also a complex manifold of predominately dark exciton states.[29, 42] The results of one such calculation from the Louie group are shown figure 2.8 for the (11,0) tube.[43] This figure associated with the \( E_{11} \) exciton manifold, highlights the complexity of the fine structure. To simplify, the underlying symmetry of the carbon nanotube allows for excitonic wavefunctions of definite parity, that restricts interband, one-photon optical transitions to states of opposite parity only.[19] Using such arguments, the majority of the remaining states in figure 2.8 are either optically forbidden by symmetry selection rules or carry inherently low oscillator strength.[44, 45] The \( 0A_u^- \) state shown results in particularly strong radiative transitions, and will be referred to as in this dissertation simply as the \( E_{11} \) transition.
Figure 2.8. *Ab initio* energy diagram of the excitonic states for the (11,0) semiconducting tube. The states are labeled by their principle quantum number, followed by even (g) or odd (u) state symmetry. $\mathrm{A'_0}$ is commonly referred to as the (optically bright) $E_{11}$ transition. Reproduced with permission from Ma et al., Phys. Rev. B, 74, 085402, 2006.

Owing to negligible momentum of the photon compared to the exciton, conservation rules requires that $\Delta K_{cm} \approx 0$ for an optical transition (see figure 2.9).[46] Once populated, the exciton is generally assumed to thermalize within the band according to Boltzmann statistics, resulting in broadening by amount $k_b T$. Assuming that the thermalization process is faster than the radiative transition, many excitons will be effective removed from the "radiative window" of $\Delta K_{cm} = k_{\text{photon}}$.[38, 47] As a consequence, this thermalization process is thought to contribute to the low photoluminescence yields ($\sim 1\% - 2\%$) commonly associated with semiconducting carbon nanotubes.[48]

Compared to conventional semiconductors where indirect and phonon assisted transitions are common, the requirement for $\Delta K_{cm} \approx 0$ is restrictive.[46] However, as shown in figure 2.9, the corresponding 1D joint density of states (JDOS) is expected to diverge near the exciton band minimum. So in stark contrast to the 3D case, the JDOS of the SWNT electron and hole bands, is inordinately large about the band minimum, allowing for multiple exciton population in the $\Delta K_{cm} \approx 0$ region. To demonstrate the importance of these multi-excitonic effects, a simple calculation for exciton population ($n_{ex}$) is carried out in figure 2.9. Using a recently reported absorption cross-section,[49] and a typical laser beam fluence, upwards of 60 exciton are expected to be populated for 600 nm long (6,5) SWNT. The ability to simultaneously populate such large number of excitons all initially localized near the band minimum can lead to markedly enhanced scattering among excitons.[50]
Figure 2.9. The requirement that $\Delta K_{cm} \approx 0$ restricts the $E_{11}$ transition to the band minimum, where the one-dimensional joint DOS (JDOS) diverges, enabling multiple exciton populations. Using typical ultrafast beam fluences calculations suggests we can populate upwards of 60 excitons per 600 nm semiconducting tube.

### 2.6 Summary

This chapter provides a brief survey of the established physical properties of carbon nanotubes. While their structural, mechanical and electrical properties can be roughly understood through analogy to graphene, SWNTs optical processes are intrinsically more complex, and comparatively unexplored. The SWNT electronic properties can only be crudely approximated by the graphene band structure in the zone-folding approximation. Instead, it has been shown that quasi 1D confinement effects inherent to semiconducting SWNTs, greatly enhance electron-hole Coulombic interactions leading remarkably large exciton binding energies.\[34, 33, 45\] The ensuing optically bright excitonic transitions dominate all spectral features, and have important consequences for both the photoluminescence yield, and the time-resolved dynamics advanced in this dissertation through non-linear spectroscopy.
2.7 References


Chapter 3

Nonlinear Spectroscopy

3.1 Introduction: *time is our metric*

It takes on average 190 ms for a human to react to a visual stimulus, which is orders of magnitude slower than the neural, electrical and photonic processes involved.[1] The initial rate limiting process is a molecule’s reaction time to light, which requires femto-second (10⁻¹⁵ s) precision to resolve. To access this timescale, a wavepacket of photons can be squeezed down into bundles of energy only a few femto-seconds in duration. Following optical excitation, the absorbed wavepacket becomes electronic energy which in turn couples to molecular motions and will eventually dissipate on the picosecond (10⁻¹² s) to nanosecond (10⁻⁹ s) timescale.[2] During this process, we can interrogate the system evolution in real-time, by applying subsequent probes pulses and measuring the resultant change in signal intensity.

In this chapter, the principles basic to the non-linear optical experiments described in subsequent chapters are introduced. To begin, the process of optical absorption is reviewed for both linear and non-linear interactions. The derived frequency-domain linear and non-linear optical susceptibilities are the re-cast into time dependent response functions, using the properties of the Fourier-Laplace transform. The resulting third-order polarization field, will then be used to provide the time-ordering necessary to describe the five types of four-wave mixing spectroscopy presented in this dissertation; transient absorption, transient grating, two-pulse photon echo, three-pulse photon echo peakshift and two-dimensional electronic spectroscopy.
Exciton annihilation and dephasing dynamics in single-walled carbon nanotubes

Figure 3.1. (6,5) SWNTs scatter intense nonlinear signals into momentum conserving directions, suggestive of an inherently large optical nonlinearity. Time-resolved detection of these signals enables the spectroscopic measurements presented in this dissertation. (see experimental photograph of nonlinear signals on right)

3.2 Light-Matter Interactions

3.2.1 Linear optical response

Given sufficient incident light intensity all materials will exhibit both linear and nonlinear optical response to light, however certain materials are more susceptible than others.[3] To explore how novel nanomaterials such as SWNTs respond to light and relax dynamically, the basic properties of light-matter interaction are reviewed. Optical absorption can be described by a material’s linear susceptibility, which is derived by considering two-state transition (from state $nk$ to $n'k'$) in the presence of an applied electromagnetic field. Beginning with the Hamiltonian for the motion of an electron of mass $m$, in an external electromagnetic field,[4] the terms involving the applied vector potential ($\mathbf{A}$) are treated as an applied perturbation, $H_I$.

$$H = \frac{1}{2} \sum_i m_i \left( \mathbf{p}_i + \frac{e\mathbf{A}}{c} \right)^2 + \sum_i V(\mathbf{r}_i) = H_0 + H_I$$

(3.1)

$$H_I = \frac{e}{2c} \sum_i \frac{1}{m_i} (\mathbf{p}_i \cdot \mathbf{A} + \mathbf{A} \cdot \mathbf{p}_i) + \frac{1}{2c^2} \sum_i \frac{e^2 A^2}{m_i}.$$  

(3.2)

Using the definition of the momentum operator, the following expression is obtained for each electronic interaction $i$ in our system.[5]

$$H_I^i = \frac{-ie\hbar \mathbf{A} \cdot \nabla_i}{mc} - \frac{ie\hbar}{2mc} \nabla_i \cdot \mathbf{A} + \frac{e^2}{2mc^2} A^2 \approx \frac{e}{mc} \mathbf{A} \cdot \mathbf{p}_i$$

(3.3)

For the Coulomb choice of gauge ($\nabla \cdot \mathbf{A} = 0$), the second term above vanishes. The last term varies nonlinearly with the applied field, and rigorously corresponds to a two photon
process mediated by a virtual state.[5] Such nonlinear processes are statistically small under ambient $E$-field sources such as the Sun. This approximation is known as the electric dipole approximation for electron-radiation interaction.[5, 3] Under the electric dipoles approximation, the imaginary dielectric coefficient $\varepsilon_2$ can be calculated to determine material absorption properties. Using Fermi’s Golden Rule expression, the transition probability rate function $W_{tot}(\omega)$ is calculated for a direct band gap transition (labeled $nk \rightarrow n'k'$),

\[
W_{tot}(nk \rightarrow n'k') = \frac{2\pi}{\hbar} |\langle n'k' | H_I | nk \rangle|^2 \frac{\delta (E_{n'k'} - E_{nk} - \hbar\omega)}{2} \tag{3.4}
\]

\[
= \frac{2\pi \hbar e^2 A_0^2}{m^2 \omega^2} |\hat{e} \cdot \mathbf{M}_{nn'}(k', k)|^2 \frac{\delta (E_{n'k'} - E_{nk} - \hbar\omega)}{2} \tag{3.5}
\]

where $\mathbf{M}_{nn'}(k', k)$ is the matrix element sandwiching the dipole operators from equation 3.3.[5] The resulting transition rate energy ($\hbar \omega W_{tot}$) can now be used to calculate the absorption coefficient ($n(\omega)$), by dividing it through by the energy incident on the sample per unit time which is given by $\frac{1}{2} \frac{n_0^2 A_0^2}{\pi c}$. Performing this substitution we obtain the absorption coefficient $n(\omega)$,

\[
n(\omega) \equiv \frac{\omega}{mc} \varepsilon_2(\omega) = \frac{2\pi \varepsilon_0}{\omega^2 A_0^2} \hbar \omega W_{tot} \tag{3.6}
\]

\[
\Rightarrow \varepsilon_2(\omega) = \frac{2\pi \varepsilon_0}{A_0^2} W_{tot}
\]

as well as an expression for $\varepsilon_2$ for direct-gap semiconductors like SWNTs. The corresponding real dielectric, $\varepsilon_1$ (for refractive processes) can be further calculated through substitution of $\varepsilon_2$ into the Kramers-Kronig relations.[3] Summing over all transitions $k$ one obtains,

\[
\varepsilon_2(\omega) = \left( \frac{2\pi \hbar e}{\omega m} \right)^2 \sum_k |\hat{e} \cdot \mathbf{M}_{nn'}(k', k)|^2 \frac{\delta (E_{n'k'} - E_{nk} - \hbar\omega)}{2} \tag{3.7}
\]

\[
\varepsilon_1(\omega) = 1 + 4\pi \hbar c \sum_k \left( \frac{2|\hat{e} \cdot \mathbf{M}_{nn'}(k', k)|^2}{m(E_{n'k'} - E_{nk})} \right) \frac{1}{(E_{n'k'} - E_{nk})^2 - (\hbar\omega)^2}
\]

In equation 3.7 above, the first term in the sum is a dimensionless value that accounts for all the allowed dipole transitions, and is commonly referred to as the oscillator strength ($f_{E_{nk}}$),

\[
f_{E_{nk}} = \frac{2|\hat{e} \cdot \mathbf{M}_{nn'}(k', k)|^2}{m(E_{n'k'} - E_{nk})}. \tag{3.8}
\]

One meaningful interpretation of a material’s oscillator strength is that it is a measure of the number of dipole oscillators with energy $E_{n'k'} - E_{nk}$.[6] Thus the oscillator strength $f_{E_{nk}}$ is intrinsic to a particular material and accounts for the large variation in linear dielectric constants observed in condensed phase. Owing in part to the sheer number of carbon atoms (calculated in chapter 2 to be $\sim 5.5 \times 10^4$ atoms for most SWNTs in this dissertation), and the large absorption cross section per nanotube atom ($5.5 \times 10^{-17}$ cm$^2$), carbon nanotubes have an inherently large linear absorption response. In the next section, the non-linear absorption response will be examined.
3.2.2 Nonlinear optical response

In developing the quantum mechanical description for the linear absorption in direct band gap semiconductors like SWNTs, higher order process such as two-photon absorption were neglected. In this section, higher orders are included by expanding the system wavefunction \( \psi(r,t) \) in the form of a power series,

\[
\psi(r,t) = \psi^{(0)}(r,t) + \psi^{(1)}(r,t) + \psi^{(2)}(r,t) + \ldots \tag{3.9}
\]

For any desired order \( N \), \( \psi^{(n)}(r,t) \) can then be solved for perturbatively by again invoking the electric dipole approximation Hamiltonian \( H_i \approx \frac{e}{mc} \mathbf{A} \cdot \mathbf{p}_i \approx \mu \cdot \mathbf{E} \), and expanding the wavefunction in real space as,

\[
\psi^{(n)}(r,t) = \sum_l a_l^{(n)}(t) u_l(r) e^{-i\omega_l t} \tag{3.10}
\]

The wavefunction is then substituted into the Schrödinger equation (below) and results up to some arbitrary order \( N \) can be solved for iteratively, i.e.

\[
i \hbar \frac{\partial \psi^{(n)}(r,t)}{\partial t} = H_0 \psi^{(n)}(r,t) + H_i \psi^{(n-1)}(r,t)
\Rightarrow i \hbar \sum_l \frac{\partial a_l^{(n)}(t)}{\partial t} u_l(r) e^{-i\omega_l t} = \sum_l a_l^{(n-1)}(t) H_i u_l(r) e^{-i\omega_l t}. \tag{3.11}
\]

Multiplying the both sides above by the orthonormal wavefunction \( u_m^* \) we obtain,

\[
\frac{\partial a_m^{(n)}(t)}{\partial t} = (i\hbar)^{-1} \sum_l a_l^{(n-1)}(t) \langle u_m | H_i^\dagger | u_l \rangle e^{-i\omega_m t}. \tag{3.12}
\]

The coefficients \( a_m^{(1)}(t) \) for the first order wavefunction can be calculated by simple integration.[4, 2] The second (and higher) orders can then be obtained by iterative substitution back into equation 3.12, i.e.

\[
a_m^{(1)} = \frac{1}{\hbar} \sum_q \langle u_m | H_i^\dagger | u_q \rangle e^{i(\omega_m - \omega_q) t}
\Rightarrow a_m^{(2)} = \frac{1}{\hbar^2} \sum_q \sum_r \sum_m \langle u_m | H_i | u_r \rangle \langle u_r | H_i^\dagger | u_q \rangle e^{i(\omega_m - \omega_q - \omega_r) t} \tag{3.13}
\]

Equations 3.13 and 3.10 provide an expression for the second and first order wavefunctions \( \psi^{(1)} \) and \( \psi^{(2)} \), from which the second order nonlinear susceptibility can be calculated from the corresponding second order polarization \( P^{(2)} \),

\[
P^{(2)} = N \left( \langle \psi^{(0)} | \mu | \psi^{(2)} \rangle + \langle \psi^{(1)} | \mu | \psi^{(1)} \rangle + \langle \psi^{(2)} | \mu | \psi^{(0)} \rangle \right). \tag{3.14}
\]

Where here polarization is defined up to an arbitrary order with respect to the dipole operator \( \mu \), i.e., \( P \equiv N \langle \psi | \mu | \psi \rangle = P^{(1)} + P^{(2)} + \ldots \). [4] Inserting in the calculated 0th, 1st and 2nd order
wavefunctions into equation 3.14, and making the substitution (which is permissible under
the sum) that \( \omega_q \rightarrow -\omega_q \) and \( \omega_r \rightarrow -\omega_r \) we obtain,

\[
P^{(2)} = \left( \frac{N}{\hbar^2} \right) \sum qr \sum mn \left( \langle u_q | \rho | u_n \rangle \langle u_n | H^I | u_m \rangle \langle u_m | H^I | u_q \rangle \right) + \frac{\langle u_n | H^I | u_q \rangle \langle u_q | \mu | u_m \rangle \langle u_m | H^I | u_q \rangle}{(\omega_{ng} - \omega_q - \omega_r)(\omega_{mg} - \omega_q)} + \frac{\langle u_n | H^I | u_q \rangle \langle u_q | \mu | u_m \rangle \langle u_m | H^I | u_q \rangle}{(\omega_{ng} + \omega_r)(\omega_{mg} - \omega_q)} \]

(3.15)

The the second order polarization depends on the product of the applied \( E \)-fields i.e., \( P^{(2)}_i = \sum_{j,k,l=x,y,z} \chi^{(2)}_{ijk} E_j E_k \).[4] As a consequence, the second order susceptibility can be read off immediately by dividing out the \( E \)-field contribution. Preforming this division and further assuming that the incident fields have identical frequencies (i.e., \( \omega = \omega_q = \omega_r \)), we obtain,

\[
\chi^{(2)}_{ijk}(\omega) = \left( \frac{N}{\hbar^2} \right) \sum mn \left( \frac{\mu^I_{nm} \mu^I_{mk} \mu^I_{mn}}{(\omega_{ng} - 2\omega)(\omega_{mg} - \omega)} + \frac{\mu^I_{nm} \mu^I_{mk} \mu^I_{mn}}{(\omega_{ng} + \omega)(\omega_{mg} - \omega)} \right) + \frac{\mu^I_{nm} \mu^I_{mk} \mu^I_{mn}}{(\omega_{ng} + \omega)(\omega_{mg} + 2\omega)} \]

(3.16)

where \( \mu_{gn} \equiv \langle u_n | H^I | u_m \rangle \). From the above expression it is observed that the second order nonlinear susceptibility tensor is resonantly enhanced both at the resonant frequency (\( \omega_g = \omega \)) and at half the transition frequency (\( \omega_g = 2\omega \)). The process is often employed as sum-frequency generation for materials with large \( \chi^{(2)} \).[4, 3] Using the same derivation, analogous expressions for \( \chi^{(3)} \) can also be formulated; which is the fundamental quantity enabling the four-wave mixing spectroscopic techniques used in this dissertation.

### 3.3 Nonlinear Spectroscopy

#### 3.3.1 Intensity induced non-linearity

The linear dielectric function adequately describes a material’s optical response under normal room light conditions, but will deviates markedly under high-fields (\( |E| > \sim 10^6 \text{ V/cm} \).[4] In this regime, the approximation that the total dielectric function is independent of the magnitude of the incident field breaks down, and the nonlinearity (\( \epsilon_{NL} \)) becomes significant.

\[
\epsilon_{tot} = \epsilon + \epsilon_{NL} \cdot E \]

(3.17)

To see this dependence more explicitly it is useful to do a power series expansion of the total polarization in terms of the applied field,

\[
P = \chi^{(1)} E + \chi^{(2)} EE + \chi^{(3)} EEE + \ldots \]

(3.18)
where here $\chi^{(1)}$ is the linear susceptibility tensor, $\chi^{(2)}$ and $\chi^{(3)}$ are the second and third order nonlinear susceptibility.\[4\] Higher-order nonlinear terms in the expansion become significant with increasing incident $E$-fields. For typical incident laser intensities investigate in this manuscript, only the third-order nonlinear susceptibility plays a dominant role. While the second order term in equation 3.18 should give the larger contribution, it vanishes identically for all centrosymmetric materials since $P^{(2n)}(E) = \chi^{(2)}(-E)(-E) = P^{(2n)}(-E)$. For expansion terms that are odd-order in $E$ like $P^{(3)}$, a measurable response can be expected for sufficient applied field, as the sign change within the $E$-field will distinguish between the forward and reverse induced polarization processes.\[4\]

The magnitude of the nonlinear susceptibility tensorial elements determines the threshold intensity required for a particular polarization order to become significant in magnitude. For a centrosymmetric solid state system such as SWNTs, generally only the first and third order susceptibility need to be considered; all other orders either vanish under symmetry or will be statistically weak. Much like $\chi^{(1)}$, the fourth rank tensor $\chi^{(3)}$ must account for all possible Cartesian directions of the three applied $E$-fields and can be written as,

$$P^{(3)} = \epsilon_0 \sum_{j,k,l=x,y,z} \chi^{(3)}_{ijkl} E_j E_k E_l.$$

(3.19)

Up to 81 different tensorial components of $\chi^{(3)}_{ijkl}$ are possible, however symmetry greatly reduces the components required to just a few elements,\[4\] that are required to explain the four-wave mixing spectroscopic techniques outlined in the subsequent sections.

### 3.3.2 Time-domain nonlinear spectroscopy

The work presented in this dissertation chiefly concerns time-resolved optical measurements. The experimentally controlled parameters are multiple applied fields ($E(t)$), in the form of ultrashort laser pulse (20 to 100 fs) that interact with a nanotube sample to produce the scattered third-order polarization field given by equation 3.19. By exploiting the properties of Fourier transform, the formalism for nonlinear processes developed in frequency domain, can be re-cast to describe time-dependent spectroscopic measurements.\[8, 10\] For example, in a first order process, $\chi^{(1)}(\omega)$ from equation 3.7, can be written as the Fourier transform of time-domain response function, $R^{(1)}(t)$, i.e.

$$\chi^{(1)}(\omega) = \int_0^\infty d\tau R^{(1)}(\tau) e^{i\omega\tau}.$$  

(3.20)

The integration is from 0 to $\infty$, since by the principle of causality, before the applied electric field, $R^{(1)}(\tau) = 0$ for $\tau < 0$.\[2\] Inserting this susceptibility into equation 3.18, and absorbing the phase into applied $E$-field we obtain,

$$P^{(1)}(t) = \int_0^\infty d\tau R^{(1)}(\tau) E(t - \tau).$$  

(3.21)
The resulting expression provides the first-order polarization produced at a time $t$, from an applied electric field (laser pulse) that interacted with a system at a time $t - \tau$. This time-dependent formalism can be extended by analogy to polarizations of any order. In particular, the third-order susceptibility derived in equation 3.16, may be expressed as the Fourier transform of a time-dependent third-order response function $R^{(3)}(\tau_1, \tau_2, \tau_3)$,

$$
\chi^{(3)}(\omega, \omega_2, \omega_3) = \int_0^\infty d\tau_1 \int_0^\infty d\tau_2 \int_0^\infty d\tau_3 R^{(3)}(\tau_1, \tau_2, \tau_3) e^{i(\omega_1 \tau_1 + \omega_2 \tau_2 + \omega_3 \tau_3)}. \quad (3.22)
$$

Inserting $\chi^{(3)}$ into equation 3.18 and absorbing the phase constants into the respective electric fields, the third-order polarization may be written as,

$$
P^{(3)}(t) = \int_0^\infty d\tau_1 \int_0^\infty d\tau_2 \int_0^\infty d\tau_3 R^{(3)}(\tau_1, \tau_2, \tau_3) E(t - \tau_1) E(t - \tau_2) E(t - \tau_3). \quad (3.23)
$$

The resulting expression depends upon the time-ordered delays ($\tau_1, \tau_2$ and $\tau_3$) of the three applied $E$-fields pulses, and the material’s third-order susceptibility which is effectively embedded in $R^{(3)}$. [8]

### 3.3.3 Four-wave mixing spectroscopy

The third-order polarization $P^{(3)}(t)$ expressed in equation 3.23 is often called a four wave mixing process. Three of these four "waves" refer to the applied $E$-fields, which in our case are temporally delayed femtosecond laser pulses labeled by their corresponding wavevectors $k_1$, $k_2$ and $k_3$. [8, 2] The fourth wave is the $P^{(3)}$ polarization labeled $k_s$, which scatters into momentum conserving directions of the combined incident pulses, i.e. $k_s = \pm k_1 \pm k_2 \pm k_3$. This scattered $P^{(3)}$ polarization, is refereed to as a photon echo when obtained with certain pulse time orderings such as those diagrammed in figure 3.2. To follow the time evolution of the quantum states involved, double-sided Feynman diagrams provide a convenient representation. As the applied fields ($k_1$, $k_2$ and $k_3$) interact with the initial ground state density matrix, denoted $\rho = |g\rangle \langle g|$, state transitions will be induced to either an excited-state coherences such as $|e\rangle \langle g|$ or a population state such as $|e\rangle \langle e|$. The temporal evolution is represented by progression along the vertical axis. The arrows if figure 3.2 corresponds to $E$-field interactions with the density matrix; incoming arrows represent absorption, and upward pointing outgoing arrows represent photon emission. The wavy arrow $k_s$ is an emissive $P^{(3)}$ polarization, and represents the trace operation over the time-dependent density matrix. [8]

The different pathways shown in figure 3.2 can be selectively measured by controlling the laser pulse time-ordering. Varying the population time ($T$, between $k_2$ and $k_3$) for instance can provide either transient grating (TG) or pump probe signals to measure the excited state lifetime and population dynamics. In contrast, scanning the coherence time ($\tau$), provides the two-pulse photon echo (2PE) measurements, which provide the timescale of optical
decoherence or dephasing. In a three pulse echo (3PE) experiment both the population and coherence times can be independently controlled.

Typically, the decay of an optical coherence (e.g. $|e\rangle \langle g|$) during time $\tau$ corresponds to a free-induction decay. To instead detect of the stimulated photon echo ($SPE$) signal, the two coherence states shown in figure 3.2b and c must be complex conjugates of each other (i.e. $|e\rangle \langle g|$ and $|g\rangle \langle e|$), this causes a collective rephasing process in the ensemble of coherently excited chromophores, producing a macroscopic echo signal in direction $k_s$ (see figure 3.3). Full details describing $SPE$ and optical rephasing are discussed extensively in the literature,[11, 12, 13, 8] and are applied here to carbon nanotubes for the first time.

### 3.3.4 Four-wave mixing experiments; pump-probe to 2D electronic

The basic experimental configuration for a four wave-mixing experiment is shown schematically in figure 3.3. The applied laser pulses are temporally delayed by times $\tau$ and $T$, and overlap at the sample position to produce a scattered $P^{(3)}$ polarization field. Only the pulse combinations which produce a $SPE$ give rise to macroscopic nonlinear signals such as those depicted in figure 3.3 showing 3PE signals emerging in the directions $k_s = \pm (k_1 - k_3) + k_2$ from an SWNT sample. Additionally, 2PE signal are also observed in the $-k_1 + 2k_3$ and $-k_2 + 2k_3$ directions.

In this dissertation four-mixing experiments on SWNTs are conducted by measuring the
time-dependent intensity of the integrated $P^{(3)}(t)$ signals that are scattered into the different directions of $\mathbf{k}_s$. For measurements using a homodyne detection scheme, the collected signal ($S_{\text{SPE}}$) is simply the time-integrated response,

$$S_{\text{SPE}}(\tau, T) = \int_{0}^{\infty} dt |P^{(3)}(t)|^2$$

of the scattered signal, measured at the variable time delays $\tau$ and $T$.\[10\] Alternatively, an analogous heterodyne measurement ($S_{\text{HSPE}}$) is obtained by interfering the scattered polarization with a local oscillator $E_{\text{LO}}$. In contrast to the homodyne case, the signal strength is linearly proportional to $E_{\text{LO}}^*$, and is given by,

$$S_{\text{HSPE}}(\tau, T) = -2\text{Im} \int_{-\infty}^{\infty} dt E_{\text{LO}}^*(t - T) P^{(3)}(t).$$

Such a detection scheme is commonly used in transient absorption spectroscopy. For transient absorption, the resulting spectrum $\Delta A(t, \lambda)$ is be expressed as \[14, 15\],

$$\Delta A(t, \lambda) \propto n(t) [\sigma^{\text{ESA}}(\lambda) - \sigma^{\text{SE}}(\lambda) - \sigma_0(\lambda)],$$

where $\sigma_0(\lambda)$ is the ground state absorption spectrum ($\lambda$ is the wavelength of the probe pulse), and $\sigma^{\text{ESA}}(\lambda)$ and $\sigma^{\text{SE}}(\lambda)$ are the cross-sections for excited state absorption and stimulated emission processes respectively.\[15, 8\] Unlike the homodyne detection case, pump interference with the local oscillator preserves both signal amplitude and phase. Such additional is information is particularly valuable for spectrally resolved measurements.

In chapter 12, spectrally resolved heterodyne detection is preformed on 3PE signals to produce a two-dimensional (2D) electronic spectrum for semiconducting SWNTs. Two-dimenensional Fourier-transform electronic spectroscopy is powerful technique that gives a
real-time picture of how an optical excitation distributes itself among its associated exciton states.[16] For SWNTs, this measurement characterized the lineshapes and dynamics of the $E_{22}$ exciton manifold (see chapter 12).

3.4 Modeling Condensed Phase Dynamics

Upon optical excitation in SWNTs, strongly-bound electron-hole pairs or excitons are created, which initially have a fixed phase relationship amongst all the carbon atoms.[15] With time, the individual motions of the carbon atoms disrupts this phase relationship and causes the excitation to become localized within the nanotube. In condensed phase, such exciton-phonon coupling processes are commonly modeled by a two-level system that is linearly coupled to a phonon bath of harmonic oscillators.[8, 17] Following the first pulse interaction, the system is converted into a coherence which will oscillate at the system optical transition frequency $\omega_{eg}$. In response to the coupled phonon bath, decoherence occurs over time $\tau$, causing $\omega_{eg}(t)$ to fluctuate by an amount $\delta\omega_{eg}(t)$ (see figure 3.4). As such, the time-domain transition frequency for each member $i$ of the molecular ensemble can be expressed as,

$$\omega_{i,eg}(t) = \langle \omega_{eg} \rangle + \delta\omega_{i,eg}(t) + \sigma_{i,inhomo} \quad (3.27)$$

where $\langle \omega_{eg} \rangle$ is the average transition energy within the ensemble and $\sigma_{i,inhomo}$ is the static frequency offset accounting for the different local environments of each absorbing chromophore.[18, 10] In figure 3.4, the right panel depicts three chromophores oscillating in phase($\omega_{eg} = \omega_{1,2,3}$) at $\tau = 0$, before each receives multiple perturbations in phase by amount $\delta\omega_{i,eg}$ in response to applied nuclear fluctuations. When all the component of ensemble are added, we obtain $\sum_i \delta\omega_{i,eg}(t) = \langle \omega_{eg}(t) \rangle$ whose phase envelope will decay exponentially for a strongly inhomogeneously broadened system at rate of $\exp(-4\tau/T_2)$.[19] As such, measurement of the photon echo signal ($S_{SPE}(\tau)$) permits extraction of the optical dephasing time ($T_2$) for 1/e of the coherently created excitations to dephase from electron-phonon coupling. $T_2$, thus becomes not only a measure on the exciton-phonon coupling strength, but also directly provides the spectral homogeneous spectral linewidth ($\Gamma_h = 2\hbar/T_2$).[19]

Alternatively, the transition frequency can be expressed in terms of a correlation function, $M(t)$

$$M(t) = \frac{\langle \delta\omega_{eg}(t)\delta\omega_{eg}(t) \rangle}{\langle \delta\omega_{eg}^2 \rangle} \quad (3.28)$$

As $t \to \infty$, the ensemble of chromophores will loose all frequency correlation due to exciton-phonon coupling, causing $M(t) \to 0.[9, 10, 20]$ In later chapters this correlation function will be extracted from experimental results using 3PE peak-shift spectroscopy.[18, 21, 9] In order to simulate $M(t)$, the Spin-Boson Hamiltonian ($H_{HO} = H_o + H' = |g\rangle H_g \langle g | + |e\rangle H_e \langle e | + H'$) couples the electronic Hamiltonian $H_o$ to a bath of harmonic oscillators given by $H'$. Application the fluctuation-dissipation theorem and statistical principles are then used to relate $H_{HO}$ directly to the time-correlation function $M(t).[8, 10, 13, 22]$ From $M(t)$, various
Figure 3.4. In SWNTs, the coherently excited $E_{11}$ state ($\omega_{ge}$) fluctuates in response to the phonon bath (left), these fluctuations cause decoherence over a time period $\tau$ (center). The coherent oscillations associated with each member of ensemble couple to the photon bath. When added together, the phase envelope $\langle \omega_{eg}(t) \rangle$ loses coherence exponentially for inhomogeneously broadened systems (right).

Optical processes can be readily characterized from linear absorption to electron-phonon coupling strengths and timescales.[9]

$M(t)$ is also related to the lineshape function, $g(t)$ under the assumption that electron-phonon coupling can be modeled as multimode bath of harmonic oscillators linearly coupled to a two-level system (by a Langevin like equation, for example).[9] Using this approximation, it can be shown that

$$g_i(t) = \langle \delta \omega_{i,eg}^2 \rangle \int_0^t dt_1 \int_0^{t_1} dt_2 M_i(t_2) - i \lambda_i \int_0^t dt_1 (1 - M_i(t_1))$$

(3.29)

where $\sqrt{\langle \delta \omega_{i,eg}^2 \rangle}$ is the electron-phonon coupling strength, and $\lambda_i$ is associated reorganizational energy with respects to the nuclear modes (commonly given as one half the total Stokes’ shift). At high temperatures, when the phonon bath heavily populated, $\langle \delta \omega_{i,eg}^2 \rangle \approx 2 \lambda_i k_b T$, where $k_b T$ is the Boltzmann thermal population.[8]

In more complex systems like SWNTs, multiple harmonic baths are required to sufficiently model $M(t)$, and so the total lineshape function becomes, $g(t) = \sum_i g_i(t)$. The spectral density is embedded in $g(t)$, and is can be shown that the real part of $g(t)$ gives the homogeneous spectral broadening from electron-phonon coupling, and the imaginary part provides the phonon induced spectral shift (e.g. Stokes’s shift).[9, 8] As consequence,
knowledge of \( g(t) \) and any inhomogeneous broadening is sufficient to provide the complete lineshapes of the linear absorption \( \sigma_{\text{Abs}}(\omega) \) and photoluminescence \( \sigma_{\text{Em}}(\omega) \) spectra [9, 8],

\[
\sigma_{\text{Abs}}(\omega) = \frac{1}{\pi} \text{Re} \int_{0}^{\infty} dt \exp \left[ i(\omega - \omega_{eg})t \right] \exp \left[ -g(t) \right] \tag{3.30}
\]

\[
\sigma_{\text{Em}}(\omega) = \frac{1}{\pi} \text{Re} \int_{0}^{\infty} dt \exp \left[ i(\omega - \omega_{eg} - 2\lambda)t \right] \exp \left[ -g^*(t) \right]. \tag{3.31}
\]

Knowledge of \( g(t) \) is also sufficient to calculate the third-order response functions \( R_i^{(3)} \), and hence \( P^{(3)} \) by equation 3.23. Obtaining the explicit forms for these relations, requires carrying out a cumulant or Magnus expansion on response function \( R^{(3)}(\tau_1, \tau_2, \tau_3) \), and is discussed in the literature in detail (see [9, 8] for example). In later chapters, the time-dependent photon echo signal \( S_{\text{SPE}}(\tau, T) \) will be collected on semiconducting SWNTs, permitting the extraction of quantities such as \( M(t) \), the homogeneous lineshape, and exciton-phonon coupling strength.

### 3.5 Summary and Outlook

The discovery in 2005 that semiconducting carbon nanotube spectroscopy is determined by stable exciton states, radically changed the understanding of the nanotube electronic structure and photophysics.[23, 15] While much progress has been made, there is still little clarity on basic questions, like the precise timescales and states involved in optical relaxation. Another significant bottleneck for carbon nanotube application development, is the still unexplained low fluorescence efficiency, and unknown exciton delocalization length. Measuring quantities such as the optical dephasing time using photon echo spectroscopy, permits selective access to the dynamics of coherent excitons, providing a fundamental basis to help tackle these questions.

In this dissertation, non-linear spectroscopy is employed as an incisive tool to time-resolve the journey from optical excitation to relaxation. In this chapter, we reviewed some the established principles of non-linear spectroscopy to enable the experiments which follow in the subsequent chapters. Beginning with Schröedinger equation, the linear \( (\chi^{(1)}) \) and non-linear \( (\chi^{(3)}) \) susceptibilities are derived in both the frequency and time-domain. The resulting expression for the third-order polarization \( P^{(3)}(t) \) is then recast to describe various nonlinear spectroscopic processes such as the stimulated photon echo. Lastly, system-bath interactions were introduced by coupling the \( E_{11} \) transition to a bath of multimode harmonic oscillators to provide a complete model for the spectral dynamics of highly disordered systems such as semiconducting SWNTs.
3.6 References


Chapter 4

Femtosecond Infrared Spectroscopy Reveals Transient Mid-IR States

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Femtosecond mid-infrared spectroscopy was applied to study the vibrational spectra and dynamics in the electronic excited-states of semiconducting single-walled carbon nanotubes. The experiments were performed by exciting the SWNTs dispersed individually in polymethylmethacrylate and polyvinyl alcohol polymer films with 40 fs laser pulses at 800 nm, and the resulting responses were monitored with broadband mid-infrared pulses ranging from 1510 to 1670 cm\(^{-1}\). The structured spectra observed show vibrational bands with up-shifted frequencies by 10-50 cm\(^{-1}\) with respect to their ground state counterparts. The observation provides direct evidence for the theoretically predicted lattice distortions in the electronic excited-state. Analysis of the kinetics probed in the mid- and near-infrared regions provide an estimate of the time scales for the vibrational relaxation.

4.1 Introduction

The remarkable electronic properties of single-walled carbon nanotubes (SWNT) have stimulated enormous interests in studying their fundamental physics using both frequency- and time-domain spectroscopic methods (for an overview, see recent reviews\(^1\text{--}^5\)). Over the past a few years, application of ultrafast spectroscopy has revealed important information on fundamental dynamics, such as electron-phonon scattering, exciton-exciton annihilation,
intrinsic relaxation and some extrinsic effects (see the review by Ma et al. and the references therein). However, all these studies have been primarily focused on electronic excited-states.

It has been predicted theoretically that creation of an exciton in a semiconducting SWNT leads to a long-ranged distortion in its lattice. The resulting change in the bond length in the electronically excited SWNT can lead to different vibrational frequencies from the corresponding ground-state. The transition from this distorted lattice to a new equilibrium lattice geometry or vibrational relaxation in the electronically excited-state can further have profound effects on the relaxation of the electronic excited-state itself. This suggests that vibrational relaxation in the electronically excited-states is an integral part of the overall dynamical process. In this paper, we report a femtosecond mid-IR spectroscopic study on the vibrational spectra and dynamics of electronically excited semiconducting SWNTs.

4.2 Experimental Details

The experiments were performed on ~100 µm thick films of SWNTs fabricated using either polymethylmethacrylate (PMMA) or polyvinyl alcohol (PVA) as the embedding matrix. Both polymers have good transmission in the mid-IR region necessary for the transient absorption (TA) measurements. Our starting material was a commercial H₂O suspension of CoMoCAT SWNTs (SouthWest Nano Tech.), which were dispersed individually with sodium dodecylbenzene sulfonate (NaDDBS) as a surfactant. The linear absorption spectra of these films and the starting aqueous solution are shown in Fig. 4.1. Although the spectra of the films exhibit a noticeable shift and a background change with respect to the solution spectrum, the main features associated with both the lowest and the second dominant exciton transitions (E₁₁ and E₂₂) of the two most abundant tube types, the (6, 5) and (7, 5) tubes, are unchanged. This excludes the occurrence of any significant tube aggregation, which would have substantially washed out these distinct features. This conclusion is further supported by the observed steady-state fluorescence emission spectra with a clearly weaker emission around 1150 nm than from those dominant tube species (data not shown). Measurement of the fluorescence emission and excitation spectra further enabled us to determine the E₁₁ (and E₂₂) transition wavelengths for both the (6, 5) and (7, 5) nanotubes. For the SWNT/PMMA film we found 1004 and 1034 (572 and 647) nm, respectively. Blank PMMA and PVA films with NaDDBS surfactant were also prepared in order to experimentally quantify their potential contributions to the TA signals in the spectral region of interest.

We employed a light source that consists of a 1 kHz Ti:Sapphire regenerative amplifier and a mid-IR optical parametric amplifier (OPA). The former produces 800 nm pulses with typical duration of 40 fs (full-width at half maximum, FWHM), whereas the latter generates short pulses tunable between 3 and 7 µm (3300-1400 cm⁻¹) with a duration of 95 fs (FWHM) at 5 µm and a pulse energy of 1-2 µJ. The 800 nm pulses were used as the pump beam, and induced changes of sample absorbance were monitored with broadband mid-IR pulses. The detection system involves a Triax 180 imaging spectrometer with 4 cm⁻¹ resolution, and
Figure 4.1. Linear absorption spectra of the aqueous suspension of CoMoCAT nanotubes (dotted line) and the nanotube films, which were prepared using this solution and PVA (dashed line) and PMMA (solid line) polymers.

a 64-element HgCdTe dual-array detector attached to an IR64-16 multichannel laser pulse integrator system. The pump beam was focused to a spot of \(~200\ \mu m\) on the sample, and its polarization was set parallel to the probe beam. For a detailed description of the light source and the experimental setup, see ref. 14. The near-IR TA data were collected using a setup that consists of a 250 kHz Ti:Sapphire regenerative amplifier and a visible OPA. We refer to our previous papers for the experimental details.\textsuperscript{15,16}

4.3 Results and Discussion

We found that a pump pulse intensity ranging from 0.64 to 3.2 mJ/cm\(^2\) was necessary to acquire data with a satisfactory signal-to-noise ratio. Representative TA spectra recorded at a pump intensity of 2.5 mJ/cm\(^2\) using the SWNT/PMMA film are shown in Fig. 4.2a. The TA spectra show positive-signed, induced absorption in the entire probe spectral region (1510 to 1670 cm\(^{-1}\)) with several distinct features. Besides the broad band peaking around 1600 cm\(^{-1}\), distinct sidebands with peaks located at 1563 and 1633 cm\(^{-1}\) are prominent. Comparison of the TA spectra measured at other five pump intensities (0.38, 0.70, 1.12, 1.98 and 3.33 mJ/cm\(^2\)) shows that, upon normalizing at the maxima of the \(a\) bands, the spectral shape observed at any given delay time is independent of intensity. This invariance consequently leads to dynamics that are independent of pump intensity at all probe frequencies. As an example, Fig. 4.2b shows the normalized kinetic profiles obtained at 1603 cm\(^{-1}\) under
two different pump intensities. Fitting the kinetics by employing a sum of exponential terms as a model function and by taking into account the finite duration of the pump and probe pulses gives the following timescales (relative amplitudes): 0.21 ps (0.63), 1.66 ps (0.30) and 81 ps (0.07). Note that 81 ps is a rough estimate for the timescale of a long-lived decay component that persists over the entire range of our scan (700 ps). The maximum magnitude of the TA signal is further found to increase with pump intensity in a nonlinear, saturating manner (Fig. 4.2c). The independence of the kinetic decay on pump intensity (Fig. 4.2b) and the saturating behavior of its signal magnitude with increasing intensity (Fig. 4.2c) are qualitatively similar to what has been found in the near-IR region where the $E_{11}$ transition of selected semiconducting SWNTs is probed following its direct optical excitation.\(^{15}\)

Although the PMMA and PVA polymers as well as the NaDDBS surfactant have absorption in the spectral region of our measurements, none of them should contribute to the observed TA signals. The reason is that they are not excited by the 800 nm pump pulse, and the finite absorption of the mid-IR probe pulse is already subtracted off in the obtained TA data. This is confirmed by our test measurements performed at a pump intensity of 3.68 mJ/cm\(^2\) on a reference PMMA film containing just the surfactant. The result shows weak transients around time zero with either positive- or negative-signed signals depending on the probe frequency, arising most likely from a pulse overlapping effect (data not shown). Also, the maximum magnitude of the detected signal is less than 1.5% of the signal maximum observed from the SWNT/PMMA film at a similar pump intensity (3.33 mJ/cm\(^2\)). We therefore neglect this weak signal in the rest of the paper. We further found that use of the PVA polymer does not cause any significant changes in both TA spectra and kinetics (as an example, see Fig. 4.3b,c), suggesting that the results obtained are intrinsic to nanotubes. Furthermore, both the spectral and kinetic features are found to be independent of sample position for the SWNT/PMMA and SWNT/PVA films, even though the magnitudes of the TA signals can vary considerably from one location to another.

The positive-signed TA signals observed indicate that they must originate from electronic excited-state(s). A transition from such excited-state(s) in the frequency region of our measurements, in principle, can be either electronic or vibrational depending solely on the nature of the final state(s). From an energetic point of view, an electronic, intra-band excitonic transition appears plausible because of the presence of an exciton-manifold above the $E_{11}$ state.\(^{17}\) However, the line-widths observed in the TA spectra are too narrow for such an intra-band excitonic transition. Due to the short lifetime associated with an excitonic state lying above the $E_{11}$ state, its involvement in the intra-band transition should result in a much broader spectrum than we observe. The well-studied $E_{22}$ state can serve as a typical example here - its lifetime was determined to be in the order of 50 fs for several semiconducting tube species.\(^{18,19}\) This short lifetime gives rise to a broad spectrum with a typical FWHM of 350 cm\(^{-1}\) or more.\(^{20,21}\) This is in stark contrast to the narrow line-widths of the observed TA spectra. Analysis of the TA spectrum measured at a delay time of 100 fs shows that the spectrum can be decomposed into five Gaussian components with peaks (FWHM widths) at 1562 (20.1), 1588 (22.2), 1607 (18.5), 1628 (13.5) and 1640 (33.3) cm\(^{-1}\), respectively (see Fig. 4.3b). The FWHM widths of the two major components peaking at 1588 and 1607 cm\(^{-1}\) are almost identical to the width of the G-band Raman spectrum measured using the same nanotube material in solution and embedded in polyvinylpyrrolidone (PVP) polymer
Figure 4.2. (a) Representative TA spectrum from 1554-1654 cm$^{-1}$, recorded at a pump intensity of 2.5 mJ/cm$^2$ at 800 nm. (b) The normalized ΔOD kinetic profiles obtained at 1603 cm$^{-1}$ under two different pump intensities: 0.61 mJ/cm$^2$ (black line) and 4.1 mJ/cm$^2$ (dark green line). (c) Plot of the maximum magnitude of the TA signal at 1603 cm$^{-1}$ as a function of pump intensity.
Table 4.1. Summary of the vibrational frequencies determined in this work and by Raman and infrared experiments.

<table>
<thead>
<tr>
<th>frequency(cm⁻¹)</th>
<th>state</th>
<th>method</th>
<th>material</th>
<th>reference</th>
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</thead>
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<td>1562</td>
<td>$E_{11}$</td>
<td>TA</td>
<td>individualized tubes</td>
<td>this work</td>
</tr>
<tr>
<td>1588</td>
<td>$E_{11}$</td>
<td>TA</td>
<td>individualized tubes</td>
<td>this work</td>
</tr>
<tr>
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<td>individualized tubes</td>
<td>this work</td>
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<td>isolated tubes</td>
<td>27</td>
</tr>
<tr>
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<td>Raman</td>
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</tr>
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<td>Raman</td>
<td>isolated tubes</td>
<td>27</td>
</tr>
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<td>Raman</td>
<td>isolated tubes</td>
<td>27</td>
</tr>
<tr>
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<td>Raman</td>
<td>isolated tubes</td>
<td>27</td>
</tr>
<tr>
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<td>24</td>
</tr>
<tr>
<td>1587</td>
<td>GS</td>
<td>IR</td>
<td>isolated tubes</td>
<td>25</td>
</tr>
</tbody>
</table>

Based on these considerations, we attribute the observed TA spectra to the transition between the levels of the tangential vibrations in the $E_{11}$ excited-state(s).

Among the five spectral components shown in Fig. 4.3b for the $E_{11}$ excited-state vibrations, three are characterized by a frequency that is up-shifted by 10-50 cm⁻¹ with respect to the frequencies of the electronic ground-state vibrations. Electronic ground-state vibrations have been a subject of extensive studies by resonant Raman spectroscopy at both single-tube and ensemble levels (see the review by Dresselhaus et al.²²). Fewer investigations based on theoretical²³ and experimental²⁴,²⁵ infrared spectroscopy have been also reported. In Table 4.3, we summarize the vibrational frequencies determined in this work (for the excited state) together with the ground state frequencies reported in the literature of Raman and infrared measurements. Although some variations exist in the results reported for the tangential vibrations, the frequencies found from a majority of work are below 1590 cm⁻¹. The clearly up-shifted frequencies observed in this work provide a direct evidence for the occurrence of a long-ranged lattice distortion in the electronic excited-state.⁶⁻⁸ We further speculate that the appearance of multiple spectral components as shown in Fig. 4.3b may be indicative of a bond-length variation in the distorted lattice. In the recent calculation by Tretiak et al.,⁷ a corrugated tube surface arising from alternative lengthening and shortening of bond-length was predicted for a semiconducting SWNT. Note that such a bond-length alternation may give rise to both down- and up-shifted vibrational frequencies compared to the ground state.

Analysis of the temporal evolution of the TA kinetics probed in the mid- and near-IR regions enables us to estimate the time scale of the vibrational relaxation in the $E_{11}$ state. Because the evolution of the mid-IR kinetics is governed by the relaxation from both the final vibrational state and the $E_{11}$ electronic state, the contribution from the electronic relaxation must be removed. For this purpose, we performed separate experiments in the
Figure 4.3. (a) Comparison of the TA spectra measured using the SWNT/PMMA (solid line) and SWNT/PVA (dashed line) films at a delay time of 100 fs. For ease of comparison, these spectra are scaled to equal amplitude at their maxima. (b) TA spectrum recorded for the SWNT/PMMA film at a delay time of 100 fs (symbols). The Gaussian components resulting from spectral deconvolution are shown as dashed lines and the fit spectrum is given by the solid line. The positions of the peaks are labeled on the figure.
Figure 4.4. (a) Comparison of the TA kinetics detected at 1603 cm$^{-1}$ (800 nm pump) (solid lines) and at 1018 nm (572 nm pump) (dashed lines) for the SWNT/PMMA film. For ease of comparison, the data collected at 1018 nm are inverted by multiplying (-1). The kinetic traces are normalized at the signal maxima. (b) The difference between the two kinetic profiles shown in (a) and its monoexponential decay fit (solid line).
near-IR region to characterize the exciton population relaxation from the $E_{11}$ state and the concomitant recovery of ground state. The dashed-line curve in Fig. 4.4 shows the data obtained by from the same SWNT/PMMA film at 1018 nm, the $E_{11}$ state of the (6, 5) tube, which is one of the dominant nanotube species in the sample. Selective detection of this particular tube type is accomplished by resonant excitation of its $E_{22}$ state at 572 nm. As is evident from Fig. 4.4a, the kinetic profile probed at 1603 cm$^{-1}$ exhibits a faster decay than the one measured at 1018 nm. The difference between these two kinetic profiles represents approximately the dynamics of the vibrational relaxation in the $E_{11}$ state. As shown in Fig. 4.4b, this difference kinetics can be well described by a single time scale of 4.4 ps. A similar value was also obtained for the data measured using the SWNT/PVA film. Note that this time scale should be considered as a rough estimate as the mid- and near-IR data were measured under electronically non-resonant and resonant conditions, respectively.

As a final remark, we briefly discuss the work of Zhao et al$^{26}$ that covers a similar spectral range. The authors reported a TA spectrum measured on a film sample prepared by dispersing the HiPco tubes into a PVA matrix. The published spectrum is very different from ours in terms of the overall shape, due to the use of different tube materials (HiPco vs. CoMoCAT) and different spectral resolution (4 cm$^{-1}$ in our case and roughly 160 cm$^{-1}$ in the case of ref. 26). The authors attributed this band to intra-band excitonic transitions from both the lowest optically allowed and dark excitonic states to some higher-lying ones.

### 4.4 Conclusions

In summary, we demonstrated in this report that femtosecond TA spectroscopy employing 800-nm pump and mid-IR probe enables to access the vibrational spectra and dynamics in the $E_{11}$ exciton states of semiconducting SWNTs. The observed induced absorption spectra exhibit prominent spectral structures, which can be decomposed into five Gaussian components. Three of these components are characterized by a frequency up-shifted by 10-50 cm$^{-1}$ with respect to the frequencies of the electronic ground-state vibrations. This observation provides a direct evidence for the occurrence of a long-ranged lattice distortion in the electronic excited-state. Analysis of the TA kinetics probed in the mid- and near-IR regions enables us to extract an approximate time scale for the vibrational relaxation. Further studies employing single tube enriched samples in combination with resonant excitation are expected to provide a more accurate determination of the time scales.
4.5 References


Chapter 5

Ultrafast Mid-Infrared

Intra-Excitonic Response

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We report a femtosecond mid-infrared study of the broadband low-energy response of individualized (6,5) and (7,5) single-walled carbon nanotubes. Strong photoinduced absorption is observed around 200 meV, whose transition energy, oscillator strength, resonant chirality enhancement and dynamics manifest the observation of quasi-1D intra-excitonic transitions. A model of the nanotube 1s-2p intra-excitonic cross section agrees well with the signal amplitudes. Our study further reveals a saturation of the photoinduced absorption with increasing phase-space filling of the correlated e-h pairs.

5.1 Introduction

The quasi-1D confinement of photoexcited charges in single-walled carbon nanotubes (SWNTs) gives rise to strongly enhanced Coulomb interactions and large exciton binding energies on the 100 meV energy scale. These amplified electron-hole (e-h) correlations are a key aspect of nanotube physics [1]. Following the availability of “individualized” SWNT ensembles, this strong excitonic behavior was independently confirmed by interband absorption-luminescence maps [2], two-photon excited luminescence [3, 4], and ultrafast spectroscopy [5]. Optical interband probes, however, are limited by symmetry and momentum to detect only a small subset of excitons.
As illustrated in Fig. 5.1(a) in a two-particle scheme, SWNT excitons are characterized by a center-of-mass momentum \( K \) and by an internal quantum state (designated here as \( 1s, 2s, 2p, \ldots \)) that accounts for the relative charge motion. Each state splits into even (g) and odd (u) parity levels corresponding to different superpositions of the cell-periodic wavefunctions of the underlying graphene lattice [4]. This entails a series of optically "dark" excitons, including the \( 1s \)-\( (g) \) lowest-energy exciton that lacks coupling in both single- and two-photon interband spectroscopy [3, 4]. Splitting into singlet and triplet spin states additionally restricts interband optical coupling [6]. Finally, interband transitions are limited to excitons around \( K \approx 0 \) due to momentum conservation.

*Intra-excitonic* transitions between low-energy levels of excitons with the same cell-periodic symmetry [arrows, Fig. 5.1(a)] represent a fundamentally different tool, analogous to atomic absorption spectroscopy. In contrast to interband absorption that measures the ability to *generate* e-h pairs, intra-excitonic absorption detects existing excitons via transitions from the \( 1s \) ground state to higher relative-momentum states [7, 8]. Being independent of \( K \), it is sensitive to genuine exciton populations across momentum space. As the cell-periodic component of the wavefunction remains unchanged, intra-excitonic absorption is also unrestricted by the exciton ground state symmetry [7]. Applied to individualized SWNTs,
intra-excitonic resonances can thus measure both bright and dark excitons and should occur in the mid-infrared (mid-IR) after ultrafast excitation. In contrast to extensive interband nanotube studies [9, 10, 11, 12], only a few ultrafast intra-band experiments have been carried out which focus largely on nanotube bundles [13, 14, 15, 16]. THz experiments on photoexcited bundled tubes revealed a non-Drude response attributed to small-gap metallic tubes or inter-tube charge separation [13, 14]. Mid-IR transient absorption was also observed in bundled nanotubes and assigned to transitions from allowed to dipole-forbidden excitons [15, 16].

In this Letter, we report ultrafast optical-pump, mid-IR-probe studies of individualized (6,5) and (7,5) SWNTs. Transient spectra after photoexcitation evidence strong mid-IR absorption around 200 meV, in accordance with intra-excitonic transitions of strongly-bound e-h pairs in semiconducting nanotubes. The absorption cross section of $4 \cdot 10^{-15} \text{cm}^2$ agrees closely with calculations of quasi-1D intra-excitonic 1s-2p dipole transitions presented here. The excitation-wavelength dependence and kinetics further underscore the excitonic origin of the transient mid-IR response, and its intensity dependence scales quantitatively with a model of phase-space filling expected for quasi-1D excitons. This intra-excitonic absorption represents a sensitive spectroscopic tool to probe correlated e-h pairs in SWNTs, unhindered by interband dipole or momentum restrictions.

5.2 Experimental Details

Ultrafast spectroscopy was carried out in transmission using widely tunable femtosecond (fs) pulses in the mid-IR and visible range. For this, two near-IR optical parametric amplifiers (OPAs) were pumped by a 1-kHz, 28-fs Ti:sapphire amplifier. Resonant and off-resonant interband excitation was achieved using the frequency-doubled OPA or a fraction of the fundamental. The output of the second OPA was difference-frequency mixed in GaSe to generate $\approx 100$ fs mid-IR probe pulses tunable from 4-12 $\mu$m [17]. We study individualized Co-Mo-catalyst grown SWNTs of mainly (6,5) and (7,5) chiralities [18] embedded in 50-μm thick polyethylene (PE). Importantly, PE ensures wide transparency throughout our mid-IR probe range, except for a narrow CH-bend vibration at 178 meV. The films were fabricated by drying PE solutions in decalin mixed with micelle-dispersed SWNTs, after transferring individualized SWNTs suspended in water with NaDDBS surfactant to the PE solution via ultrasound and thermal treatments. In Fig. 5.1(b), the sample’s photoluminescence (PL) spectra for resonant (6,5) and (7,5) $E_{22}$ excitation clearly exhibit the distinct $E_{11}$ emission of these individualized SWNT chiralities, with only weak emission from bundled tubes around 1160 nm [19]. The absorption spectrum [inset, Fig. 5.1(b)] also exhibits the distinct $E_{11}$ and $E_{22}$ absorption peaks.
Figure 5.2. (a)-(d) Ultrafast spectrally-resolved mid-IR transmission changes after 800 nm excitation for four different delays $\Delta t$ as indicated. The transient spectra are characterized by an asymmetric resonance that peaks above 160 meV and a low-frequency plateau measured down to 120 meV. Inset: normalized dynamics of the mid-IR transmission probed at 4.4 $\mu$m wavelength.
5.3 Results and Discussion

Ultrafast spectrally-resolved mid-IR transmission changes $\Delta T/T$ are shown in Fig. 5.2 for different time delays $\Delta t$ after 800 nm photoexcitation at room temperature. A strong photoinduced absorption appears within the time resolution after photoexcitation [Fig. 5.2(b), $\Delta t = 200$ fs] and decays on a ps timescale [Fig. 5.2(c)-(d)]. The transient spectra are characterized by a broadly sloping, asymmetric resonance around 200 meV, with a step-like onset above 160 meV. This mid-IR resonance occurs in the transparent region far below the lowest interband exciton ($E_{11} \simeq 1.2$ eV) and intersubband transitions ($E_{22} - E_{11} \geq 0.6$ eV). The peak energy is close to the (6,5) and (7,5) 1s-2p energy splitting in two-photon luminescence studies and calculations [3, 4, 20]. Thus, we associate this absorption with intra-excitonic transitions between 1s and 2p exciton levels of opposite parity. Both dipole-allowed and optically-dark 1s excitons can fundamentally contribute to this response. The dynamics exhibits a pulse-width limited rise of the photoinduced mid-IR absorption (inset, Fig. 5.2), which indicates rapid exciton formation.

We should comment on the asymmetric line shape observed in Fig. 2. The observed step-like onset points to a predominantly inhomogeneous broadening, and the asymmetry and large $\simeq 100$ meV width both agree well with similar spectral features observed in the analogous two-photon PL experiments [3, 4]. We attribute the higher-energy tail of the mid-IR response to intra-excitonic transitions from the 1s into higher-lying np bound states and into the broad continuum of unbound pairs. This assignment is consistent with the asymmetric intra-excitonic spectra of quasi-2D $e-h$ pairs [8]. Note that a much narrower peak seems to exist around 170 meV which we assign as an artifact [21]. Low-energy absorption is also observed below 160 meV which can arise e.g. from fluctuations of the dielectric environment around the nanotube and other chiral tube species associated with Co-Mo-catalyst-grown SWNT samples [22].

To further substantiate the nature of the response, Fig. 5.3(a) shows the excitation wavelength dependence. Resonant photoexcitation of the (6,5) and (7,5) interband $E_{22}$ transitions, at 572 nm and 697 nm respectively, leads to significant enhancement of the transient mid-IR absorption. The amplitude closely tracks the PL-excitation spectrum [Fig. 5.3(b)], which clearly underscores the tube-specific origin of the transient mid-IR response. This conclusion is further supported by the disappearance of the photoinduced signal for excitation below the $E_{11}$ transition [1250 nm, Fig. 5.3(a)]. Hence, the observed photo-induced absorption arises from intra-excitonic transitions of (6,5) and (7,5) SWNTs. The mid-IR dynamics after (6,5) $E_{22}$ excitation is shown in Fig. 5.3(c) on an extended timescale, revealing a strongly non-exponential decay [dots, Fig. 5.3(c)] over several 10 ps. The dynamics closely follows the $E_{11}$ exciton bleaching [solid line, Fig. 5.3(c)], confirming that the mid-IR signals originate from excitations in the $E_{11}$ manifold. Thermal broadening $k_B T \simeq 26$ meV at 300 K entails comparable occupation of dark and bright excitons (split by $\simeq 10$ meV), which enables this comparison. The decay has a bimolecular shape [dashed line, Fig 5(c)], similar to the fs kinetics of excitons in individualized SWNT suspensions explained by exciton-exciton annihilation [9], which further underscores the excitonic origin of the mid-IR response.

The mid-IR transmission changes can be used to estimate the absorption cross section
Figure 5.3. (a) Pump wavelength dependence on and off-resonant to the (6,5) and (7,5) $E_{22}$ transitions. Traces are offset for clarity, and measured at 4.4 $\mu$m with 260 $\mu$J/cm$^2$ excitation fluence. (b) PL-excitation spectrum for fixed $E_{11}$ emission at 1012 nm. (c) Normalized mid-IR dynamics (dots) after 572 nm excitation. Thick line: $E_{11}$ transmission change, scaled to the mid-IR signal at long delays. Dashed line: bimolecular decay $|\Delta T| \propto (1 + \gamma t)^{-1}$ with $\gamma = 1.5$ ps$^{-1}$. 
\( \sigma_{MIR}^{||} \) of the intra-excitonic transition, whose dipole is oriented parallel to the SWNT axis. It is defined as \( \sigma_{MIR}^{||} = 3 \ln(1 - \Delta T/T) / n_{exc} \), where \( \Delta T \) is the initial transmission change and \( n_{exc} \) the photoexcited density. The factor 3 accounts for the random SWNT orientation. Considering (6,5) \( E_{22} \) resonant excitation in Fig. 5.3(a) one has \( \Delta T/T \approx 1.7\% \) and \( n_{exc} = (F/\hbar \omega) \times \ln(10) A = 1.2 \times 10^{13} \text{ cm}^{-2} \); given \( F = 260 \mu \text{J/cm}^2 \) and \( A \simeq 0.007 \) [inset, Fig. 5.1(b)]. This yields the experimentally-derived value for the cross section of \( \sigma_{MIR}^{||} \approx 4 \times 10^{-15} \text{ cm}^2 \).

For comparison, we calculate the intra-excitonic 1s-2p cross section based on a model of Wannier-like excitons in SWNTs. The normalized 1s and 2p wavefunctions of Coulomb-bound \( e-h \) pairs on a cylindrical surface are [23]

\[
\psi_{1s}(x) = \frac{8}{(a_B^\ast)^3 \alpha_{1s}^3 B_{1s}} |x| e^{-\frac{|x|}{a_B^\ast}} U(1 - \alpha_{1s}, 2, \frac{2|x|}{a_B^\ast \alpha_{1s}}),
\]

\[
\psi_{2p}(x) = \frac{2}{(a_B^\ast)^3} x e^{-\frac{|x|}{a_B^\ast}},
\]

(5.1)

where \( x \) measures the distance along the nanotube axis and \( a_B^\ast = 4\pi \epsilon_0 \hbar^2 / \mu e^2 \) is the effective 3D Bohr radius with reduced mass \( \mu \) and permittivity \( \epsilon \). Furthermore, \( U \) is Kummer’s confluent hypergeometric function of the second kind and \( B_{1s} \equiv 2 \int_0^\infty y^2 e^{-y} [U(1 - \alpha_{1s}, 2, y)]^2 dy \) is a normalization constant. The binding energies are \( E_{1s} = -Ry^*/(\alpha_{1s})^2 \) and \( E_{2p} = -Ry^* \), where \( Ry^* \equiv \hbar^2 / (2\mu a_B^* \alpha_{1s}^5) \) is the 3D effective Rydberg energy. Also, \( \alpha_{1s} \) is a scaling parameter that depends on the SWNT nanotube radius \( r_{NT} \) via \( \ln(\alpha_{1s}) = -\Psi(1 - \alpha_{1s}, 2) - (2\alpha_{1s})^{-1} \equiv \ln(r_{NT}) - 2\Psi(1) \) where \( \Psi \) is the digamma function [23]. For the (6,5) and (7,5) SWNTs studied here, we have \( r_{NT} \approx 0.4 \text{ nm} \) which entails \( \alpha_{1s} = 0.33 \), and \( \mu \approx 0.067 \) from interpolated carrier effective masses [24].

The scale and shape of the resulting exciton wavefunctions are shown in Fig. 5.4(a). For this, the permittivity which depends on the local dielectric environment was adjusted to \( \epsilon = 6 \) to reproduce the intra-excitonic splitting \( E_{2p} - E_{1s} \approx 0.2 \text{ eV} \) from the experiment, which corresponds to a binding energy of 233 meV.

With the above wavefunctions, we obtain the 1s-2p intra-excitonic oscillator strength of quasi-1D excitons in SWNTs

\[
f_{1s \to 2p} \equiv \frac{128 \mu a_B^5 \alpha_{1s}^5 (E_{2p} - E_{1s})}{\hbar^2 B_{1s}} \times \left( \int_0^\infty s^3 e^{-s(1 + \alpha_{1s})} U(1 - \alpha_{1s}, 2, 2s) ds \right)^2
\]

(5.2)

For our specific parameters, \( f_{1s \to 2p} = 0.41 \). Transitions into higher bound \( np \) levels (\( n > 2 \)) were also calculated but are very weak and add less than 15% in spectral weight. The \emph{spectrally-integrated} absorption cross section is then determined as \( \sigma_{1s \to 2p}^{int} = 2\pi^2 e^2 / (4\pi \epsilon_0 \mu \epsilon n) \times f_{1s \to 2p} = 4.4 \times 10^{-13} \text{ cm}^2 \text{ meV} \), where \( n = 1.5 \) is the polymer refractive index. Spreading this absorption across \( \approx 100 \text{ meV} \) results in an estimated 1s-2p intra-excitonic cross section of \( \sigma_{1s \to 2p} \approx 4.4 \times 10^{-15} \text{ cm}^2 \), in very close agreement with our experiment. We
Figure 5.4. (a) Squared wavefunction amplitude $|\psi_{1s}(x)|^2$ compared to the (6,5) SWNT scale (left), and bare 1s and 2p wavefunctions (right). (b) pump fluence dependence of the initial mid-IR transmission change (dots) after resonant (6,5) $E_{22}$ excitation. Solid line: model explained in the text, dashed line: linear scaling (guide to the eyes).
note that full modeling of the observed, asymmetric mid-IR intra-excitonic line shape in Fig. 2 is beyond the scope of the Wannier-exciton model. However, the above illustrates a general consistency between the observed mid-IR signal amplitude and the quasi-1D 1s-2p intra-excitonic cross section, motivating more sophisticated theory to calculate bound-bound and bound-continuum spectra with chirality-specific SWNT wave functions.

The transient mid-IR absorption represents a strong oscillator comparable to the interband absorption. In the photoexcited state, this low-energy oscillator strength is derived via transfer from the interband exciton peaks, i.e. from \( E_{11} \) bleaching [10, 11]. As plotted in Fig. 5.4(b), with increasing excitation fluence, the mid-IR amplitude \( |\Delta T/T| \) exhibits a distinctly nonlinear behavior. This finding is well described by a saturation model \( \Delta T \propto 1 - e^{-F/F_s} \), shown as the solid line in Fig. 5.4(b) for \( F_s = 170 \, \mu J/cm^2 \). This corresponds to a 1D saturation density \( n_s = \sigma_{22}^\text{eff} \times F_s/\hbar \omega \), where \( \sigma_{22}^\text{eff} \) is the effective \( E_{22} \) absorption cross section per unit nanotube length. The cross section of (6,5) SWNTs was recently demonstrated as \( \sigma_{22}^\parallel \simeq 85 \, \text{nm}^2/\mu \text{m} \) for light polarized parallel to the nanotube axis, such that \( \sigma_{22}^\text{eff} = 1/3 \times \sigma_{22}^\parallel \) [25]. This yields from our experiment a saturation density \( n_s = 1.4 \times 10^6 \, \text{cm}^{-1} \) corresponding to an average exciton spacing \( d_{XX} \approx 7 \, \text{nm} \). The value is close to the saturation density extrapolated from \( E_{11} \) interband bleaching at lower densities [11], while surpassing the saturation of time-averaged PL by more than an order of magnitude [12]. The difference occurs since PL depends on density-dependent decay times that saturate at lower densities, while our study detects the initial pair density. For comparison, we consider phase-space filling (PSF), i.e. the increasing occupation of the constituent Fermion states of the exciton many-particle wavefunction [26]. The PSF density is given by \( N_s^\text{PSF} = L / \sum_k |\psi_k|_2^2 |\psi(x = 0)| \), where \( \psi_k \) are the Fourier coefficients of the exciton wavefunction \( \psi(x) \), and \( L \) is the normalization length [11, 26, 27]. For our quasi-1D 1s exciton wavefunction [Fig. 5.4(a)] this yields \( N_s^\text{PSF} = 2.5 \times 10^6 \, \text{cm}^{-1} \). Hence, the mid-IR response approaches yet remains somewhat below the limit imposed by phase space filling.

### 5.4 Summary of Mid-IR SWNT Response

In conclusion, intra-excitonic transitions are both a direct consequence and a measure of \( e-h \) correlations. The experiments reported here provide new insights into the chirality-specific femtosecond mid-IR response of electronic excitations in individualized SWNTs. A photo-induced absorption around 200 meV was observed, manifesting quasi-1D intra-excitonic transitions in close agreement with the calculated 1s-2p oscillator strength. The non-exponential kinetics and (6,5)/(7,5) chirality-specific enhancement of the transient mid-IR absorption further underscores its excitonic origin. We believe that the mid-IR probe, extended e.g. into the low-temperature or low-density limit, will provide a versatile spectroscopic tool to investigate bound quasi-1D \( e-h \) pairs and their internal electronic structure independent of interband symmetry.
5.5 References


[17] The probe was spectrally resolved (10 nm resolution) with small photoinduced changes sampled by 500 Hz synchronous chopping coupled to shot-by-shot gated integration. Pump and probe diameters were ≈400 μm and 200 μm (full width at half maximum), respectively.


Differences in this splitting can arise from the dissimilar embedding matrices i.e. dielectric constants.

It appears due to a downward step at exactly the 178 meV vibrational resonance in the PE matrix.


Chapter 6

Multi-Exciton Population Dynamics

Femtosecond transient absorption kinetics are obtained on semiconducting (6,5) single and (7,5)/(17,6) double-walled carbon nanotubes, and the relaxation dynamics are modeled with explicit inclusion of both phase space filling restrictions and nonlinear annihilation of coherent excitons. To holistically simulate the kinetics in all time regimes, both a continuum and a stochastic model of population probabilities are employed. The amplitude of $E_{11}$ transient bleach signal is found to scale linearly with photon fluence for $E_{22}$ excitation, but strikingly only with the square root for direct $E_{11}$ excitation. Simulation of the peak amplitude dependence for both the $E_{22}$ and $E_{11}$ excitation, suggests the contrasting intensity dependence can be understood in terms of nonlinear annihilation of coherent excitons, and phase space filling at high photon fluences. Analysis of the kinetic decay curves, support a predominately diffusion-controlled mechanism for exciton-exciton annihilation at room temperature. However, at intermediate delays times ($<\sim 1$ ps) or at low temperatures ($<\sim 200$ K) multiexciton states of coherently delocalized excitons also contributes strongly to the $E_{11}$ relaxation kinetics of (6,5) carbon nanotubes. While both the continuum and stochastic models could acceptably reproduce the kinetics and peak amplitude intensity dependences observed, markedly different branching ratios between the population decay pathways, and phase space filling restrictions are obtained. The stochastic model put forward highlights the importance of including contributions from coherent multiexciton states in modeling the optical relaxation dynamics of semiconducting single-walled carbon nanotubes.

6.1 Introduction

Depending on the strength of the Coulombic interaction, the elementary excitation in solid states can be either a neutral exciton, or a pair of electrons ($e$) and holes ($h$) with a weak mutual correlation.[1] A quantitative measure of the Coulombic interaction is the exciton
binding energy ($E_b$), defined as the energy difference between the $e$-$h$ continuum and the lowest bound exciton state. As deduced experimentally\cite{2,3} and from \textit{ab initio} calculations\cite{4,5}, the $E_b$ value determined for semiconducting single-walled carbon nanotubes (SWNTs) typically ranges from 0.3 to 1 eV, permitting assignment of the dominant absorption/emission spectral bands to excitonic transitions. Such large $E_b$ values are possible because of greatly enhanced electron-hole Coulombic interactions owing to quasi-one-dimensional (quasi-1-D) confinement in SWNTs.\cite{6}

Experimental studies of the excitation dynamics in the SWNT employing ultrafast transient absorption\cite{7-10} and time-resolved fluorescence techniques with sub-100 femtosecond time resolution\cite{11,12} reveal a very fast kinetic decay component on the time scale of a few hundreds of femtoseconds. Through analysis of both the non-exponential kinetic decay component and the dependence of the corresponding amplitude on excitation intensity it was concluded that exciton-exciton annihilation in semiconducting SWNTs is a dominant relaxation process.\cite{10,11,13,14} This nonlinear annihilation process involves a pair of excitons whose interaction lead to rapid relaxation of one exciton whereas the other be promoted to a doubly excited-state $E_{nn} \approx 2E_{11}$ owing to momentum and energy conservation (see Fig. b).

For an exciton pair to annihilate they must first occupy the same physical space. This required overlap can occur from either from the delocalization of excitons or after diffusional motion along the tube length.\cite{12,13} The energy and momentum of the annihilated exciton pair must also be conserved, requiring the newly created exciton to occupy a transient state $E_{nn}(=2E_{11})$ just above the $E_{22}$ transition (see Fig. 6.1b). In general, these requirements make annihilation an inefficient process for most solid state systems. However, for quasi-1D systems like SWNTs, confinement inherently enhances the exciton-exciton scattering, inducing annihilation among either delocalized excitons or after 1D exciton diffusional motion. Further enhancing annihilation effects, the requirement of momentum conservation is thought to be relaxed because the translational symmetry along the tube is easily disrupted for nanoscale systems. For these reasons, it is perhaps not surprising that the exciton-exciton annihilation rate, $\gamma(t)$ for a given excitation fluence is significantly greater than in comparable bulk semiconductors. While exciton-exciton annihilation in SWNTs is a well established process, a more general kinetic model is desirable to explicitly treat the dynamics of multiple exciton states associated with the $E_{11}$ and $E_{22}$ transitions. Such a kinetic model may provide important insight into how multiple exciton states are involved with annihilation and impact ionization processes in SWNTs, which are fundamental to such recently reported practical applications as the development highly-efficient SWNT photodiode devices \cite{34}.

The exciton energy, $E_{nm}^{cv}(K_{CM})$, in semiconducting SWNTs is typically characterized by the translation wave number $K_{CM}$, which satisfies the translation symmetry of the center of mass of the $e$-$h$ pair, and the quantum number $n$ corresponding to their relative motion ($1s, 2p, \ldots$ states of the Hydrogen type spectrum).\cite{1} The subscripts $c$ and $v$ refer to the corresponding van Hove singularities in the conduction and valence bands, respectively.\cite{4,5} These exciton states are the eigen states of electronic excitation, which are qualify the excited states delocalized over the system under consideration. Thus, any exciton evolution should be determined by their interactions with phonons, impurities or by scattering with
other excitons resulting in exciton-exciton annihilation. A theoretical description of such exciton-exciton annihilation process would then define the transitions between the bands of the multiexciton manifolds resonantly coupled with other excited states, which decay by subsequent linear relaxation due to electron-phonon coupling.[13]

The evolution of the occupation probability of these multiexciton states and the annihilation rate constant are the main characteristics of a stochastic model. According to this description, exciton-exciton annihilation manifests itself as long as more than one exciton is present in the system but switches off when a single exciton is finally left.[15,16] Such a scheme is well suited for describing the exciton decay kinetics at the initial times, shorter than 10 ps.[10,11,14] On the other hand, it has been also demonstrated that the exciton decay kinetics on a longer timescale (up to 1 ns) follows the diffusion-controlled behavior.[17,18] In addition, calculations based on a diffusion-controlled exciton-exciton annihilation model enabled to reproduce the saturation behavior of photoluminescence emission with increasing excitation intensity.[19,20] Moreover, a recent study of the intensity-dependent exciton decay further suggested that exciton-exciton annihilation in semiconducting SWNTs is an inefficient process.[21] Apparently, these conclusions differ greatly from the conclusions derived from the earlier studies[7-12], and are also inconsistent with the conclusions drawn from recent four-wave-mixing spectroscopic experiments at different excitation intensities.[22,23] In order to provide clarity to these conflicting studies, analyses of the exciton decay kinetics at different timescales and at different excitation intensities will be presented in this paper.

6.2 Materials and Methods

The SWNT sample used in this study is highly enriched in a single semiconducting tube type, the (6, 5) nanotube, which was isolated through density-gradient ultracentrifugation [24]. The obtained aqueous solution contains individually separated nanotubes dispersed with sodium cholate as a surfactant. The experiments were performed directly on the aqueous suspensions in a 200 µm path length cell, or on a thin composite film fabricated by mixing the solution with appropriate amount of water soluble polyvinylpyrrolidone (PVP) polymer. Use of polymers films enabled low temperatures measurements, by placing the polymer in a temperature controlled Janis cryostat which operates under continuous liquid helium flow. Linear absorption and steady-state fluorescence emission spectra confirm that the nanotubes remain individualized and of optical quality after being transferred from the solution to the solid film. The double-walled carbon nanotubes (DWNTs) were prepared by chemical vapor deposition in combination with thermal oxidation to greatly reduce the presence of SWNTs[25]. The purified DWNTs were dispersed individually in D2O solution using sodium dodecyl sulfate (SDS) as a surfactant, and have ~90% content of double-walled carbon nanotubes. A quartz sample cell of 1 mm path length was used for measurements on DWNT samples. Here, only the results measured on the (7, 5) tube, the inner tube of a dominant DWNT species in the sample, will be presented.

The femtosecond transient absorption setup employed here has been described extensively
Figure 6.1. (a) Linear absorption spectrum of the (6, 5) tube-enriched aqueous solution and laser pulse spectra (dotted line) resonant with either its $E_{22}$ or $E_{11}$ transitions. (b) Schematic energy level diagram of a semiconducting SWNT with a dominant relaxation pathway mediated by exciton-exciton annihilation (with a rate constant $\gamma(t)$), shown for the direct $E_{11}$ excitation case. c. Delocalized excitons can annihilate either from mutual overlap or after diffusion-controlled motion along the tube length (indicated by arrows).
elsewhere [13, 26]. In short, the light source was an optical parametric amplifier pumped by a 250 kHz Ti: sapphire regenerative amplifier, which enables resonant excitation at either the $E_{11}$ or $E_{22}$ transitions of the selected nanotube species with 60 and 45 fs laser pulses respectively. The pump beam was focused to a spot size of 161 $\mu$m at the sample. A single-filament white-light continuum served as the probe beam, and selection of the probe wavelength was realized using a single-grating monochromator with a typical band-width of 8 nm. The detection scheme consists of a photo-diode and a lock-in amplifier. The polarization of the pump beam was set to the magic angle ($54.7^0$) with respect to the probe beam. A combination of a waveplate and polarizer was used to control the intensity of the pump laser beam.

### 6.3 Results

#### 6.3.1 Experimental observations

Fig. 6.1 shows the linear absorption spectrum of the (6, 5) tube-enriched, individualized SWNTs in aqueous solution. The two bands peaking at 982 and 570 nm correspond to the $E_{11}$ and $E_{22}$ excitonic transitions of the (6, 5) tube type, respectively. Upon resonant excitation of these bands with ultrashort laser pulses (see the dotted lines in Fig. 1 for the laser pulse spectra), a series of transient absorption kinetics were probed at 988 nm under different pump intensities. As observed previously, the transient absorption signals ($\Delta OD(t)$) are dominated by photobleaching and stimulated emission.[27] Also, in consistent with previous works, the kinetic profiles are, after normalizing at the signal maxima ($\Delta OD_0$), largely invariant to the excitation intensity for each chosen pump wavelength.[10] However, the amplitudes of the signal maxima show strikingly different dependence on laser pump intensity for the $E_{11}$ and $E_{22}$ pump cases as shown in Fig. 6.2. A linear dependence of the amplitude on the intensity of the $E_{22}$ excitation was found, whereas for the $E_{11}$ excitation the corresponding amplitude scales linearly with the square root of the intensity. In both cases, the amplitudes of signal maxima exhibit saturation behavior when excitation intensity is greater than $\sim 1.4 \times 10^{13}$ photons/cm$^2$. The same intensity dependence was also found for the SWNT/PVP composite film (see the open circles in Fig. 6.2). In this case, the absence of the saturation behavior due to high sample optical density makes the different intensity dependence found for the $E_{11}$ and $E_{22}$ excitation even more distinct.

Quantitative data analysis employing a least square deconvolution fitting algorithm with explicit consideration of the finite temporal response shows that all the decay kinetics can be satisfactorily described with a model function consisting of three or four exponents. The component with the longest lifetime typically has a timescale of few hundreds picoseconds, which characterizes the relaxation associated with the last remaining exciton in the system. The kinetics probed at room temperature for the $E_{11}$ transition of the (6, 5) tube upon excitation of its $E_{22}$ state exhibits a slower initial decay than the corresponding kinetics measured with direct $E_{11}$ excitation (Fig. 6.3a). In particular, the two fast decay components
Figure 6.2. (a) Plots of the maximal transient absorption signals measured at 988 nm as a function of the square root of pump fluence for the (6, 5) tube species upon $E_{11}$ excitation. The samples were either a polymer-SWNT composite film (open circles) or an aqueous solution (filled circles). (b) Plots of the maximal transient absorption signals measured at 988 nm as a function of the pump fluence for the (6, 5) tube species upon $E_{22}$ excitation.
have considerably different decay timescales (and relative amplitude), which are 122 fs (55%) and 1.3 ps (29%) for the $E_{11}$ excitation, and 350 fs (57%) and 2.4 ps (31%) for the $E_{22}$ excitation. In contrast, the two slow decay components appear similar for the two pump scenarios, with decay times of $\sim 22$ ps and $\sim 300$ ps, respectively.

The kinetics measured at low temperatures until 4.4 K show a similar trend with the change of pump intensity as observed at 292 K (in Fig. 6.2) for both the $E_{22}$ and $E_{11}$ pump scenarios (data not shown). A representative set of transient absorption profiles measured at 110 K is plotted in Fig. 6.3b, where a remarkably faster decay is seen for the $E_{11}$ pump case than the one obtained with the $E_{22}$ pump. The lifetimes (relative amplitudes) determined from deconvolution fitting are 140 fs (63%), 1.5 ps (29%), and 19 ps (8%) for the $E_{11}$ excitation data, whereas corresponding results are 310 fs (52%), 2.1 ps (28%), and 22.4 ps (20%) for the the $E_{22}$ excitation case.

The need for multiple (three or four) exponential components to satisfactorily fit the transient absorption kinetics is partially due to occurrence of nonlinear exciton-exciton annihilation.[13] A qualitative justification can be obtained by assuming that the exciton-exciton annihilation process dominates the kinetic decay, and in this case a simple rate equation for exciton density $n(t)$ can be written as: $\frac{dn(t)}{dt} = -\frac{1}{2} \gamma t^{d/2-1} n^2(t)$, where $g$ is the time-independent annihilation rate, and $d$ is the dimensionality.11 As the transient absorption signal at a given delay time $t$, $\Delta OD(t)$, is proportional to $n(t)$, for a 1-D system ($d = 1$) the solution of the rate equation suggests a linear relation when the transient absorption signal is plotted in the form of $(\Delta OD_0/\Delta OD(t) - 1)^2$ versus delay time $t$ ($\Delta OD_0$ is the signal amplitude at $t = 0$). As shown in Fig. 6.3c, a good linear relation is indeed seen for the data collected with $E_{11}$ excitation when $t$ is approximately greater than 1 ps (green circles). This linear behavior suggests diffusion-limited annihilation in 1-D system. In comparison, the data obtained with $E_{22}$ pump exhibit relatively large deviation from linearity (filled black circles), indicating possibly substantial contribution from linear relaxation to ground-state. Upon cooling, the data collected with the $E_{22}$ pump at 110 K again show good linear relation in the plot of $(\Delta OD_0/\Delta OD(t) - 1)^2$ versus delay time within the experimental uncertainty (see Fig. 6.3d, black circles). In stark contrast, the result obtained with $E_{11}$ pump at the same temperature exhibits an excellent linear relation between $\Delta OD_0/\Delta OD(t) - 1$ and delay time $t$ (Fig. 3d, green circles). The latter linear relation can be derived from the same rate equation but for $d = 2$, and a resultant time-independent annihilation rate constant.

As discussed in our earlier work, this time-independent annihilation rate arises from a rapid annihilation process involving coherently delocalized excitons.[13,28]

The difference between the kinetics probed at the $E_{11}$ state upon excitation of the $E_{11}$ and $E_{22}$ states at room temperature is much more pronounced for the (7, 5) inner tube of the DWNT species (see Fig. 6.4a for the DWNT data). Here the dominant and fastest decay component has a lifetime of 110 fs for $E_{11}$ pump, whereas it is 800 fs for the $E_{22}$ pump. It is also noteworthy that the kinetics probed for the (7, 5) inner tube exhibits a substantially slower decay than the decay of the (7, 5) SWNT type measured under a comparable excitation intensity (see the black trace in Fig. 6.4a for example). However, our measurements under different excitation intensities for the (7, 5) inner tube of the DWNT species show linear dependence of the maximum transient absorption amplitude on the intensity of the $E_{22}$
Figure 6.3. Transient absorption kinetics measured upon resonant excitation of the $E_{11}$ state at 988 nm and the $E_{22}$ state at 570 nm, respectively, for the (6,5) tube species. (a) Data acquired at 292 K for an aqueous solution sample, and (b) at 110 K for a PVP polymer composite film. (c) Plotting the same data shown in a as $(\Delta\text{OD}_0/\Delta\text{OD}(t) - 1)^2$ versus delay time. The dashed lines are linear fits to the majority of data points. (d) Plotting the same data shown in b as $\Delta\text{OD}_0/\Delta\text{OD}(t)$ – 1 (left axis) or $(\Delta\text{OD}_0/\Delta\text{OD}(t) - 1)^2$ (right axis) versus delay time. Again, the dashed lines are linear fits to the majority of data points.
Figure 6.4. (a) Comparison of transient absorption kinetics obtained for the (7, 5) inner tube of a dominant DWNTs species upon $E_{22}$ (orange) and $E_{11}$ (black) excitation with the one measured for the (7, 5) SWNT (dark green) following excitation of its E22 state. (b) Plot of the peak amplitudes obtained upon the $E_{11}$ (filled circles) or $E_{22}$ (open circles) excitation for the (7, 5) inner tube of the dominant DWNT species as a function of the square root of pump fluence or pump fluence, respectively. (c) The data measured for the (7, 5) inner tube upon $E_{11}$ excitation is plotted as a function of inverse of the square root of delay time. The inset shows the same data plotted as $(\Delta OD_0/\Delta OD(t) - 1)^2$ versus delay time.
excitation (Fig. 6.4b, open circles), whereas a square root dependence on the intensity of $E_{11}$ excitation (Fig. 6.4b, filled circles). This observation is the same as what found the SWNTs such as the (6, 5) tube type as shown in Fig. 6.2, suggesting the observed distinct intensity dependence may be generic phenomenon for semiconducting nanotubes. Moreover, a plot of the kinetics measured for the (7, 5) inner tube upon its $E_{11}$ excitation (black line in Fig. 4a) in the form of $(\Delta OD_0/\Delta OD(t) - 1)^2$ vs. delay time $t$ gives rise to good linear relationship for the first a few picoseconds (see Fig. 6.4c, inset). As for the (6, 5) tube type (see Fig. 6.3c, d), this linear relation again suggests occurrence of diffusion-limited annihilation. However, at short times deviation from the linearity is again noticed, which can be more clearly seen from an alternative plot of the same data as a function of the inverse of the square root of delay time, $1/\sqrt{t}$ (see Fig. 6.4c). The initial decay within the first 600 fs does not follow the linear dependence (indication of diffusion-controlled annihilation) seen at longer delay times.

6.4 Theoretical description of exciton-exciton annihilation

The key findings of our transient absorption measurements on the (6, 5) SWNT species and the (7, 5) inner tube of a dominant DWNT type are as follows. First, we found that the initial decay of the kinetics probed at the $E_{11}$ state of the (6, 5) tube species upon excitation of its corresponding $E_{22}$ transition is clearly slower than that measured with its direct $E_{11}$ excitation (see Fig. 6.3a,b), and this difference appears much more pronounced for the (7, 5) inner tube type (Fig. 6.4a). Second, the maximal signal amplitudes scale linearly with the intensity of the $E_{22}$ excitation, but with the square root of the $E_{11}$ excitation intensity (see Figs. 6.2 and 6.4b). Our qualitative analysis further shows occurrence of a diffusion-limited annihilation process except for the data collected at 110 K and with a direct $E_{11}$ excitation (Fig. 6.3d, dark green circles). In order to gain insights into these strikingly different temporal and intensity behaviour in response to the different excitonic states initially excited, we will develop detailed theoretical description with explicit consideration of exciton-exciton annihilation.

6.4.1 Continuum model.

Exciton-exciton annihilation (Auger recombination) is typically described in terms of a simple scheme, which is well justified for extended systems [10, 13, 29]. The time evolution
of excitons in this approach can be determined by the following kinetic equations:

\[
\begin{align*}
\frac{dn_1}{dt} &= G_1(t)f_1(n_1) - Kn_1 - \gamma(t)n_1^2 + k_{21}f_1(n_1)n_2, \\
\frac{dn_2}{dt} &= G_2(t)f_2(n_2) + kn_2f_2(n_2)n_n - k_{21}f_1(n_1)n_2, \tag{6.1} \\
\frac{dn_n}{dt} &= \frac{1}{2}\gamma(t)n_1^2 - kn_nf_2(n_2),
\end{align*}
\]

where \(n_i\) is the exciton concentration populating the \(i\)-th exciton state (the \(E_{ii}\) state), \(G_i(t)\) is the generation function of the pump pulse (depending on the resonance condition corresponding to the \(E_{ii}\) state), \(f_i(t) = 1 - \frac{n_i}{N_i}\) is the phase space-filling factor (\(N_i\) determines the maximal amount of the excitations, which could be generated in the \(i\)-th state), \(\gamma(t)\) is the rate of exciton-exciton annihilation (on the \(E_{11}\) exciton state), and the linear relaxation terms determine the dominant relaxation pathways. \(K\) is the relaxation rate for the \(E_{11}\) exciton, \(k_{21}\) determines the rate of the relaxation from the \(E_{22}\) state to the \(E_{11}\) state. Here the \(E_{nn}\) state corresponds to the excited state, which is involved in the process of exciton-exciton annihilation (\(E_{nn} \cong 2E_{11}\) shown in Fig. 6.1b), and \(k_{n2}\) determines the rate of the exciton transfer between the corresponding states. In the case of the short pump pulses (when the pump pulse duration is shorter than \(1/k_{21}\) and \(1/k_{n2}\) the excitation intensity dependence of the initial populations will be different for different pump conditions. If the pump pulse is in resonance with the \(E_{11}\) exciton state, then \(G_2(t) = 0\), and if also the time dependence of the annihilation rate can be discarded, at high excitation conditions (when the nonlinear exciton relaxation due to exciton-exciton annihilation is dominating) but not so high that the phase filling starts manifest itself, i.e. when \(n_1 << N_1\) is still fulfilled and, thus, \(f_1(n_1) \approx 1\), from Eq. 6.1 it follows that:

\[
n_1(0) = \sqrt{\frac{G_{1,max}}{\gamma}}, \tag{6.2}
\]

where \(G_{1,max}\) is the maximal value of the generation function. Due to the short pulse duration (in comparison with \(1/k_{21}\) and \(1/k_{n2}\) the \(E_{22}\) state is not populated at the initial times, i.e. \(n_2(0) \approx 0\). In the opposite case, when the pump pulse is in resonance with the \(E_{22}\) exciton state, we have \(G_1(t) = 0\), and then

\[
n_2 \approx \frac{G_{2,max}}{k_{21}}, \tag{6.3}
\]

while \(n_1(0) \approx 0\). Here \(G_{2,max}\) is the maximal value of the generation function.

The transient spectrum \(\Delta A(t, \lambda)\) is defined by the exciton populations and, thus, can be given by [13, 27]:

\[
\Delta A(t, \lambda) \propto \sum_i n_i(t)[\sigma_i^{ESA}(\lambda) - \sigma_i^{SE}(\lambda) - \sigma_0(\lambda)], \tag{6.4}
\]

where \(\sigma_0(\lambda)\) is the ground state absorption spectrum (\(\lambda\) is the wavelength of the probe pulse), \(\sigma_i^{ESA}(\lambda)\) and \(\sigma_i^{SE}(\lambda)\) are the cross-sections for excited state absorption and stimulated emission of the \(i\)-th excited state, respectively, \(n_i(t)\) determines the time evolution of the \(i\)-th
excited state population according to Eq. 6.1 (\(i\) enumerates the exciton states populated by excitation pulses, relaxation from higher states and via exciton-exciton annihilation). Thus, by substituting Eq. 6.2 into Eq. 6.4 we will get that the transient bleaching amplitude should be proportional to \(\sqrt{G_{1,\text{max}}'}\), while by substituting Eq. 11.3 into Eq. 6.4 we will get the result proportional to \(G_{2,\text{max}}\). This qualitatively is in line with the experimental dependences shown in Fig. 6.2.

Due to the finite rate \(k_{21}\) of the exciton relaxation from the \(E_{22}\) exciton state to the \(E_{11}\) state (in comparison with the pump pulse duration), the situation corresponding to the pumping conditions into the \(E_{22}\) exciton state can be considered in a similar way as in the case when pumping into the \(E_{11}\) exciton state but with longer pulses. This should evidently slow down the excitation kinetics in accord to the experimental observations shown in Fig. 6.3.

The ground state bleaching should be proportional to \((n_1 + n_2)_{\text{max}}\), where the subscript indicates the maximal value, as follows from Eq. 6.4. For modeling let us assume the Gaussian pump pulse with amplitude \(A\) and FWHM duration of 50 fs. Also taking typical values such as \(k_{21}^{-1} \approx 50\) fs [30], \(\gamma^{-1} \approx 800\) fs [12] (the latter value corresponds to normalization of the amount of excitons per nanotube), \(K^{-1} \approx 10\) ps, and also assuming that \(k_{n2} > k_{21}\), we cannot obtain the intensity dependence as shown in Fig. 6.2 (to compare the pulse duration of the order of tens of fs with \(k_{21}^{-1}\). At high intensities of excitation usually \(n_{2\text{max}} > n_{1\text{max}}\) independent of either \(E_{11}\) or \(E_{22}\) state is initially excited. Furthermore, in both cases the amplitude of the bleaching signal always follows almost linear intensity dependence, and change of the parameters used in our calculations does not alter this result. This clear discrepancy from the experimental data can be improved by modifying the annihilation kinetic scheme described by Eq. 6.1 through assuming existence of two pathways of the exciton relaxation from the \(E_{nn} \approx 2E_{11}\) state: one via population of the \(E_{22}\) exciton state and another directly to the \(E_{11}\) exciton state bypassing the \(E_{22}\) exciton state. Such branching scheme for the exciton relaxation from the \(E_{nn} \approx 2E_{11}\) state in combination with an assumption of similarly high relaxation rates can be described by slightly modifying kinetic equations given by Eq. 6.1:

\[
\begin{align*}
\frac{dn_1}{dt} &= G_1(t)f_1(n_1) - Kn_1 - \frac{1}{2}(1 + \alpha)\gamma(t)n_1^2 + k_{21}f_1(n_1)n_2, \\
\frac{dn_2}{dt} &= G_2(t)f_2(n_2) + \frac{1}{2}\alpha\gamma(t)n_2^2 - k_{21}f_1(n_1)n_2,
\end{align*}
\]

(6.5)

where \(\alpha\) determines the branching ratio. The intensity dependence of the \((n_1 + n_2)_{\text{max}}\) value obtained by neglecting the phase-filling effects and assuming relatively small \(\alpha\) values, e.g. \(\alpha = 0.1\), resembles the experimental observations for both excitation conditions (Fig. 6.5a). However, the same set of parameters produces much faster decay behavior than the kinetics observed experimentally as shown in Figure 6.3. Better agreement at least for the initial delay times can be obtained assuming that the relaxation rate, \(k_{21}\), is up to 10 times slower. The best fit of the experimental kinetics measured at 292 K is obtained for the following parameters, which are treated to be variable: \(\alpha = 0.4\), \(\gamma^{-1} = 1040\) fs, \(k_{21}^{-1} = 480\) fs (Fig. 6.5b). An excitation intensity of \(G_{\text{max}} \equiv A = 8\) is used for our calculations. Similarly, for the kinetics measured at 110 K we get \(\alpha = 0.5\), \(\gamma^{-1} = 3760\) fs and \(k_{21}^{-1} = 410\) fs for the same excitation intensity (Fig. 6.5c). We further found that an increase of the \(A\) value
Figure 6.5. a. The dependence of $(n_1 + n_2)_{max}$ calculated according to the continuum model (Eq. 6.5) with typical values $\gamma^{-1} = 800$ fs, $k_{21}^{-1} = 50$ fs, and assuming $\alpha = 0.1$ on the pump pulse intensity $A$ in the case of pumping to the $E_{22}$ band (red curve, lower x-axis) and of its square root $\sqrt{A}$ in the case of pumping to the $E_{11}$ band (green curve, upper x-axis). b. The best fit for the both experimental kinetics measured at room temperature (292 K) upon excitation of the $E_{11}$ or $E_{22}$ band (green and red curves, respectively) is obtained using the following parameters: $\alpha = 0.4$, $\gamma^{-1} = 1040$ fs, $k_{21}^{-1} = 480$ fs, and an amplitude of the generation function $A \equiv G_{max} = 8$. c. The best fit for the corresponding kinetics measured at 110 K is obtained by assuming the same intensity of the generation function, $A$, and using the following parameters: $\alpha = 0.5$, $\gamma^{-1} = 3760$ fs, and $k_{21}^{-1} = 410$ fs. d. The dependence of the $(n_1 + n_2)_{max}$ on the pump pulse intensity $A$ in the case of the $E_{22}$ excitation (red curve, lower x-axis) and on its square root $\sqrt{A}$ in the case of the $E_{11}$ excitation (green curve, upper x-axis) calculated using the same set of parameters. It is almost the same for the kinetics measured at different temperatures.
Figure 6.6. The kinetic scheme for the system with multiple exciton population of both $E_{11}$ and $E_{22}$ exciton states. The lowest energy level $E_0$ (grey bar) indicates the ground state. The population of the $E_{11}$ exciton band is reflected in the upward direction with the corresponding energies of $E_{11}$, $2E_{11}$, $3E_{11}$, ... (shown up to $4E_{11}$), while the population of the $E_{22}$ exciton band is indicated rightwards (with the corresponding energies of $E_{22}$, $2E_{22}$, ... (shown up to $3E_{22}$)). In addition, the levels of the combined population corresponding to energies $E_{i,j} = i \cdot E_{11} + j \cdot E_{22}$ are also shown. The probabilities of the occupation of these energy levels are denoted as $P_{i,j}$, and the possible transition pathways between different states are indicated with arrows (for the labeling see the legend in the kinetic scheme). For clarity, the upper electronic band $E_{an} \approx 2E_{11}$ involved in exciton-exciton annihilation is not shown since the excitons relax form this state almost instantaneously (comparing with other characteristic rates in this model) either to the $E_{22}$ or back to the $E_{11}$ band.
from 1 to 30 leads to almost linear variation of the corresponding $1/\gamma$ value with $A$. The intensity dependences of the $(n_1 + n_2)_{\text{max}}$ calculated using the same sets of parameters are very similar for both cases and qualitatively agree to the experimental observations as shown in Fig. 6.5d.

The calculated kinetics, however, start to substantially deviate from the experimental kinetics on a longer time scale ($>400$ fs). The much faster decays than our experimental data can be considered as indication of overestimation of the efficiency of the exciton-exciton annihilation processes on longer time scales. To avoid such fast excitation decay, a stochastic description of the exciton-exciton annihilation process should be used [13].

### 6.4.2 Stochastic model.

This model describes the population probabilities [13] according to the scheme shown in Fig. 6.6. In the case of multiple excitons in the system they can populate both $E_{11}$ and $E_{22}$ states in the course of their generation/relaxation. To reflect these relaxation/generation pathways, various energy levels $E_{i,j} = i \cdot E_{11} + j \cdot E_{22}$ have to be taken into account as shown in Fig. 6.6, where $i$ and $j$ prescribe the amount of excitons in the $E_{11}$ and $E_{22}$ bands, respectively. The possible transition pathways between various energy levels determining the evolution of probabilities, $P_{i,j}$, are depicted by arrows. Time-dependent rates of the exciton generation in the $E_{11}$ and $E_{22}$ bands already containing $i$ and $j$ excitons are defined as $G_1^{(i)}(t)$ and $G_2^{(j)}(t)$, respectively, while the relaxation rates $k_{21}$ determines the relevant transition from the $E_{22}$ band containing $j$ excitons to the relevant $E_{11}$ band. The rate constants for the linear relaxation $K^{(i)}$ and nonlinear annihilation $\Gamma^{(i)}$ determine the exciton loss from the $E_{11}$ band already containing $i$ excitons. It is also assumed that after annihilation the excitons from the $E_{nn} \approx 2E_{11}$ electronic band can relax either to the $E_{22}$ band (with probability $\alpha$) or directly back to the $E_{11}$ band with probability $(1 - \alpha)$. According to the scheme shown in Fig. 6.6, the following Master equations for the occupation probabilities $P_{i,j}$ are derived:

$$
\frac{dP_{0,0}}{dt} = - \left\{ G_1^{(0)}(t) + G_2^{(0)}(t) \right\} P_{0,0} + K^{(1)} P_{1,0}, \tag{6.6}
$$

$$
\frac{dP_{1,0}}{dt} = G_1^{(0)}(t)P_{0,0} - \left\{ G_1^{(1)}(t) + G_2^{(0)}(t) + K^{(1)} \right\} P_{1,0} + k_{21}^{(1)} P_{0,1}, \tag{6.7}
$$

$$
\frac{dP_{0,1}}{dt} = G_2^{(0)}(t)P_{0,0} - \left\{ G_1^{(0)}(t) + G_2^{(1)}(t) + k_{21}^{(1)} \right\} P_{0,1} + \alpha \Gamma^{(2)} P_{2,0} + K^{(1)} P_{1,1}, \tag{6.8}
$$

etc. For $P_{i,j}$ when $i \geq 2$ and $j \geq 1$ the relevant equations can be given by:

$$
\frac{dP_{i,0}}{dt} = G_1^{(i-1)}(t)P_{i-1,0} - \left\{ G_1^{(i)}(t) + G_2^{(0)}(t) + K^{(i)} + \Gamma^{(i)} \right\} P_{i,0} + k_{21}^{(1)} P_{i-1,1} + \left\{ K^{(i+1)} + (1 - \alpha) \Gamma^{(i+1)} \right\} P_{i+1,0}, \tag{6.9}
$$

etc.
\[
\frac{dP_{0,j}}{dt} = G_{0}^{(j-1)}(t)P_{0,j-1} - \left\{ G_{1}^{(0)}(t) + G_{2}^{(j)}(t) + k_{21}^{(j)} \right\} P_{0,1} + \alpha \Gamma^{(2)}P_{2,j-1} + K^{(1)}P_{1,j}, \quad (6.10)
\]

\[
\frac{dP_{1,j}}{dt} = G_{2}^{(j-1)}(t)P_{1,j-1} + G_{1}^{(0)}(t)P_{0,j} - \left\{ G_{1}^{(i)}(t) + G_{2}^{(j)}(t) + K^{(i)} + k_{21}^{(j)} \right\} P_{1,j}
+ k_{21}^{(j+1)}P_{0,j+1} + \alpha \Gamma^{(3)}P_{3,j-1} + \left\{ K^{(2)} + (1 - \alpha) \Gamma^{(2)} \right\} P_{2,j}, \quad (6.11)
\]

\[
\frac{dP_{i,j}}{dt} = G_{2}^{(j-1)}(t)P_{i,j-1} + G_{1}^{(i-1)}(t)P_{i-1,j} - \left\{ G_{1}^{(i)}(t) + G_{2}^{(j)}(t) + K^{(i)} + k_{21}^{(j)} + \Gamma^{(i)} \right\} P_{i,j}
+ k_{21}^{(j+1)}P_{i-1,j+1} + \alpha \Gamma^{(i+2)}P_{i+2,j-1} + \left\{ K^{(i+1)} + (1 - \alpha) \Gamma^{(i+1)} \right\} P_{i+1,j}. \quad (6.12)
\]

Since the annihilation process corresponds to the two-exciton relaxation, the following relationship for the annihilation rates can be deduced if the statistical number of possible relaxation pathways are taken into account:

\[
\Gamma^{(i)} = \frac{i(i-1)}{2}\Gamma^{(2)} \equiv i(i-1)\frac{\gamma}{2}. \quad (6.13)
\]

Similarly, for the linear relaxation rates we obtain:

\[
k_{21}^{(i)} = ik_{21}^{(1)} \equiv ik_{21} \quad (6.14)
\]

and

\[
K^{(i)} = iK^{(1)} \equiv iK. \quad (6.15)
\]

Substituting Eqs. 6.13-6.15 into Eqs. 6.6-6.12 and also assuming that the exciton generation rate is independent of \(i\) and \(j\), i.e. \(G_{1}^{(i)}(t) \equiv G_{1}(t)\) and \(G_{2}^{(j)}(t) \equiv G_{2}(t)\), we get:

\[
\frac{dP_{0,0}}{dt} = - \{ G_{1}(t) + G_{2}(t) \} P_{0,0} + KP_{1,0}, \quad (6.16)
\]

\[
\frac{dP_{1,0}}{dt} = G_{1}(t)P_{0,0} - \{ G_{1}(t) + G_{2}(t) + K \} P_{1,0} + k_{21}P_{0,1} + \left\{ 2K + (1 - \alpha) \cdot \gamma \right\} P_{2,0}, \quad (6.17)
\]

\[
\frac{dP_{i,0}}{dt} = G_{1}(t)P_{i-1,0} - \{ G_{1}(t) + G_{2}(t) + iK + i(i-1)\frac{\gamma}{2} \} P_{i,0} + k_{21}P_{i-1,1}
+ \left\{ (i+1)K + (1 - \alpha)(i+1)i\frac{\gamma}{2} \right\} P_{i+1,0}, \quad (6.18)
\]

\[
\frac{dP_{0,j}}{dt} = G_{2}(t)P_{0,j-1} - \{ G_{1}(t) + G_{2}(t) + jk_{21} \} P_{0,j} + \alpha \cdot \gamma P_{2,j-1} + KP_{1,j}, \quad (6.19)
\]
\[
\frac{dP_{i,j}}{dt} = G_2(t)P_{i,j-1} + G_1(t)P_{0,j} - \left\{G_1(t) + G_2(t) + K + jk_{21}\right\}P_{i,j} \\
+ (j + 1)k_{21}P_{0,j+1} + \alpha \cdot 3 \cdot \gamma P_{3,j-1} + \left\{2K + (1 - \alpha) \cdot \gamma\right\}P_{2,j},
\]
(6.20)

\[
\frac{dP_{i,j}}{dt} = G_2(t)P_{i,j-1} + G_1(t)P_{i-1,j} - \left\{G_1(t) + G_2(t) + iK + jk_{21} + i(i - 1)\frac{\gamma}{2}\right\}P_{i,j} \\
+ (j + 1)k_{21}P_{i-1,j+1} + \alpha (i + 2) (i + 1) \frac{\gamma}{2} P_{i+2,j-1} \\
+ \left\{(i + 1)K + (1 - \alpha) (i + 1) i \frac{\gamma}{2}\right\}P_{i+1,j}
\]
(6.21)

for \(i \geq 2, j \geq 1\).

The amount of excitons in the \(E_{11}\) and \(E_{22}\) bands can be also defined accordingly as:

\[
n_1(t) = \sum_{i,j} i \cdot P_{i,j}(t), n_2(t) = \sum_{i,j} j \cdot P_{i,j}(t).
\]
(6.22)

Thus, to determine the temporal evolution of the excitations in the system, the set of differential equations (equations 6.16-6.21) have to be solved. The amount of these equations increases with the excitation intensity but is restricted when population is reaching the limits due to the phase space filling. If the amount of exciton states in the phase space (\(N_1\) for the \(E_{11}\) manifold and \(N_2\) for the \(E_{22}\) manifold) is taken into account, the set of equations to be solved reaches the finite number, which equals to \((N_1 + 1) \times (N_2 + 1)\). As a result, the exciton kinetics should become intensity-independent for excitation intensities large enough to approach the limit of the phase space filling.

According to the experimental conditions, we assume a Gaussian pump pulse with an amplitude \(A\) and a FWHM duration of 50 fs. The maximum amounts of exciton states in the phase space for the \(E_{11}\) and \(E_{22}\) manifolds are assumed to be \(N_1 = N_2 = 50\), and the amplitude \(A\) of the excitation pulse is chosen to ensure the occurrence of the phase space saturation effect. In our case, the excitation kinetics become independent of \(A\) when it is greater than \(\sim 1.2\) (when neglecting phase space filling factors and when the exciton relaxation/annihilation processes are switched off, this would results in generation of about 60 excitons per nanotube). The linear relaxation rate from the \(E_{11}\) manifold is assumed to be equal \(K^{-1} = 10\) ps. We find that both kinetics measured at room temperature with either \(E_{11}\) or \(E_{22}\) excitation can be well described for their initial part by assuming the following set of parameters: \(\alpha = 0.5, \gamma^{-1} = 460\) fs, and \(k_{21}^{-1} = 400\) fs (Fig. 6.7a). On the other hand, for the data collected at 110 K the best fit is obtained when \(\alpha = 0.5, \gamma^{-1} = 770\) fs, and \(k_{21}^{-1} = 390\) fs are chosen (Fig 6.7b). With these parameters we are also able to obtain the intensity dependences for the maximum value of the bleaching signal, as defined by Eq. 6.4, close to the experimental observations, which appear almost the same for the two temperatures (110 and 292 K) (Fig. 6.7c).

It is noteworthy that in opposite to the continuous model, the calculated kinetics obtained within the frame of the statistical model are less sensitive to the changes of the \(\alpha\) parameter, the branching ratio. In this case, sensitivity of the kinetics to the excitation intensity is controlled by an appropriate phase space filling factor.
Figure 6.7. a. The best fit for the excitation kinetics of SWNT calculated according to the stochastic model (solid curves) with the experimental data measured at 292 K (squares and circles) obtained using the following parameters: $\alpha = 0.5$, $\gamma^{-1} = 460$ fs, $k_{21}^{-1} = 400$ fs. b. The best fit for the same excitation kinetics measured at 110 K, obtained using $\alpha = 0.5$, $\gamma^{-1} = 770$ fs and $k_{21}^{-1} = 390$ fs. c. The dependence of the $(n_1 + n_2)_{max}$ upon intensity of the pumping signal defined as $A$ in the case of pumping to the $E_{22}$ band (red curve) and upon its square root $\sqrt{A}$ in the case of pumping to the $E_{11}$ band (green curve) calculated using the same parameter set. The intensity dependencies demonstrate almost the same behavior at both temperatures.
Figure 6.8. a. The best fit for the excitation kinetics of DWNT calculated according to the stochastic model (solid curves) with the experimental data (squares and circles) obtained using the following parameters: $\alpha = 0.5$, $\gamma^{-1} = 3930$ fs, $k_{21}^{-1} = 800$ fs. b. The dependence of the $(n_1 + n_2)_{\text{max}}$ upon intensity of the pumping signal defined as $A$ in the case of pumping to the $E_{22}$ band (red curve) and upon its square root $\sqrt{A}$ in the case of pumping to the $E_{11}$ band (green curve) calculated using the same parameter set.
Within the same annihilation scheme, the much larger differences in the kinetics measured with \( E_{11} \) and \( E_{22} \) excitation for the DWNTs (see Fig. 6.4) could be attributed to much slower rates of the annihilation \( \gamma \) and the relaxation \( k_{21} \), which may be caused by the presence of the outer nanotube. Indeed, the best fit of the kinetics is obtained assuming \( \alpha = 0.5, \gamma^{-1} = 3930 \) fs, \( k_{21}^{-1} = 800 \) fs (Fig. 6.8a). Using these parameters, the intensity dependence of the resulting maximal bleaching signal also provides a trend similar to the experimental results (Fig. 6.8b). It is evident that our chosen value \( A = 1.7 \) corresponds to a situation when both intensity dependences exhibit some saturation effect. As a result, by increasing the \( A \) value above \( \sim 1.5 \) the obtained value of \( \gamma^{-1} \) remains almost invariant.

### 6.5 Discussion

Through numerical simulations presented above, we found that the strikingly different dependence of the maximal bleaching signal on the excitation intensity observed for \( E_{11} \) and \( E_{11} \) excitation (square root dependence vs. linear dependence as shown in Figs. 6.2 and 6.4b) could be understood in terms of nonlinear annihilation of coherent excitons. In order to reproduce these intensity dependences, we proposed two relaxation pathways from the doubly excited states that are populated in the course of nonlinear exciton-exciton annihilation. One of them takes into account a sequential relaxation from these high-lying excited states via the band to the lowest \( E_{11} \) band, while the other pathway corresponds to a direct exciton relaxation to the \( E_{11} \) band that bypasses the \( E_{22} \) band. The branching ratio \( \alpha \) between these two pathways, the values of the linear relaxation rate \( k_{21} \) and nonlinear annihilation rate \( \gamma \) are all sensitive to the phase space filling factors. Through fitting the same experimental data based on the continuum model (Fig. 6.5b) and the stochastic model (Fig. 6.7a), we found that all these values are markedly different.

It is noteworthy that the phase space filling factors used in the two theoretic model are also very different: \( N_1 \) and \( N_2 \) were chosen to be 2000 and 50 for the continuum model and the stochastic model, respectively. Since the initial kinetics have to be independent of the model used for calculations (either the continuum or stochastic model), use of different phase space filling factors result in differences in \( \alpha, k_{21} \) and \( \gamma \) values needed for the best fits of the experimental data. Moreover, the annihilation rates determined according to the optimum model is dependent on excitation intensity, and the defined value of \( 1/\gamma \) varies linearly with \( A \). However, this is not the case for the stochastic model, where the annihilation rate is found to be almost independent of the excitation intensity. Indeed, for the chosen phase space filling factors, \( N_1 = N_2 = 50 \), the saturation of the maximal bleaching signal occurs at very similar excitation intensities for the \( (7, 5) \) inner tube of a DWNT species upon pumping its \( E_{11} \) or \( E_{22} \) state (see Fig. 6.8b). When the excitation intensity exceeds this limiting value, the calculated kinetics remain almost invariant, and the obtained rate parameters (\( \gamma \) and \( k_{21} \)) are no longer dependent on the intensity. On the other hand, our calculations for the \( (6, 5) \) SWNT species with the same assumption for the phase space filling factors (\( N_1 = N_2 = 50 \)) show that the maximal bleaching signal starts to saturate at a much lower excitation intensity in the case of the \( E_{22} \) excitation than the corresponding intensity
for the $E_{11}$ excitation (Fig. 6.7c). As a result, the calculated kinetics still depend on the excitation amplitude for the chosen intensity in our simulations ($A = 1.7$), although to a lesser extent than what seen at lower intensities. For much higher excitation intensities when the maximal bleaching signal calculated for the $E_{11}$ excitation starts to saturate, the rate parameters become intensity independent. However, the maximal bleaching signal calculated for the $E_{22}$ excitation would remain invariant within a very wide region of $A > 1.5$. This difference in the intensity dependence for the $E_{11}$ and $E_{22}$ excitation could be overcome by assuming different phase space filling factors for the two excitonic bands ($N_1 < N_2$).

The kinetics measured experimentally can be reasonably well fitted using either the continuum or stochastic models. However, our calculations using the same sets of parameters lead to distinct differences in the dependence of the bleaching signal amplitude on the excitation intensity. The phase space filling factors $f_i(n_i)$ introduced in the equations of the continuum model (Eqs. 6.1 and 6.5) can partly account for the saturation effect found experimentally, and thus such modifications allow us to obtain the similar restriction effect. By taking the phase space filling restriction into account, we obtain from Eq. 6.5 (instead of Eqs. 6.2 and 11.3) that:

$$n_1(0) \approx \frac{G_{1,\text{max}}}{(1 + \alpha)\gamma N_1} \left(\sqrt{1 + \frac{2N_2^2(1 + \alpha)\gamma}{G_{1,\text{max}}} - 1}\right), \quad n_2(0) \approx 0 \quad (6.23)$$

when the pump pulse is in resonance with the $E_{11}$ exciton state, whereas

$$n_1(0) \approx 0, \quad n_2(0) \approx \frac{G_{2,\text{max}}}{k_{21} + \frac{G_{2,\text{max}}}{N_2}} \quad (6.24)$$

when the $E_{22}$ exciton state is excited. From Eqs. 6.23 and 6.24, it is clear that the saturation of the bleaching signal amplitude with increasing the excitation intensity is very gradual (see Fig. 6.5a,d), and the discrepancies from Eqs. 6.2 and 11.3 are obvious even at the intermediate intensities of excitation. On the other hand, in stochastic model the phase space filling appears naturally when the number of excitons reaches the maximum number of the energy states that are available in the system. This provides a much stronger (abrupt) saturation (Fig. 6.7c), which does not manifest itself at the intermediate values of the excitation intensity, and thus is in better agreement with experimental observations.

With the same stochastic model, we are able to reproduce quantitatively the initial portion of the kinetics and qualitatively the intensity dependence of the maximal bleaching signals by assuming only slower rates $k_{21}$ and $\gamma$ (Figs. 6.7 and 6.8). The nonlinear annihilation kinetics calculated in the frame of the stochastic model exhibit slower decay for delay times $> 400$ fs than the corresponding kinetics obtained according to the continuum model.[15,16,31] However, this slow-down is still insufficient to describe the kinetics observed experimentally. This is in contrast to the data from our previous studies on aqueous solutions of semiconducting SWNTs, where nonlinear annihilation of coherent excitons as the leading relaxation process is well identified at room temperature.[10,13,14] This discrepancy between our present and previous results suggests a possible sample dependence of exciton relaxation dynamics. In view of the strong environmental effects on exciton dynamics observed
by both single-tube and ensemble time-resolved experiments,[8,32] it may be not surprising
that the variation of nanotube surroundings can affect the mechanisms of exciton-exciton
annihilation.

As follows from qualitative analysis of the experimental data, a plot of the transient
absorption kinetics measured at room temperature as $(\Delta OD_0/\Delta OD(t) - 1)^2$ scales linearly
with time on a long delay times (picoseconds and longer), and thus can be attributed to
the 1D diffusion-limited annihilation.[29] It indicates a change of the physical mechanism of
exciton-exciton annihilation from involving delocalized coherent excitons to localized ones
at the intermediate time scale, from a few hundreds of fs up to 1 ps (see Figs. 6.3c and
6.6b). This possible change of physical mechanisms of exciton-exciton annihilation can be
understood in a following way. Initially the exciton density is high enough so that the
wavefunctions of coherent excitons are overlapping in the nanotube. As a result, the nonlinear
annihilation process involving coherent excitons dominates. The resulting exciton relaxation
leads to decrease of the concentration of excitons, and consequently their wavefunctions will
no longer overlap. In this case, exciton diffusion becomes a dominant factor in the nonlinear
exciton annihilation.[29] Evidently, this mechanistic change in the nonlinear annihilation
process will result in a corresponding rate decrease owing to the finite exciton diffusion
timescale. Therefore the kinetics on the intermediate and long times should be attributed
to nonlinear annihilation between excitons which are affected by their scattering on the
lattice imperfections caused by the external conditions. These external conditions could also
stimulate the spontaneous symmetry breaking or so-called Peierls distortion expected in 1-D
systems.[33] As the result of these processes, the exciton diffusion starts to dominate. On the
other hand, the data collected at temperatures below $\sim 200$ K, such as at 110 K (Fig. 6.3d)
indicates an annihilation process involving long-lived coherent excitons. This observation is
qualitatively in line with the long exciton dephasing times found at low temperatures.[22]

6.6 Summary

A new picture is emerging of excitons in semiconducting SWNTs in which the character
of the excitation and its dynamical behavior vary remarkably as a function of time following
excitation. Using femtosecond transient absorption measurements on the (6, 5) SWNT type
and the (7, 5) inner tubes of a dominant DWNT species we found that the dynamics of
exciton relaxation depends strongly on their method of preparation - either directly into
$E_{11}$ or via ultrafast relaxation from $E_{22}$. For excitons created directly in $E_{11}$ the initial
state comprises multiple overlapping coherent excitons. As exciton-exciton interaction does
not require exciton motion, rapid exciton-exciton scattering and exciton-exciton annihilation
ensues. Following this initial annihilation phase, the remaining excitons may still be coherent
for timescales of 1 ps.[28] Qualitative analysis of the $E_{11}$ transient decay kinetics at longer
delay times ($\leq 1$ ps) indicates occurrence of diffusion-limited exciton-exciton annihilation,
and therefore these results support the concept based on the diffusion type of exciton-exciton
annihilation as observed on long time scales.[17,18]
The exciton annihilation process produces complex behavior in the optical response that is sensitive to how the \( E_{11} \) state is populated. When \( E_{22} \) is initially populated, the subsequent phonon-mediated relaxation leads to exciton occupation at the \( E_{11} \) state with various momenta. Relaxation of all these excitons is ‘visible’ in transient absorption experiments: those with close to zero momenta are through stimulated emission of the \( E_{11} \) state and its excited-state absorption, and the rest with finite momenta are through ground state recovery. In contrast, direct excitation of the \( E_{11} \) state will create excitons with negligible momentum and subsequent relaxation is expected to be more rapid, provided that this process is faster than the thermalization. Experimentally, a clearly slower decay is indeed observed when the \( E_{22} \) state of the (6, 5) tubes is excited than the one measured with its \( E_{11} \) excitation. This difference is even more pronounced for the (7, 5) inner tube species. Striking differences in the excitation intensity dependence are further found for the maximal bleaching signals obtained for both the (6, 5) and (7, 5) tubes upon excitation of their corresponding \( E_{22} \) or \( E_{11} \) states. The former exhibits a linear dependence on the \( E_{22} \) excitation intensity, whereas the latter scales linearly with the square root of the \( E_{11} \) excitation intensity. This complex picture is not fully included in our theoretical model yet. The \( E_{22} \) to \( E_{11} \) transition is present in our scheme while population distribution in the \( K_{CM} \)-space of the \( E_{11} \) excitons arising from this relaxation is not taken into account.

In order to better understand these experimental findings, we develop the continuum model and stochastic model by explicit consideration of the annihilation of coherent excitons and a branching parameter. Our numerical simulations show that both models can reproduce reasonably well the initial portion of decay kinetics measured upon the \( E_{22} \) and \( E_{11} \) excitation of the chosen tube species but with significantly different sets of adjustable parameters. In particularly, our calculations based on the stochastic model give qualitatively better agreement with the intensity dependence observed experimentally than those obtained with the continuum model. However, it should be pointed out that the complex behavior in the optical response depending on how the \( E_{11} \) state is populated is not fully included in our theoretical model yet. While the \( E_{22} \) to \( E_{11} \) transition is present in our scheme, population distribution in the K-space of the \( E_{11} \) excitons arising from this relaxation is not taken into account. Nevertheless, we believe the kinetic models developed here may provide important insight into how multiple exciton states are involved in the annihilation and impact ionization processes in SWNTs, which may play a key role in practical applications such as development highly-efficient SWNT photodiode devices.[34]

6.7 References


Chapter 7

Ultrafast Exciton Dephasing


Femtosecond two-pulse degenerate four-wave mixing spectroscopy was applied to study the exciton dephasing in a broad range of excitation intensity and lattice temperature. We find that both exciton-exciton and exciton-phonon scattering have profound effects on the dephasing process. The dominant phonon mode involved in the dephasing is identified as the out-of-plane, transverse optical mode with a frequency of 847 cm$^{-1}$. The extracted homogeneous linewidths at all measured temperatures are in excellent agreement with the results of a single tube photoluminescence experiment.

7.1 Introduction

A single-walled carbon nanotube (SWNT) is a one-dimensional (1-D) seamless cylinder of a one-atom thick graphitic sheet. Depending on its structure defined by two indices $(n, m)$, it can exhibit either metallic or semiconducting characteristics [1]. The spatial confinement in the transverse direction gives rise to markedly enhanced Coulomb correlations and many-body interactions[2, 3]. An unambiguously identified effect is the formation of neutral excitons in semiconducting SWNTs upon optical excitation, which are characterized by an anomalously large binding energy which is a substantial fraction of the bandgap energy ($\sim$0.4 eV [4, 5]). These excitons determine essentially all the optical properties of semiconducting SWNTs [6].

In general, the excitons created in semiconductors with an ultrashort laser pulse initially posses a definite phase relationship among themselves and with the electromagnetic radia-
Subsequent scattering among themselves and with charged carriers, phonons, impurities and defects will lead to decoherence or dephasing, and eventually de-excitation or exciton population relaxation. Investigations of exciton dynamics in this coherent regime employing coherent transient spectroscopy [7] have offered an excellent opportunity of learning fundamental physics in a variety of systems, including many quantum-confined materials such as quantum wells [8-10], wires [11, 12] and dots [13, 14]. Determination of the time scales of various dephasing processes has further provided a wealth of information about the intrinsic homogenous linewidths of specific exciton transitions directly through an ensemble measurement [9, 11, 12].

Ultrafast dynamics of exciton population relaxation in semiconducting SWNTs is an active field and has recently been reviewed [15]. The coherent behavior of SWNTs, however, has not been explored experimentally. Studies of exciton dynamics in the coherent regime are important for understanding the complex interactions among various quasi-particles in this strongly confined, 1-D system, and for identifying their potential contributions to the exciton dephasing process. The spectroscopic information gained from such studies is also particularly valuable, because the substantial heterogeneity in all currently available samples leads to significant inhomogeneous broadening of spectral lines, and because the data obtained from single-tube spectroscopy is currently very limited and gives highly variable results even for the same tube type [16-18]. Here, we present an experimental study of ultrafast exciton dephasing in semiconducting SWNTs. The exciton dynamics in the coherent regime is investigated by femtosecond two-pulse degenerate four-wave mixing (FWM) experiments. Our measurements for a broad range of excitation intensity and lattice temperature enable us to separate the effects of exciton-exciton and exciton-phonon scattering on exciton dephasing. Quantitative analyses of our data further allow us to identify the dominant phonon mode involved in the dephasing process, to determine the decay timescales of the FWM signals, and to estimate the corresponding homogeneous linewidth of the lowest exciton transition of selected tube species.

7.2 Experimental Details

The sample used in this study is highly enriched in a single semiconducting tube type, the (6, 5) nanotube, which was isolated through density-gradient ultracentrifugation [19]. The obtained aqueous solution was mixed with appropriate amount of water soluble polyvinylpyrrolidone (PVP) polymer to fabricate a thin composite film. Use of this solid sample greatly suppresses the light scattering arising from motion of nanotubes in the solution. Measurements of linear absorption and steady-state fluorescence emission spectra confirm that the nanotubes remain individualized after being transferred from the solution to the solid film.

We studied the coherent exciton dynamics using femtosecond two-pulse degenerate FWM spectroscopy. The light source was an optical parametric amplifier pumped by a 250 kHz Ti:Sapphire regenerative amplifier [20], which was tuned to a central wavelength of 990 nm.
in order to resonantly excite the lowest excitonic transition \( E_{11} \) of the \((6,5)\) tube (see Fig. 7.2). In this experiment, two nearly equal intensity laser pulses of 45 fs duration with a variable decay \( t_{12} \) are focused to the sample. The first pulse with wavevector \( k_1 \) generates a coherent macroscopic polarization of the exciton ensemble, and when the second pulse with wavevector \( k_2 \) arrives before the dephasing of the induced polarization an interference grating is produced. This transient grating diffracts photons into the background-free, phase-matching direction \( 2k_2 - k_1 \). A schematic of the FWM geometry is shown in Fig. 7.3a. As the time delay \( t_{12} \) increases, the amplitude of the grating decays and the diffracted signal decreases. Measurement of the diffracted signal as a function of \( t_{12} \) yields a time scale that is directly proportional to the dephasing time \( T_2 \) (see following discussion). The diffracted signal was detected in a time-integrated manner with an InGaAs photodiode and a lock-in amplifier.

### 7.3 Results and Discussion

We performed measurements at seven lattice temperatures ranging from 77 to 292 K, and at each temperature several different excitation intensities between 1.74 and 12.21 \( \mu \)J/cm\(^2\) were employed. Fig. 7.3b shows the data collected at 100 K for five different excitation intensities. Here, the intensity of the FWM signal is plotted as a function of the time decay \( t_{12} \). The decay of the diffracted signal depends strongly on the intensity, manifesting by a significantly faster decay with increasing intensity. Quantitative analysis employing a least square deconvolution fitting algorithm with explicit consideration of the finite temporal response shows that the decay time \( (\tau_{\text{decay}}) \) decreases from 71 fs at 1.74 \( \mu \)J/cm\(^2\) to 36 fs at
12.21 $\mu$J/cm$^2$. Such a trend of the decay time change with excitation intensity is also observed at other lattice temperatures measured (77, 130, 160, 200, 250 and 292 K). Furthermore, a comparison of the data collected at $\sim 1.74$ $\mu$J/cm$^2$, the lowest intensity used in this work, demonstrates a clear temperature effect (see Fig. 7.3c). The decay time extracted from the data decreases from 77 fs at 77 K to 35 fs at 292 K. The observed strong dependence on temperature and excitation intensity provides the direct evidence for the involvement of both excitons and phonons in the exciton dephasing process.

The markedly enhanced contribution of phonons to the exciton dephasing with increasing temperature results in strikingly distinct excitation intensity effects on the FWM decays at different temperatures. For the given seven-fold increase of excitation intensity, we find that the reduction of $\tau_{\text{decay}}$ at 292 K (from 35 to 22 fs) is three times smaller than that observed at 77 K (from 77 to 36 fs). This temperature-dependent phonon contribution further leads to a prominent difference in the intensity dependence of the corresponding dephasing rate, $1/T_2$, or equivalently the homogeneous linewidths [full width at half maximum (FWHM)] $\Gamma_h$ of the $E_{11}$ transition, at different lattice temperature. Here, the dephasing time $T_2$ is calculated from the $\tau_{\text{decay}}$ by assuming $T_2 = 4 \tau_{\text{decay}}$, which is strictly valid for a strongly inhomogeneously broadened, independent two-level system. The corresponding $\Gamma_h$ value is then obtained from $\Gamma_h = 2\hbar/T_2$, and is indicated by the label on the right-side of Fig. 7.3. As shown in Fig. 7.3, the dephasing rate (or the homogeneous width) at 77, 100 and 130 K increases linearly with intensity. Such linear dependence has been observed in quantum wells [9, 10] and wires [11, 12]. However, at higher temperatures, the dependence found for the same intensity change deviates obviously from linearity. This obvious deviation strongly suggests a pronounced phonon contribution at high temperature.

The linear intensity dependence of $1/T_2$ (or $\Gamma_h$) observed at 77, 100 and 130 K represents a typical characteristics of dominant exciton-exciton collision broadening. The linear dependence can be described by $1/T_2(N_x) = 1/T_2(0) + \beta N_x$, with $N_x$ the excitation density, $\beta$ the exciton-exciton scattering parameter, and $1/T_2(0)$ the temperature-dependent zero-density dephasing rate. $N_x$ is estimated from an absorption cross section ($5.2 \times 10^{-14}$ cm$^2$ per tube), a mean tube length of 600 nm, the measured $1/e^2$ beam diameter (148 $\mu$m) and the excitation intensity, and is depicted by the labels of the top axes of Fig. 7.3. The linear fits shown in Fig. 7.3a give a $\beta$ value of 0.84, 0.85 and 0.78 ps$^{-1} \cdot \mu$m at 77, 100 and 130 K, respectively. The corresponding $1/T_2(0)$ values are 2.84, 3.01 and 3.67 ps$^{-1}$. As the absorption cross section employed in the calculation represents a lower limit of the actual value, the resulting $N_x$ must be underestimated. Consequently, this suggests that the $\beta$ values are an upper limit. Note that these $\beta$ values are several times smaller than those determined from 1-D quantum wires [11, 22], suggesting a reduced exciton-exciton scattering in semiconducting nanotubes.

By extrapolating the decay times determined at different intensities to the limit of zero intensity for each temperature, we can examine the contribution of the phonons to the dephasing without other effects. This extrapolation involves a nonlinear regression using an empirical function $\tau_{\text{decay}} = c_1 \exp(-I/I_0) + c_2$ ($I$ is the intensity, $c_1$, $c_2$ and $I_0$ are the variables). Similar results were also obtained using a hyperbolic function $\tau_{\text{decay}} = 1/(c_1 + c_2 I)$ for the data measured at 77, 100 and 130 K. The dephasing rate $1/T_2$ and the corresponding homogeneous width $\Gamma_h$ are plotted in Fig. 7.3 as a function of temperature. The resulting
Figure 7.2. (a) Schematic of the geometry of four-wave mixing. Here $t_{12}$ is considered positive (negative) when pulse 1 (2) precedes pulse 2 (1). (b) FWM signals measured at 100 K for five different excitation intensities. (c) FWM signals measured at 77, 130, 200 and 292 K under the lowest excitation intensity used for this experiment, which was 1.74 $\mu J/cm^2$. The dashed line is the auto-correlation function of the two laser pulses. All the data have been normalized at the signal maxima.
Figure 7.3. Dependence of the dephasing rates and the corresponding homogeneous linewidths on excitation intensity at different lattice temperatures. (a) 77, 100, and 130 K, (b) 160, 200, 250, and 292 K. The solid lines in (a) are the linear fits to the data obtained at 77, 100 and 130 K. The dashed lines in (b) are drawn to guide the eye. The corresponding exciton densities estimated from the absorption cross section, mean tube length, laser beam size at the focus and the excitation intensities are depicted by the scales on the top of the plots.
temperature dependence can be best described by the function: \( \Gamma_h = a + b \exp\left(-\Delta E/k_B T\right) \), where \( T \) is the lattice temperature, and \( \Delta E \) denotes an energy scale. The solid line in Fig. 7.3 is obtained with \( a = 4.2 \text{ meV} \), \( b = 254 \text{ meV} \), and \( \Delta E = 847 \text{ cm}^{-1} \). Note that the second term in the fitting function is equivalent to the thermal occupation function of optical phonons after neglecting the constant term of 1 in the denominator\([7, 10]\), which is negligible for the given \( \Delta E \) value and the temperature range. Thus from the fitting result we deduce a frequency of 847 cm\(^{-1}\) for the phonon mode involved in the dephasing. This frequency matches well with the frequency of the out-of-plane, transverse optical (TO) phonon mode found in the Raman spectra of both SWNT bundles and single tubes as a broad and weak feature\([23, 24]\). We therefore conclude that this TO phonon mode plays a dominant role in the exciton dephasing process. As this TO mode has an atomic displacement along the tube axis\([25]\), it can effectively modulate both the exciton binding energy and \( E_{11} \) energy, and thus induce dephasing. We found no evidence for contribution from much stronger G-band mode (\( \sim 1590 \text{ cm}^{-1} \)), which was predicted to dominate the exciton dephasing in recent calculations\([26]\).

It is interesting to note that the homogeneous widths determined in the zero-intensity limit are in excellent agreement with the results of a single tube photoluminescence (PL) measurement at all lattice temperatures we studied\([27]\). This agreement justifies the applicability of the simple relation \( T_2 = 4\tau_{\text{decay}} \). We therefore can confidently deduce in the zero-intensity limit an exciton dephasing time of 380 and 162 fs at 77 and 292 K, respectively. The dephasing time obtained at 77 K is very close to the result (350 fs) of a recent frequency domain, single tube PL experiment at 90 K \([28]\). Literature values for the homogeneous width vary substantially\([16-18]\). However, the experiments reported in refs. 27 and 28 were performed on as-grown, air-suspended nanotubes. In comparison to those experiments employing the tubes subjected to rigorous post-growth processing, these results should be least affected by environment \([15, 29]\), defects \([16]\) and unintentional doping \([18]\), and therefore we expect them to more closely reflect the intrinsic spectral properties of individual tubes. Moreover, the homogeneous width appears much narrower than the FWHM width of linear absorption spectrum, with room temperature FWHM widths of 8.1 and 50.3 meV, respectively. Clearly, the absorption spectrum shown in Fig. 7.2 is dominated by inhomogeneous broadening. Assuming a Gaussian distribution of the \( E_{11} \) energies, we estimate an inhomogeneous width of 49.7 meV. This gives a ratio of inhomogeneous to homogeneous widths of 6.1.

### 7.4 Conclusions

In summary, we have demonstrated that both exciton-exciton and exciton-phonon scattering processes have profound effects on exciton dephasing in semiconducting SWNTs. We find that both the dephasing rates and the corresponding homogeneous linewidths increase with excitation intensity. These intensity dependences vary markedly with lattice temperature. At 77, 100 and 130 K, the intensity dependence is linear, whereas a clear deviation from linearity is observed at higher temperatures. Analysis of the temperature dependence
Figure 7.4. The dephasing rates in the zero-intensity limit versus temperature. The solid line is a least squares fit. The corresponding homogeneous linewidths are depicted by the scales on the right side. See text for details. The crosses at 77, 100 and 130 K show the $1/T_2(0)$ values obtained through linear extrapolation.

of homogeneous linewidth in the zero-intensity limit further enable us to identify the dominant phonon mode as the out-of-plane TO mode with a frequency of 847 cm$^{-1}$. Moreover, the estimated homogeneous linewidths are in excellent agreement with the results of a single tube PL experiment. A large ratio of the inhomogeneous to homogeneous widths of 6.1 is estimated for the room temperature absorption spectrum, consistent with the presence of substantial sample heterogeneity. The observation of exciton coherence in semiconducting SWNTs that persists over 162 fs at room temperature and almost 400 fs at 77 K provides a sufficient window of studying many-body effects in real time, along with the resulting dynamical and spectroscopic signatures. Our finding may also stimulate exploration of potential applications such as in ultrafast all-optical devices.
7.5 References


Chapter 8

Photon Echo Spectroscopy and Absorption Lineshape Properties

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Three-pulse photon echo peak shift measurements were performed on semiconducting single-walled carbon nanotubes embedded in polymer matrix at room temperature. The peak shifts exhibit a striking dependence on the excitation intensity and an exceptionally large initial value. Simultaneous modeling of the peak shift data in the limit of zero-intensity and the linear absorption spectrum enable us to extract intrinsic spectral lineshape information through ensemble measurements. We found that the overall width of the chosen absorption band is dominated by inhomogeneous broadening with a full width at half maximum (FWHM) of 698 cm$^{-1}$. The intrinsic homogeneous linewidth is determined to be 178 cm$^{-1}$. From the simulation parameters, we further calculated a Huang-Rhys factor of 0.04 for the radial breathing mode vibration. This value suggests weak exciton-phonon coupling in semiconducting nanotubes, and is fully consistent with the observed large initial peak shift. Two-pulse photon echo experiments were also conducted for independent verification of the homogeneous linewidth and for direct quantification of the dephasing time scale. Finally, the exciton population relaxation dynamics were simultaneously measured using either transient grating or pump-probe experiments.
8.1 Introduction

Semiconducting single-walled carbon nanotubes (SWNTs) are one of the most intriguing nano-materials due to their large aspect ratios, size-tunable properties, and recent progress in fabrication and purification techniques\(^1\)\(^-\)\(^3\) The scope of optoelectronic applications for SWNTs depends critically on a detailed understanding of their underlying physical mechanisms, spectral features and excited-state dynamics\(^4\) Recent advances in the optical spectroscopy of semiconducting SWNTs have revealed specific spectral characteristics of structurally distinct tube species,\(^5\) the excitonic nature and binding energy of elementary excitations,\(^6\),\(^7\) and ultrafast dynamics at both the single tube and ensemble levels\(^8\).

One of the greatest challenges in the spectroscopic studies is the substantial heterogeneity in the samples currently available, which contain a variety of tube species with different indexes \((n, m)\). Besides metallic tubes, the samples typically contain variable amounts of semiconducting species with diameter distribution depending critically on the synthetic conditions\(^5\),\(^9\)-\(^11\). Even for the same tube type, the length, curvature, defect and surfactant wrapping can vary substantially from one tube to another. As a result, the frequency of a given excitonic transition varies accordingly, giving rise to significant inhomogeneous broadening of spectral lines. Assessment of the intrinsic, homogeneous linewidth is not possible from linear spectroscopic measurements of nanotube ensembles due to their inherent limitation in differentiating fast fluctuations of the transition frequencies (homogeneous broadening) from the static distributions (inhomogeneous broadening). Although such information should in principle be accessible by single tube spectroscopy, the reported results so far differ remarkably even for the same tube type, owing presumably to occurrence of defects,\(^12\),\(^13\) unintentional doping,\(^14\) and/or differences in tube environments.\(^12\),\(^13\)

In this paper, we report an experimental study of the spectral line broadening of the lowest allowed excitonic transitions of semiconducting SWNTs by exploiting two femtosecond four-wave mixing (FWM) techniques. Application of three-pulse stimulated photon echo peak shift (3PEPS) spectroscopy\(^15\),\(^16\) in combination with data simulations enable a clear separation of the homogeneous and inhomogeneous broadening of the selected spectral line directly through measurements on nanotube ensembles, and provides estimates of the strength and timescales of electron-phonon coupling. A complimentary technique employing degenerate two-pulse FWM spectroscopy or two-pulse photon echo (2PE) allows for quantification of the timescale of exciton dephasing and independent determination of the corresponding homogeneous linewidth. Furthermore, transient grating (TG) and pump-probe (PP) spectroscopy permit measurement of exciton population relaxation dynamics under the excitation intensities used for 3PEPS and 2PE experiments, respectively.

8.2 Experimental Methods

The sample used for this study is a nanotube-polymer composite film of \(\sim 200 \mu m\) thickness. Use of such a sample greatly suppresses scattering arising from slow tube motion in an
aqueous solution, and enables measurement of photon echo signals at low excitation powers and long population times with a high signal-to-noise ratio. The starting material is a commercial D$_2$O suspension of the CoMoCAT nanotubes dispersed individually with surfactant sodium dodecylbenzene sulfonate (NaDDBS, SouthWest Nano Technologies, Inc.). The suspension was mixed with appropriate amount of water-soluble polyvinylpyrrolidone (PVP) polymer, drop-cast in layers into a Teflon mold and slowly dried in a desiccator to yield an optical quality sample with no visible aggregation. Although the linear absorption spectrum of the polymer film exhibits a clear red-shift and enhanced background with respect to the spectrum of the corresponding aqueous solution (Fig. 8.2a), the steady-state fluorescence emission spectra of the film show no sign of significant tube aggregation. As shown in Fig. 8.2b, upon resonant excitation of the second allowed excitonic states (E$_{22}$) of the (6, 5) and (7, 5) tubes, the emission from the corresponding E$_{11}$ states is much stronger than the emission band around 1150 nm. The presence of a broad, intense emission in the 1150 nm spectral region has been shown to indicate tube bundling$^{17,18}$.
The 3PEPS technique employed here has been described extensively elsewhere.\textsuperscript{15,16,19,20} In short, the light source was a 250-kHz Ti:Sapphire regenerative amplifier pumped optical parametric amplifier that generates 62 fs pulses with a central wavelength of 1018 nm. The laser pulse spectrum is indicated by the dotted line in Fig. 8.2a. This excitation wavelength was chosen to resonantly excite the lowest transition-allowed excitonic states ($E_{11}$) of the (6, 5) as well as the (7, 5) nanotubes, with the majority of absorption coming from the (6, 5) tubes. The laser beam was split into three replicas of equal intensity with wave vectors $k_1$, $k_2$, and $k_3$, and focused to the sample with a 15-cm singlet lens. Time-integrated photon echo signals at the two phase-matching directions $k_1 - k_2 + k_3$ and $-k_1 + k_2 + k_3$ were detected simultaneously with two InGaAs photodiodes connected to separate lock-in amplifiers. The intensity of the incident light was controlled with a waveplate and polarizer combination, and monitored with a reference photodiode. TG signals were measured using the same setup by setting the time delay between the $k_1$ and $k_2$ pulses to zero.

Separate 3PEPS measurements were also performed at selected excitation intensities on an aqueous suspension of individualized SWNTs. A quartz cell with a path length of 100 $\mu$m was employed in order to minimize laser light scattering and thermal lensing effects. As the measurements on the aqueous solution produced similar results to those obtained from the polymer film at similar intensities, we will focus on the data collected using the film which is of higher signal to noise ratio. All measurements were performed at room temperature (294 K).

The same setup was used for the two-pulse FWM experiment by blocking the third beam ($k_3$), and the diffracted signal was detected at the phase-matching direction $2(k_2 - k_1)$. In order to directly time resolve the exciton dephasing process from the diffracted signal, a shorter laser pulse with duration of 45 fs was employed. Simultaneous detection of the $k_1$ beam after passing through the sample further enabled measurement of the PP signals.

### 8.3 Results and Discussion

Representative time-integrated photon echo profiles collected in the two phase matching directions $k_1 - k_2 + k_3$ (open circles) and $-k_1 + k_2 + k_3$ (filled circles) are shown in Fig. 8.2 for the population times $T = 0, 50, 500$ and 900 fs. The echo signals are symmetric along the axis of coherence time ($\tau$). The peak shift ($\tau^*$) at each population time $T$ are obtained by fitting each of the echo signals to a Gaussian function and then calculating half the difference between their maxima. This calculation gives peak shifts of 26.7, 18.2, 12.8 and 12.6 fs for the data shown in Fig. 8.2, which progressively decreases with $T$ in response to electronic dephasing induced by nuclear motions.\textsuperscript{21,22} As discussed extensively in previous studies on molecular systems and quantum dots,\textsuperscript{19,21,23} the echo peak shift ($\tau^*$) plotted as a function of the population time is related to the time correlation function of the electronic transition frequencies $M(t)$,\textsuperscript{16,22}

$$M(t) = \frac{\langle \delta \omega_{eg}(0) \delta \omega_{eg}(t) \rangle}{\langle \delta \omega_{eg}^2 \rangle} \quad (8.1)$$
Figure 8.2. Normalized integrated photon echo profiles collected in the two phase matching directions $\mathbf{k}_1 - \mathbf{k}_2 + \mathbf{k}_3$ (open circles) and $-\mathbf{k}_1 + \mathbf{k}_2 + \mathbf{k}_3$ (filled circles) for the population times $T = 0$ (a), 50 (b), 500 (c) and 900 fs (d), respectively. The solid lines are the fits to Gaussian functions.
where $\delta \omega_{eg}$ is the transition frequency from the ground to the $E_{11}$ state.

Measurements on aqueous SWNT suspensions produced essentially identical 3PEPS results (see Fig. 8.3a, open squares) to those obtained using the PVP polymer film at comparable excitation intensities. This similarity indicates that the dynamics detected using 3PEPS spectroscopy are highly insensitive to the environment outside the nanotube and surfactants, and thus are in stark contrast to the dynamics of exciton population relaxation. More importantly, the similarity between the results measured from the aqueous solution and the PVP films confirms that embedding SWNT into PVP polymer films does not induce additional broadening of the spectral line-width. Otherwise, the residual peak shift at long population time ($T > 300$ fs) would be larger than that observed from the aqueous suspension. Moreover, this similarity provides further additional support for the absence of substantial tube aggregation in the polymer film samples.

One surprising finding of our 3PEPS studies is the strong dependence of peak shift on excitation intensity. As shown in Fig. 8.3a, the peak shift at a given population time increases sharply with decreasing excitation intensity. When the intensity is decreased 27 times, the peak shift increases at all population times by $\sim 25$ fs. To the best of our knowledge, such a dependence has not been observed for molecular systems or other nanoscale materials. While the observed peak shifts depend strongly on excitation intensity (see Fig. 8.3b), the decay timescale of the 3PEPS profiles themselves are largely invariant to intensity effects. This invariance is best illustrated by overlaying the peak shift profiles (Fig. 8.3b, inset) onto the curve collected at the lowest intensity. Each of the 3PEPS profiles can be satisfactorily described by a mono-exponential decay with a 60 fs decay constant and a time-independent non-zero offset. This time constant is very different from the time scales of exciton population relaxation, which were determined through TG measurements at the corresponding excitation intensities (see Fig. 8.3b). The TG signals measured at different intensities exhibit essentially identical kinetics, with their peak amplitudes linearly proportional to the excitation intensity. This behavior is fully consistent with the results of previous PP measurements. To extract the time scales of population relaxation from the TG data, we performed deconvolution fitting by explicitly considering the finite laser pulse width and the $E$-field squared nature of the TG signal. This fitting gives two time scales of 130 and 790 fs, both are much longer than the 60 fs decay time of the 3PEPS profiles.

The intensity dependence of peak shifts arises from exciton-exciton scattering and annihilation, and its analysis will be described elsewhere. Instead, we focus our analysis on extracting absorption lineshape information from the 3PEPS profile in the limit of zero-intensity, where complications from exciton-exciton interactions can be neglected. The invariance in the decay behavior of the 3PEPS profiles with excitation intensity (see Fig. 8.2b, inset) enables us to construct a zero-intensity 3PEPS profile. This construction involves measuring the peak shifts under different excitation intensities at selected population times, and then extrapolating the experimental data to the limit of zero-intensity. This extrapolation gives a $\tau^*(T=0) = 52$ fs, which is only marginally higher than the $\tau^*(T=0) = 50$ fs measured at the lowest experimental excitation energy (0.60 $\mu$J/cm$^2$ for all three beams). The constructed zero-intensity profile shown in Fig. 8.3 is obtained by shifting the entire 3PEPS
Figure 8.3. (a) Transient grating signals measured on the SWNT/PVP films (line colors match with corresponding 3PEPS excitation intensities in µJ/cm²). (b) Three-pulse echo peak shifts measured on the SWNT/PVP film at four different excitation intensities (in µJ/cm²). The inset shows that the 3PEPS profile collected at different intensities can all be superimposed by means of a linear shift in peak shift. The open squares depict the data collected from the aqueous solution at an excitation intensity of 27.8 µJ/cm². Due to pronounced scattering, measurement was possible only for a limited range of population times.
profile measured at the lowest excitation intensity by a 2 fs increment in peak shift. The resulting 3PEPS profile can then be modeled by conventional methods, since all the effects from the exciton-exciton interactions which dominate at higher intensities become negligible.

Our data simulation involves constructing an $M(t)$ that is capable of reproducing both the peak shift curve and the experimental linear absorption spectrum in the high-temperature limit ($2k_B T \gg \hbar \omega$, $\omega$ is the frequency of vibrations).\textsuperscript{15,22,28} A detailed description of the general procedure and the related theoretical background can be found in references 22,23,29 We begin our simulations with a simple form of $M(t)$, composed of a gaussian, exponential and static inhomogeneity terms. This simulation is found to capture the overall features of the extrapolated 3PEPS profiles except the weak oscillatory behavior. To improve the match between the simulation and the extrapolated zero-intensity 3PEPS profile, we add an additional term to simulate a damped vibrational frequency present in our data. The $M(t)$ can be written as,

$$M(t) = A_g \exp \left[ \left( -\frac{t}{\tau_g} \right)^2 \right] + A_e \exp \left( -\frac{t}{\tau_e} \right) + A_c \exp \left( -\frac{t}{\tau_c} \right) \cos(\omega_c t + \phi_c) + \sigma_{in}^2, \quad (8.2)$$

where $A$ and $\tau$ are the corresponding coupling strengths and time constants, respectively. Static inhomogeneity $\sigma_{in}$ is also included, which is defined as the standard deviation of the inhomogeneous distribution of transition frequencies. The simulated curve is in excellent agreement with the extrapolated zero-intensity 3PEPS profile (see the solid line in Fig. 8.3a). The parameters determined from this simulation are $A_g = 2 \text{ cm}^{-1}$, $\tau_g = 20 \text{ fs}$, $A_e = 18 \text{ cm}^{-1}$, $\tau_e = 200 \text{ fs}$ and $\sigma_{in} = 300 \text{ cm}^{-1}$. Note that $A_e + A_g = 20 \text{ cm}^{-1}$ is approximately one half the Stokes shift of the (6, 5) tubes, which equals to the total reorganization energy according to the fluctuation-dissipation theorem. Among the four additional parameters $A_c$, $\tau_c$, $\omega_c$ and $\phi_c$; $\omega_c$ was predetermined by independent curve-fitting employing an algorithm based on singular-value decomposition. The extracted frequency of 245 cm$^{-1}$ is fairly close to the frequency of the radial breathing mode (RBM) of 282 cm$^{-1}$ observed from a resonant Raman measurement on the PVP film sample (data not shown). The rest of the vibrational parameters extracted from our simulations are $A_c = 10 \text{ cm}^{-1}$, $\tau_c = 120 \text{ fs}$ and a phase factor $\phi_c = 4.5 \text{ rad}$.

To verify that the simulation parameters used are physically reasonable, we simulated the linear absorption spectrum via the relation

$$\sigma(\omega) = \frac{1}{\pi} Re \int_0^\infty dt \exp[i(\omega - \omega_{eg})t - g(t)], \quad (8.3)$$

where $\omega_{eg}$ is the transition frequency of the system and $g(t)$ is the line-broadening function that is obtained from $M(t)$.\textsuperscript{22} As shown in Fig. 8.3b, the simulated spectrum fits rather well to the experimental absorption spectrum, with an overall full width of half maximum (FWHM) of 720 cm$^{-1}$. The corresponding homogenous linewidth is calculated by setting $\sigma_{in}$ to zero in eq. 2, resulting in a value of 178 cm$^{-1}$. These results give a ratio of overall to homogeneous widths of 4.1. Note that the total width is an overestimate of the $E_{11}$ band associated with the (6, 5) tube because of the contribution from the (7, 5) tube and
Figure 8.4. (a) Zero-intensity three-pulse echo peak shift profile obtained by extrapolating the experimental data collected at 0.6 µm/cm². The solid line is the simulated curve based on the $M(t)$ described in eq. 2. (b) Measured (black line) and simulated (green line) absorption spectra. The red line represents the homogenous line shape calculated by setting $\sigma_{in}$ to zero (see text for details).
others. Based on Gaussian decomposition of the broad featureless absorption band of the PVP sample in the $E_{11}$ region, we estimate that the contribution from the (7, 5) and other tubes should not be greater than 25% of the total width. The homogeneous width may be also overestimated by a similar amount.

From the frequency and coupling strength of the vibrational contribution, we can further calculate the Huang-Rhys factor $S = \Delta^2/2 = A_c/\hbar\omega_c = 0.04$, where $\Delta$ is the dimensionless displacement between potential minima of the ground state and the resonant electronic state. This value is fully consistent with the results of recent $ab\ initio$ calculations and Raman experiments, and provides further evidence for weak exciton-phonon coupling in semiconducting SWNTs. Our simulations further provide one of the first experimental estimates for the time scale ($\tau_c = 120$ fs) for the damping of the RBM vibrational mode. The damping time is significantly shorter than the overall exciton population relaxation times, but is comparable to the timescale obtained for pure dephasing.

The exceptionally large values of the initial peak shift $\tau^*(T=0$ fs) make semiconducting SWNTs distinct from all previously studied molecular systems studied with similar pulse durations. At the lowest excitation intensity possible (0.60 $\mu$m/cm$^2$), we measured a initial peak shift of 50 fs. A slightly larger value of 52 fs is obtained by extrapolating the experimental data to the limit of zero intensity. Generally, large initial peak shift values are indicative of weak electron-phonon coupling. This is fully consistent with the small Huang-Rhys factor calculated using the simulation parameters. It is also in line with the rather small Stokes shift and reorganization energy, the latter was required for simulating our 3PEPS results. Further work is required, however, to determine the influence of the delocalization length of the coherent excitons on the effective exciton-phonon coupling. The extent to which exchange narrowing related effects, such as seen in molecular aggregates, reduces the apparent exciton phonon coupling strength is not yet clear.

As an independent verification of the homogeneous linewidth extracted from the simulation, we performed two-pulse FWM measurements on the same film sample. Fig. 8.3a shows the time-integrated FWM signal measured at an excitation intensity of 4.2 $\mu$J/cm$^2$, along with the auto-correlation profile of the two laser pulses (dotted line) and the fitting result (solid line). The FWM signal exhibits an essentially instantaneous rise for the negative delay times and reaches a maximum at a positive delay of $+37$ fs. This shift from the zero delay time corresponds well to the peak shift at $T = 0$ determined at a similar intensity. The decay of the FWM signal is best characterized by a timescale of $\tau_d = 19.5$ fs, obtained through a least squares fit with explicit consideration of the finite temporal response. From the extracted timescale $\tau_d$, we calculate the FWHM homogeneous linewidth $\Gamma_h$ through a simple relation $\Gamma_h = 2\hbar/T_2$, where the dephasing time $T_2$ is obtained from $\tau_d$ by $T_2 = 4\tau_d$. Although the latter relation is strictly valid only for a strongly inhomogeneously broadened, independent two-level system, our recent study on a sample that is highly enriched in a single tube species shows that the homogeneous linewidths obtained with this expression at different temperatures agree very well with the results of a single tube photoluminescence experiment. Calculation based on the same relation gives an homogeneous linewidth of 136 cm$^{-1}$ at room temperature, which is fairly close to the value (178 cm$^{-1}$) determined from our 3PEPS simulation.
Figure 8.5. (a) Two pulse echo signal measured at an excitation intensity of 4.2 µJ/cm². The solid line is the result of least squares deconvolution fitting, and the dotted line is the auto-correlation of laser pulses measured using thin nonlinear BBO crystal. (b) Pump-probe signal recorded simultaneously.
A simultaneously measured PP signal has a much slower decay (see Fig. 8.3b) and excludes any significant contribution from exciton population relaxation to the observed FWM signal decay. Based on the well-known relation between the dephasing time $T_2$, pure dephasing time $T_2^*$ and the population relaxation time $T_1$ for a two-level system

$$\frac{1}{T_2} = \frac{1}{T_2^*} + \frac{1}{2T_1},$$

we can deduce a $T_2^*$ value of 78 fs at room temperature. This result suggests that a proper description of ultrafast exciton dynamics in semiconducting SWNTs should take exciton coherence into account even at room temperature.

### 8.4 Conclusions

In summary, we have demonstrated that photon echo spectroscopy is an incisive technique for elucidating spectral lineshape information through ensemble measurements of semiconducting SWNTs. We observed a strong dependence of the peak shift on excitation intensity owing to simultaneous creation of multiple excitons and their mutual interactions. To overcome these multi-exciton complications, and to extract absorption lineshape information, we simulate the 3PEPS profile obtained in the limit of zero-excitation intensity. We find that the linear absorption spectrum associated with the transitions from the ground-states to the $E_{11}$ excitonic states of the abundant tube species is dominated by inhomogeneous broadening with a FWHM of 698 cm$^{-1}$. A much narrower homogeneous linewidth with a FWHM of 178 cm$^{-1}$ is obtained, which is close to the value (136 cm$^{-1}$) determined from a separate two-pulse degenerate FWM experiment at low but finite excitation intensity. The total width (720 cm$^{-1}$) is overestimated for the spectral band of the $(6, 5)$ tube because of the contribution from the $(7, 5)$ and other tubes, which amount to no greater than 25%. Determination of the very short decay time of the two-pulse FWM signal compared with the exciton population relaxation further enables us to conclude that the obtained finite homogeneous width arises primarily from a pure exciton dephasing process. Moreover, the exceptionally large initial peak shift observed at $T = 0$ suggests weak exciton-phonon coupling. This is further supported by the small Huang-Rhys factor calculated for the RBM using the simulated parameters. Future study employing ultrashort laser pulses of $< 20$ fs should enable assessment of the coupling strengths of high-frequency vibrational modes and excitons.
8.5 References


Chapter 9

Exciton-Exciton Annihilation Induced Dephasing


Three-pulse photon echo peak shift measurements were performed on semiconducting single-walled carbon nanotubes embedded in a polymer matrix at room temperature. We found a striking dependence of the peak shift on the excitation intensity. Numerical simulations based on a newly developed interacting-boson model demonstrate that the intensity dependence originates from a highly-nonlinear optical response initiated by exciton-exciton annihilation.

9.1 Introduction

The optical properties of semiconducting single-walled carbon nanotubes (SWNTs) are governed by excitons with anomalously large binding energies [1, 2, 3]. Understanding of exciton dynamics is important from the prospective of both fundamental research and potential applications [4]. Recently, investigations on the coherent phenomena of the excitons have emerged [5, 6]. Experiments in the time domain reveal that the dependence of the exciton dephasing rate \(1/T_2\) on excitation intensity changes markedly with temperature [6]. At 77, 100 and 130 K, a linear dependence on intensity is found, whereas a clear deviation is evident at higher temperature. This deviation indicates possible contributions from inelastic exciton-exciton scattering processes. A significant shortening of exciton population
relaxation times, $T_1$, with increasing temperature [7, 8] can enhance exciton dephasing at high temperature through the well-known relation: $1/T_2 = 1/T_2^* + 1/2T_1$ ($1/T_2^*$ is the pure dephasing rate). The results of recent single tube photoluminescence spectroscopy lend support to this inference, where a nonlinear dependence of homogeneous linewidth on excitation intensity was observed and attributed to exciton-exciton annihilation [5].

To unambiguously identify the effect of population relaxation on exciton dephasing, we employ time-integrated three-pulse photon echo peak shift (3PEPS) spectroscopy [9], which is capable of detecting simultaneously exciton dephasing and population relaxation. A key distinction of this incisive tool from conventional two-pulse photon echo or, equivalently, two-pulse degenerate four-wave mixing spectroscopy, is the presence of a population period. It offers the capability of elucidating directly the electronic dephasing induced by population transfer processes within the bandwidth of employed laser pulses. We present 3PEPS data for selected semiconducting SWNTs embedded in a solid polymer film. Surprisingly, we find a strong dependence of the photon echo peak shift on excitation intensity, which increases approximately exponentially with decreasing intensity. Note that previous intensive studies on molecules, molecular complexes and aggregates, and polymeric systems have shown that the peak shift is highly insensitive to the processes taking population out of the laser bandwidth [9].

To identify the origin of this striking intensity dependence, we carried out theoretical model simulations. Third order nonlinear response theory predicts that a plot of the peak shift as a function of population time $T$ follows closely the correlation function of transition energy fluctuation [10, 11], and its signal amplitude is proportional to the cube of excitation intensity. The strong dependence on the intensity observed in this study thus goes beyond the third order nonlinearity. We use a Mean-Field-Approximation (MFA) combined with non-perturbative numerical simulations to convert a complex many-exciton problem into a single exciton problem, and most importantly to calculate the contributions of induced polarizations beyond the usual third-order response. By extracting up to the 10th order contributions we show that the exciton-exciton annihilation process contributes substantially to the observed intensity dependent photon echo peak shift [12].

9.2 Experimental Methods

A commercial D$_2$O solution of the CoMoCAT nanotubes wrapped with surfactant sodium dodecylbenzene sulfonate (NaDDBS) was used to fabricate a thin SWNT-PVP (polyvinylpyrrolidone) composite film of $\sim 200$ µm thickness. Use of this solid sample enables significant suppression of the light scattering arising from the motion of nanotubes in the solution sample. A dichloroethane solution of laser dye IR26 was used for reference measurements, which was circulated through a 200 µm thickness flow cell with a peristaltic pump.

The 3PEPS technique employed here has been described extensively elsewhere [13]. In short, the light source was an optical parametric amplifier pumped by a 250-kHz Ti:Sapphire
A regenerative amplifier, generating 62 fs pulses at 1018 nm. This wavelength was chosen in order to excite resonantly the lowest transition-allowed excitonic state ($E_{11}$) of the dominant semiconducting species, the (6,5) tube. The laser beam was split into three replicas of equal intensity with wave vectors $k_1$, $k_2$ and $k_3$, and focused to the sample by a 15-cm focal length singlet lens. Time-integrated photon echo signals at the two phase matching directions $k_1 - k_2 + k_3$ and $-k_1 + k_2 + k_3$ were detected simultaneously with two InGaAs photodiodes connected to separate lock-in amplifiers.

Representative time-integrated photon echo profiles collected in the two phase matching directions for a population time $T = 50$ fs are plotted as a function of coherence time $\tau$ in the inset of Fig. 9.1. The peak shift at each $T$ is obtained by calculating half the difference between their maxima. The 3PEPS data collected at three different excitation intensities are plotted in Fig. 9.1 as a function of $T$. The most intriguing feature of the data is that the peak shift, $\tau^*(T)$, strongly depends on excitation intensity. For a given $T$, an increase of the intensity leads to an approximately exponential decrease of $\tau^*(T)$. This dependence is illustrated in Fig. 9.1a through the peak shift measured at $T = 0$. By contrast the data obtained from an IR26 solution (filled orange circles in Fig. 9.2a) shows a very small increase ($< 4$ fs) in accord with third order nonlinear response theory.

Fig. 9.2b compares dependence of the peak amplitude on intensity for SWNTs and IR26. The latter exhibits the expected cubic dependence, whereas the former saturates at very low intensity. A similar saturation behavior was also observed previously for the amplitude of the pump-probe signal and was identified unambiguously as originating from exciton-exciton annihilation [12]. Clearly, the photon echo signal from the SWNTs is no longer governed by the third-order induced polarization, and thus higher-order contributions must be taken into account in order to adequately simulate the unusual intensity-dependent peak shift data.

### 9.3 Simulations

Theoretical description of the correlations of multiple excitons in semiconductors is a challenging many-body problem [14, 15]. At the third order in the field, description of a two-exciton scattering process must account for not only the Coulomb interactions between the electrons and holes but also their Pauli exclusion.

The simplest tight-binding model Hamiltonian of electrons and holes in a semiconductor (no phonons) in real space is [21]

\[
\hat{H} = \sum_i \left[ \varepsilon_i^{(c)} \hat{c}_i^\dagger \hat{c}_i + \varepsilon_i^{(d)} \hat{d}_i^\dagger \hat{d}_i \right] + \sum_{ij} \left[ V_{ij}^{(cc)} \hat{c}_i^\dagger \hat{c}_j^\dagger \hat{c}_j \hat{c}_i + V_{ij}^{(dd)} \hat{d}_i^\dagger \hat{d}_j^\dagger \hat{d}_j \hat{d}_i \right] + \sum_{ij} \left[ \frac{1}{2} W_{ij}^{(cc)} \hat{c}_i^\dagger \hat{c}_j^\dagger \hat{c}_j \hat{c}_i + \frac{1}{2} W_{ij}^{(dd)} \hat{d}_i^\dagger \hat{d}_j^\dagger \hat{d}_j \hat{d}_i - W_{ij}^{(cd)} \hat{c}_i^\dagger \hat{d}_j^\dagger \hat{d}_j \hat{c}_i \right].
\]

Here $\hat{c}_i^\dagger$ is an electron creation operator at site $i$, $\hat{d}_i^\dagger$ is a hole creation operator; the operators without daggers are the conjugate annihilation operators. The electron on-site energies are
Figure 9.1. 3PEPS data obtained at three excitation intensities: 3.3 (green), 16.4 (orange) and 92.4 $\mu$J/cm$^2$ (black). The inset shows the normalized time-integrated photon echo profiles collected in the two phase matching directions $k_1 - k_2 + k_3$ (open circles) and $-k_1 + k_2 + k_3$ (filled circles) for the population time $T = 50$ fs and an excitation intensity of 18.9 $\mu$J/cm$^2$. The solid lines are the fits to Gaussian functions.
Figure 9.2. (a) The intensity dependence of the peak shifts at $T = 0$ fs obtained for the SWNT-PVP film (open green squares) and the IR26 solution (filled orange circles). The solid line is a mono-exponential fit. Black squares are the simulated result as a function of $\kappa$ depicted by the scale on the top of the plot (see text). This simulated result is also shown in the inset for a broad range of $\kappa$ values, and the vertical gray line is drawn for $\kappa = 1$, which separates the two intensity regimes. (b) Plot of the corresponding peak amplitudes of the time-integrated photon echo signals versus the cube of the excitation pulse energy. The dotted line is a linear fit to the IR26 data (orange), whereas the solid line through the SWNT data (green) is drawn to guide the eye. (c) Simulated 3PEPS decays at different intensities using Eq. 9.6. The solid lines connecting the symbols are for visual purposes.
$\varepsilon_i^{(e)}$, while those of holes are $\varepsilon_i^{(d)}$. Electron and hole hopping parameters are $V_{ij}^{(e)}$ and $V_{ij}^{(d)}$ respectively. These parameters characterize non interacting electrons and holes. The rest of the parameters are the Coulomb monopole-monopole interaction energies: $W_{ij}^{(cc)}$ between two electrons on sites $i$ and $j$, $W_{ij}^{(dd)}$ between two holes and $W_{ij}^{(cd)}$ between an electron and a hole. This Hamiltonian neglects exchange and four-point Coulomb integrals, however it captures the main exciton properties. The electrons and holes are fermions with nonzero anticommutators:

$$\hat{c}_i \hat{c}^\dagger_j + \hat{c}^\dagger_j \hat{c}_i = \delta_{ij}, \quad (9.2)$$

$$\hat{d}_i \hat{d}^\dagger_j + \hat{d}^\dagger_j \hat{d}_i = \delta_{ij}. \quad (9.3)$$

This Hamiltonian has been used to derive equations of motion for electrons and holes in semiconductors, where each atom is taken as a site. A hierarchy of equations of motion for electron and hole variables is obtained using the Heisenberg equation of motion. The hierarchy is truncated exactly at four-particle correlation functions when considering third order nonlinear optical signals. In this case only two electron-hole pairs need to be considered. Such an approach has been successfully used for semiconductors with the Hamiltonian parameters obtained from ab-initio simulations [14, 16, 17].

The nonlinear behavior of the final equations of motion originate from two sources: the Coulomb interaction and the Pauli exclusion resulting from the Fermion commutation relations. Instead of using the Fermion particle commutation relations for deriving equations of motion, the Pauli exclusion requirements in real space may be mapped into the nonlinear interaction potential of bosons as basic particles. While the boson commutation relations allow the existence of unphysical states, where two electrons (or two holes) as bosons may occupy the same state, such states may be excluded later by forcing their energies out of physical detection window, e. g. to infinity. The only anharmonic potential containing such divergencies is then solely responsible for nonlinear signals.

The four-point particle correlation truncation is approximate for our problem of high excitation intensities, because high-order many-body correlations may be important at these conditions. Their inclusion expands the hierarchy of necessary equations and the number of parameters considerably. The 3PEPS signal does not directly reveal the many-body resonances, instead it is most sensitive to various dephasing processes. Therefore instead of a full microscopic model, in this paper we develop a phenomenological model of delocalized interacting bosonic excitons representing exciton bands in momentum $k$ space, as inspired by effective bosonization techniques[18, 19]. On the basis of delocalized excitons, we treat the exciton bands as an anharmonic ladder of single-exciton, two-exciton, etc delocalized exciton bands, which is a sufficient level of sophistication for calculating the 3PEPS signal. The starting point of our modeling is the Hamiltonian of interacting single-type bosons, which are excitons in our case, coupled to a phonon bath and an optical field $E(t)$:

$$\hat{H} = \sum_{mn}^{m \neq n} (\delta_{mn} h_{mm} + h'_{mn}(Q)) (\hat{b}^\dagger)^m (\hat{b})^n - \hat{P} E(t) + \hat{H}_B, \quad (9.4)$$

where $h_{00} \equiv 0$, $\hat{b}^\dagger$ is the exciton creation operator, and $\hat{b}$ is the conjugate annihilation operator ($[\hat{b}, \hat{b}^\dagger] = 1$). $h_{11} \equiv \varepsilon$ is the energy of a single exciton, $h'_{mn}(Q)$ describes the
fluctuations induced by phonon coordinate $Q$, characterized by the bath Hamiltonian $\hat{H}_B$. Higher-orders of $h$ determine nonlinear exciton properties, such as biexciton binding energies $(h_{22})$ and resonances, etc. In principle the $h_{mn}$ parameter may be required for describing nonlinear signals up to $m$th order in the optical field. For isolated excitons ($h_{mm}' = 0, E = 0$), the Hamiltonian (9.4) conserves the number of particles. Since in the following we consider a resonant optical signal, where the laser is tuned to a single system resonance, this model of a single-type boson is sufficient to capture essential intensity-related effects. The interaction of the system with the optical field is represented by a polarization operator:

$$\hat{P} = \mu (\hat{b}^\dagger + \hat{b}), \quad (9.5)$$

where $\mu$ is the transition dipole.

This system response to the optical field is described by using perturbation theory with respect to the optical field. The Heisenberg equation is used to determine time evolution of the polarization operator, $i\hbar \dot{\hat{P}} = [\hat{H}, \hat{P}] [20, 21]$. Since $\langle \hat{P} \rangle$ is proportional to $\langle \hat{b} \rangle$, we obtain the equations of motion for the expectation values of products of operators $\hat{b}$. The lowest-order exciton variable is $b \equiv \langle \hat{b} \rangle$; the induced polarization is then $P = \mu b + c.c.$. System nonlinearities lead to an infinite hierarchy of coupled differential equations. These can be closed at a certain order in the incoming field [20]. In the MFA at the third-order in the field a single equation is obtained [20, 21]:

$$\frac{d}{dt} b = -i(\varepsilon - i\frac{\gamma}{2})b - i(\Delta - i\frac{3}{2}\gamma)b|b|^2 + i\mu E(t), \quad (9.6)$$

where $\Delta \equiv h_{22}/2$ is the biexciton binding energy, $\gamma$ is the linear exciton decay rate, and $\bar{\gamma}$ represents the nonlinear decay of excitons. These rates can be derived using second-order perturbation theory in the Markovian approximation from the off-diagonal fluctuation parameters $h_{10}'$ and $h_{21}'$. They are given by the Fermi-Golden rule:

$$\gamma = \frac{2\pi}{\hbar} |h_{10}'|^2 \rho(\varepsilon), \quad (9.7)$$

$$\bar{\gamma} = \frac{2\pi}{\hbar} |h_{21}'|^2 \rho(\varepsilon + \Delta), \quad (9.8)$$

where $\rho(\omega)$ represents the bath spectral density. The term proportional to $\bar{\gamma}$ is cubic in $\hat{b}$ and thus describes the transition from two excitons into a single exciton, i.e., reflects exciton-exciton annihilation.

The optical field in a 3PEPS experiment consists of three Gaussian pulses:

$$E(t) = \sum_j \mathcal{E}_j(t - \tau_j) \exp[ik_j r - i\omega_0(t - \tau_j)] + c.c. \quad (9.9)$$

where $k_j$ and $\tau_j$ are the wavevector and the central time of pulse $j$ with a Gaussian envelope $\mathcal{E}_j(t - \tau_j)$. We consider the same carrier frequency, resonant to the excitation energy, $\omega_0 = \varepsilon$. For convenience it is useful to consider chronologically ordered pulses with $k_1$ first, and delayed by times $\tau$ (between pulses 1 and 2) and $T$ (between 2 and 3). This set of pulses
generates a four-wave-mixing signal characterized by the induced nonlinear polarization, $P(t)$. It is given by the expectation value of the polarization operator and its time evolution may be calculated from Eq. (9.6) for a certain configuration of pulse delay times.

The photon-echo signal, $P_s(t)$, detected in the $-k_1 + k_2 + k_3$ phase matching direction [22]. We do numerical non-perturbative propagation of Eq. (9.6) to calculate the induced polarization at strong excitations. However, numerically propagated quantities continuously depend on the excitation intensity and all phase-matching contributions are entangled. Thus the photon echo contributions up to the 10th order in the field are extracted using phase cycling [23, 24], which is equivalent to spacial Fourier transformation. The general procedure to extract a certain phase-matching signal at high excitation intensities is as follows. The 2π interval of a j-th pulse phase $\Phi_j = k_j r$ is divided into $N$ points, $\Phi_j = \phi n$, $n = (0, ..., N - 1)$, with a step $\phi = 2\pi/N$; $N$ is the order of the signal at which the phase-matching contributions are extracted exactly. The time evolution of the variable $b$ is calculated for a certain pulse delay configuration according to Eq. (9.6) as a function of phases $b(\Phi_3, \Phi_2, \Phi_1)$ of three pulses. The $uk_1 + vk_2 + wk_3$ phase matching exciton variable may then be obtained using

$$\bar{b}_{uvw} = \sum_{\Phi_3, \Phi_2, \Phi_1} b(\Phi_3, \Phi_2, \Phi_1) e^{-i\Phi_3 - i\Phi_2 - i\Phi_1}.$$  \hspace{1cm} (9.10)

Only homogeneous dephasing is included in Eq. (9.6) via parameters $\gamma$ and $\bar{\gamma}$ corresponding to the off diagonal bath fluctuations. Thus the phase-matched homogeneous photon-echo induced polarization is given by

$$P_h(t) = \mu b_{-1,1,1}.$$ \hspace{1cm} (9.11)

Structural fluctuations on various timescales induce motional narrowing (additional homogeneous contribution) and inhomogeneous broadening through diagonal Hamiltonian fluctuations $h_{11}'$ (for simplicity we neglect $h_{22}'$ and higher terms). Using the time correlation functions of these fluctuations their action is expressed through the line-shape functions $g(t)$ by cumulant expansion techniques [22]. We consider the transition frequency fluctuations ($\bar{\epsilon} \equiv h_{11}'$). They are characterized by Gaussian statistics and the corresponding correlation function is

$$\langle \bar{\epsilon}(\tau)\bar{\epsilon}(0) \rangle = 2\Gamma\delta(\tau) + \sigma_e^2 \exp(-\tau/\tau_c),$$ \hspace{1cm} (9.12)

where $\tau > 0$. Here $\Gamma$ and $\sigma_e$ are the strengths of fast and slow phonon modes, respectively, and $\tau_c$ is the correlation time of the slow mode. The line-shape function for this type of fluctuations is [22]

$$g(t) = \Gamma t + (\sigma_e \tau_c)^2 [\exp(-t/\tau_c) + t/\tau_c - 1],$$ \hspace{1cm} (9.13)

where for slow modes we use $\tau_c^{-1} \ll k_B T/\hbar$ (high temperature) and $\tau_c \sigma_e \gg 1$ (slow limit). This model for $\tau_c \rightarrow \infty$ leads to an absorption linewidth of $\sigma_e \sqrt{8 \ln(2)}$. The third-order induced polarization at the $-k_1 + k_2 + k_3$ phase-matching direction for the real line-shape function may be written in the form [22]

$$P_s(t_4) = P_h(t_4) \exp[-g(t_{21}) - g(t_{43}) + g(t_{32}) - g(t_{42}) - g(t_{31}) + g(t_{41})],$$ \hspace{1cm} (9.14)

where $t_{jj'} = t_j - t_{j'}$ are the delays between time-ordered pulses with $t_4$ standing for the signal detection time. $P_h$ and $P_s$ are the homogeneous and inhomogeneous signals, respectively. In
our simulations, even though they go beyond third order theory, we use Eq. (9.14) on top of the homogeneous signal extracted using Eq. (9.11) to account for diagonal fluctuations.

The photon-echo signal in the 3PEPS spectroscopy is a time-integrated intensity at a certain pulse delay configuration

$$ I_s(T, \tau) = \int dt_4 |P_s(t_4)|^2. \quad (9.15) $$

This is simulated for a grid of $T$ and $\tau$ values and the peak shift is extracted by the value of $\tau$, where $I_s(T, \tau)$ has its maximum amplitude, as a function of $T$. In our simulations the maximum $\tau$ value is determined using a parabolic interpolation procedure.

We choose the fundamental transition frequency $\varepsilon = 9800$ cm$^{-1}$, and the parameter $\Delta$, which characterizes the shift of the two-exciton resonances from $\varepsilon$, is set to zero by assuming that the exciton binding effect in 3PEPS signal is a secondary effect compared to exciton annihilation at high exciton intensities. The dephasing parameter $\gamma$ and the annihilation parameter $\bar{\gamma}$ are set to $\gamma/\varepsilon = 5.4 \cdot 10^{-5}$ (10 ps) and $\bar{\gamma}/\varepsilon = 6.75 \cdot 10^{-4}$ (800 fs) [25], respectively, and the inhomogeneous linewidth is chosen to be $\sigma_e/\varepsilon = 0.02$. The diagonal fluctuation parameters $\tau_c$ and $\Gamma$ were tuned to best reproduce the experimental data: $\tau_c \varepsilon = 4000$, $\Gamma/\varepsilon = 4.5 \cdot 10^{-3}$.

The annihilation rate $\bar{\gamma}$ controls the system susceptibility to different excitation intensities (see Eq. 9.6). When the ratio $\bar{\gamma}|b|^2/\gamma \ll 1$, the linear decay dominates. The annihilation is the main relaxation pathway in the opposite limit. This ratio can be estimated by linear response theory, which gives the maximum $|b^{(1)}| = \mu \bar{E}$, where $\bar{E} = \int d\tau E(\tau)$ is the time-integrated field amplitude. We approximate the polarization decay by $\sigma_e$ which is usually much larger than $\gamma$ and introduce an intensity parameter

$$ \kappa = \frac{\bar{\gamma}}{\sigma_e} \mu^2 \bar{E}^2. \quad (9.16) $$

The regime where exciton annihilation becomes important is uniquely defined by the excitation intensity and the ratio of the annihilation rate to the full linewidth.

In the inset of Fig. 9.2a we present the calculated dependence of initial peak-shift at $T = 0$ on the pulse intensity $\kappa$ (black squares). It clearly shows transition behavior from an intensity-independent regime $\kappa \ll 1$ into a regime where the peak shift rapidly decreases when $\kappa \gg 1$. The same calculated values are also plotted in Fig 9.2a for a narrower range of $\kappa$ values (from 1.2 to 230), showing very good agreement with experiment. Note that this comparison allows an estimate of the degree of system excitation in the experiment. The calculated 3PEPS decays at different intensities are shown in Fig. 9.2c. These decays describe the trend of the observed intensity dependence rather well.

### 9.4 Discussion

The experimental data demonstrate an unusual and striking effect of excitation intensity on photon echo peak shift. Our simulations capture the main feature of the experimental
Figure 9.3. Measured (symbols) and simulated (line) two-pulse photon echo profiles. The measured data was taken from Fig. 5 of ref. [27], where a full account of the experimental details can be found. The calculated data was horizontally shifted by $-15\text{fs}$ to account the effect of finite excitation intensity used to collect the experimental data.
findings - the intensity dependence of peak shift, and also offer insights into the physical mechanism underlying this unusual phenomenon. With current level of simplifications, our simulations still can not satisfactorily reproduce the decay behavior of the 3PEPS traces (compare the results shown in Fig. 9.1 and Fig. 9.2c). To improve the match between the experimental data and simulated results, it may be important to consider a full atomistic model of the nanotube. The simplifications we used include: (i) the MFA (no biexciton resonances [26]), (ii) neglect of multiple exciton scattering pathways by electrons/holes/excitons beyond phonon-induced annihilation, and (iii) the phenomenological spectral broadening scheme. However, since the 3PEPS (unlike pump-probe or two dimensional photon echo) does not directly resolve the many-body resonances but instead reveals dephasing processes, the phenomenological interacting-boson model built directly for delocalized excitons is adequate to explain our 3PEPS data and the physical phenomena behind them. The qualitative agreement between our simulations and the experimental results demonstrates that at high excitation intensities the system behaves as a simple nonlinearly damped oscillator.

The correlation time of slow bath fluctuations, $\tau_c = 2253 fs$, determined here is about one order of magnitude longer than the timescale ($\tau_e = 200 fs$) extracted from our previous simulations for an exponential decay term in the correlation function $M(t)$ [27]. This difference, at first glance, seems to indicate inconsistency between our previous and current work. However, direct comparison of these timescales is inappropriate because the forms of the correlation functions used are different (compare Eq. (9.12) above with Eq. 2 in ref. [27]). Instead, consistency between our previous and current simulations is verified through calculations of both 3PEPS and two-pulse photon echo signals using these $M(t)$ functions, and confirmed by the similar results for both cases (data not shown). We further find that the correlation function given by Eq. (9.12) can reproduce very well the decay behavior of an experimental two-pulse photon echo profile acquired using a similar SWNT-PVP film (see Fig. C.4). This long $\tau_e$ timescale accounts for both the slow bath fluctuations and the peak shift offset at population times longer than $\approx 300 fs$ (see Fig. 9.1). This offset was modeled by an additional term describing static inhomogenity in our previous paper [27]. The present correlation function thus constitutes the simplest model, which agrees approximately with the 3PEPS data.

9.5 Summary

The remarkable intensity dependence of the photon echo peak shift sets SWNTs apart from almost all other systems studied by this technique to date. Although a decrease of the photon echo peak shift with increasing excitation intensity was reported by Cundiff and coworkers for GaAs quantum wells, no analysis was presented and therefore the cause leading to the observed dependence remains unknown [28]. The strong dependence of the initial peak shift value (Figs. 9.1 and 9.2a), the absence of a dependence on population time [27], and the marked derivation from the typically observed cubic dependence on excitation intensity (Fig. 9.2b) found from the semiconducting SWNTs all imply the existence of a new dephasing mechanism dependent on the creation of multiple excitons.
According to our simulations the observed intensity dependence of peak shift arises from two levels of electronic dephasing - a characteristic, intensity-independent dephasing of single exciton and an intensity-dependent dephasing owing to an enhanced exciton-exciton scattering in this spatially confined system [6]. These dephasing processes are described in our simulations by the dephasing parameter $\gamma$ and the pulse intensity parameter $\kappa$, respectively. Since we let $\Delta=0$ in our simulations, we find that exciton-exciton annihilation makes a major contribution to the intensity dependence compared to other possible elastic and inelastic exciton-exciton scattering pathways.

9.6 References


Chapter 10

Exciton Annihilation and Dephasing Dynamics


Semiconducting single-walled carbon nanotubes (SWNTs) are one of the most intriguing nanomaterials due to their large aspect ratios, size tunable properties, and dominant many body interactions. While the dynamics of exciton population relaxation have been well characterized, optical dephasing processes have only been examined indirectly through steady-state measurements such as single-molecule spectroscopy that can yield highly variable estimates of the homogeneous linewidth. To bring clarity to these conflicting estimates, a time-domain measurement of exciton dephasing at an ensemble level is necessary. Using two-pulse photon echo (2PE) spectroscopy, comparatively long dephasing times approaching 200 fs are extracted for the (6,5) tube species at room temperature. In this contribution, we extend our previous study of 2PE and pump-probe spectroscopy to low temperatures to investigate inelastic exciton-exciton scattering. In contrast to the population kinetics observed upon excitation of the second transition-allowed excitonic state (E_{22}), our one-color pump-probe data instead shows faster relaxation upon cooling to 60 K when the lowest transition-allowed state (E_{11}) is directly excited for the (6,5) tube species. Analysis of the kinetics obtained suggests that the observed acceleration of kinetic decay at low temperature originates from an increasing rate of exciton-exciton annihilation. In order to directly probe exciton-exciton scattering processes, femtosecond 2PE signal is measured as a function of excitation fluence and temperature. Consistent with the observed enhancement of exciton-exciton scattering and annihilation at low temperatures, the dephasing rates show
a correlated trend with the temperature dependence of the population lifetimes extracted from one-color pump-probe measurements.

10.1 Introduction

Semiconducting single-walled carbon nanotubes (SWNTs) have recently shown strong potential for use as efficient fluorophores[1, 2] and photodiodes[3]. The development of such promising optoelectronic applications requires an understanding of the dominant many-body photophysics of these nanomaterials. Inherent one-dimensional confinement in nanotubes, greatly enhances electron-hole Coulombic interactions which give rise to strongly bound (0.4 to 1.1 eV binding energy) excitons whose transitions ($E_{11}$, $E_{22}$, etc.) dominate the optical spectra (figure 10.2).[4, 2, 3] These stable Mott-Wannier type excitons have yet to be fully characterized optically. In particular the short-time coherent behavior of excitons delocalized in SWNTs is an often overlooked property that determines important physical observables such as spectral line-broadening.[7] Coherent excitons occur when incident photons create delocalized excitations that have a definite phase relationship between themselves and the absorption of electromagnetic radiation creating them.[8] In the site basis, such delocalized excitons can extend for length scales up to the wavelength of the resonant excitation pulse. As time evolves, the nuclear modes of the nanotube and its surroundings couple to the coherent exciton causing both rapid dephasing and exciton localization toward its inherent radius of 1-2 nm.[4] In this contribution we use time-resolved spectroscopy as an incisive probe of inelastic exciton-exciton scattering and annihilation to investigate how these many-body scattering processes contribute to the overall dynamics of the $E_{11}$ transition.

The timescale of coherence between the ground and $E_{11}$ state is characterized by the dephasing time ($T_2$) required for $1/e$ of the coherence to decay from exciton scattering with phonons and other quasi-particles. In pump-probe experiments, $E_{11}$ population relaxation and annihilation processes overwhelm the contribution of the rapidly decaying coherent dynamics.[9] In order to directly access the timescales of optical dephasing, 2PE spectroscopy is used. 2PE measures the collective ability of an excited ensemble of SWNTs to maintain coherence after a variable time delay over which dephasing occurs. This process generates a macroscopic polarization or photon echo signal which decays primarily from exciton-phonon coupling, allowing direct extraction of the dephasing time.[9] For most molecular and solid state systems at room temperature, the electron-phonon coupling will dephase electronic coherence within 10s of femtoseconds. Recent determination of comparatively long $T_2$ times approaching 200 fs at room temperature in semiconducting (6,5) SWNTs highlights the important role of coherent excitons for the fundamental photophysics of this quasi one-dimensional nanomaterial.[10, 11] To better understand the long $T_2$ times recently observed in SWNTs,[10] we will review existing work and present new data acquired at low temperature to examine the contribution of multi-excitonic effects to optical dephasing.

The exciton dynamics associated with population relaxation from the $E_{11}$ state have been investigated through femtosecond transient absorption and time-resolved fluorescence
Figure 10.1. a. Simplified kinetic relaxation pathways from the lowest $E_{11}$ excitonic state with inclusion of exciton depletion by annihilation. b. Corresponding linear absorption and laser pulse spectra (dotted line) showing resonant excitation of the $(6,5)$ tube species embedded in PVP polymer. c. Two-pulse photon echo beam geometry on SWNT sample with emitted echo signal.

measurements.[7] While fluorescence-based results have already quantified the temperature-dependent relaxation kinetics, these measurements rely on indirect excitation of the $E_{11}$ state via relaxation from the corresponding $E_{22}$, vibronic bands or off-resonant excitation.[12, 13, 14] Such indirect measurement of $E_{11}$ kinetics are usually justified since the $E_{22} \rightarrow E_{11}$ relaxation occurs with approximately 80% efficiency on a roughly 40 fs timescale.[23, 10] However, because the electronic and phonon processes which couple the $E_{11}$ state to higher-lying states are not clearly understood, an $E_{11}$ transition excited directly may for instance be substantially more delocalized than one that relaxed from a higher lying state. This subtle question comparing $E_{11}$ relaxation dynamics for $E_{22}$ versus $E_{11}$ resonant excitation is investigated in detail elsewhere.[17] Instead, here we avoid such complications by using transient absorption spectroscopy where the $E_{11}$ state is excited directly. Previously, such one-color pump-probe measurements have been conducted at room temperature only, and reported that the $E_{11}$ population dynamics are dominated by depletion through rapid exciton-exciton annihilation.[18] After reviewing the established kinetics for exciton-exciton annihilation in SWNTs, we will describe the characteristics of annihilation at low temperature through pump-probe experiments. To understand the origin of the observed low temperature enhancement of exciton annihilation, we will discuss the correlation between the annihilation kinetics and the coherent dynamics of exciton-exciton scattering processes probed through 2PE measurements.

### 10.2 Sample Characteristics and Experimental

To unambiguously probe the $E_{11}$ exciton dynamics associated with a specific nanotube species using femtosecond pump-probe and 2PE spectroscopic techniques, a sample highly
enriched in a single SWNT chirality is desirable. We employed a sample highly enriched in the (6,5) tube species (see figure 10.2b for the linear absorption spectrum), which was prepared using a density gradient enrichment method.[31] The starting material was synthesized through the cobalt-molybdenum catalyst (CoMoCAT) technique, and the obtained SWNTs were subsequently dispersed via sonication in bile salts followed by ultracentrifugation.

Our measurements at room temperature were performed using aqueous suspensions of SWNTs with a quartz sample cell with a path length of 100 µm. For measurements at lower temperatures, we fabricated thin SWNT-polymer composite films of approximately 200 µm thickness by mixing the suspensions with either polyvinylpyrrolidone (PVP) polymer or gelatin and drop casting layer-wise into teflon molds. After drying in a dessicator, the solid films are removed from molds for spectral characterization and time-resolved experiments. Steady-state photoluminescence measurements on these films upon the $E_{22}$ excitation gives a sharp $E_{11}$ peak whose intensities are an order of magnitude stronger than the emission band around 1150 nm. The presence of a broad, intense emission in the 1150 nm spectral region has been shown to indicate tube-bundling.[20, 21] A Janis ST-100 cryostat with a Lakeshore temperature controller was used for measurement at low temperature, and a temperatures as low as 2.5 K could be realized using continuous flow liquid helium under reduced pressure.

The experimental setup for femtosecond 2PE and pump-probe spectroscopy have been described in detail previously and only a brief account will be given here.[22] The light source was an optical parametric amplifier pumped with a 250 kHz Ti:Sapphire regenerative amplifier. The 2PE experiments were performed by directly exciting the $E_{11}$ state of the (6,5) tube with 45 fs laser pulses centered at 995 nm for SWNT-PVP films, and 998 nm for SWNT-gelatin films in order to account for the spectral shift induced by different tube environment. The laser beam was split into two nearly equal intensity replicas and focused on the sample to a spot diameter of 148 µm (see figure 10.2c). The first pulse with wavevector $k_1$ creates a coherent microscopic polarization of the exciton ensemble that is allowed to dephase over a variable delay time or coherence time ($\tau$). After time $\tau$, a second pulse $k_2$ arrives producing an interference grating with respect to the partially dephased coherent polarization created by $k_1$. The time integral of the photon echo signal is detected in the phased-matched direction $2k_2-k_1$, with an InGaAs photodiode and a lock-in amplifier. A plot the diffracted signal as function of positive $\tau$ delay time shows a nearly monoexponential decay and the corresponding timescale ($\tau_{\text{decay}}$) can be accurately extracted through a least square deconvolution fitting algorithm with explicit consideration of finite pulse duration. For strongly inhomogeneously broadening systems, this will further allow us to determine the dephasing time through the simple relation: $T_2 = 4\tau_{\text{decay}}$.[9, 22] One-color pump-probe measurements were performed concurrently with 2PE experiments by directly detecting the $k_1$ beam as shown in figure 10.2c. The detection consists of an InGaAs photodiode and a lock-in amplifier. Parallel polarization between the pump and probe beams were used, and the pump beam fluence was controlled by a combination of a waveplate and a polarizer.
10.3 Kinetics of exciton-exciton annihilation

The exceptionally large absorption cross sections, which is estimated to be $5.1 \times 10^{-13}$ cm$^2$ for the $E_{11}$ transition of a 600 nm long (6,5) tube,[23] indicates the creation of an average of 1.4 excitons even under the lowest laser excitation fluence employed in this work (0.1 $\mu$J/cm$^2$). As revealed in previous studies, the interaction of these simultaneously created excitons will result in rapid annihilation leading to depletion of the $E_{11}$ state.[24, 25] For a one-color pump-probe experiment with resonant $E_{11}$ excitation, the exciton relaxation can be described by following rate equation,

$$\frac{dn_1(t)}{dt} = G_1(t) - \frac{1}{2} \gamma(t)n_1^2(t) - k_1n_1(t) + k_{i1}n_i(t)$$ (10.1)

where $n_1(t)$ is the population of the excitons, $G_1(t)$ is the exciton generation rate, $k_1$ is the linear relaxation rate to ground state, and $\gamma(t)$ is the exciton-exciton annihilation rate.[18, 26] In the annihilation process, a new exciton is created in a higher-lying state ($n_i(t)$) according to energy-momentum conservation, and its subsequent relaxation to the $E_{11}$ state is denoted by $k_{i1}$. This simplified kinetic model is outlined schematically in figure 10.2a.

For diffusion-limited annihilation in an extended system whose size is comparable with or larger than the exciton diffusion radius, the annihilation rate becomes time-dependent for systems with dimensionality ($d$) less than two. This rate can be expressed by $\gamma(t) = \gamma_0/t^{1-d/2}$, where $\gamma_0$ is the time-independent annihilation rate.[24] For one-dimensional systems like SWNTs and under high excitation intensity where the annihilation term dominates, equation 10.1 can be approximated by,[24]

$$\frac{dn_1(t)}{dt} \approx -\frac{1}{2} \gamma_0 t^{-1/2}n_1^2(t).$$ (10.2)

This equation can be solved analytically,

$$\frac{n_1(0)}{n_1(t)} - 1 = n_1(0)\gamma_0 \sqrt{t}.$$ (10.3)

As the pump-probe signal amplitude is proportional to $n_1(t)$, this equation suggests a linear dependence can be obtained when the signal amplitude is instead plotted as $(n_1(0)/n_1(t) - 1)^2$. Kinetics obeying this rate law with $d=1$ correspond to the annihilation arising from exciton diffusion along the nanotube axis.[24, 25] In figure 10.3 (inset), the one-color pump-probe signal for the $E_{11}$ state is plotted, where the change in normalized optical density ($\Delta OD(t)/\Delta OD_0$) is analogous to $(n_1(t)/n_1(0))$, and the negative signed signal indicates dominant contribution of photobleaching and/or stimulated emission. Three exponentials are necessary to fit the kinetic decay with corresponding lifetimes (and relative amplitudes) of 0.1 (60%), 1.6 (28%) and 38 ps (12%). The multiexponential decay originates from the nonexponential kinetics described by equation 10.2 owing to dominant contribution from exciton annihilation.[24] For laser intensities typical to pump-probe spectroscopy, exciton-exciton annihilation has been observed to dominate relaxation kinetics.[24, 25] Exponential relaxation is expected
Figure 10.2. One-color pump-probe signal resonant with the $E_{11}$ band at 995 nm (inset) for the (6,5) SWNTs in aqueous solution at room temperature. The decay is linear for times longer than 2 ps when plotted according to the square of equation 10.3 (see text). This suggests that the kinetic decay occurs predominately by annihilation via one-dimensional exciton diffusion at room temperature.

only for the longest decay components, when optically excited nanotubes are likely to have only one exciton left per tube.

Assuming one-dimensional diffusion-limited annihilation is the predominant decay mechanism, equation 10.3 can be used to fit the room temperature kinetics. Figure 10.3 shows the experimental data plotted as $(\Delta OD_0/\Delta OD(t) - 1)^2$ versus time, and gives a good linear fit, suggesting dominant one-dimensional diffusion-limited annihilation with a rate coefficient $\Delta OD_0 \gamma_0 = 4.1 \text{ ps}^{-1/2}$. For comparison we also consider the case of annihilation in two-dimensions. Solving equation 10.2 using a time-independent annihilation rate obtained for $d = 2$, we obtain

$$\frac{n_1(0)}{n_1(t)} - 1 = \frac{1}{2} n_1(0) \gamma_0 t. \quad (10.4)$$

Plotting $(\Delta OD_0/\Delta OD(t) - 1)$ versus delay time in figure 10.3 results in a nonlinear dependence on time. While this supports that annihilation occurs predominately by one-dimensional diffusion of excitons, for shorter timescales on the order of $T_2$ an annihilation process involving delocalized excitons may also contribute.

Previous time-resolved fluorescence and two-color pump-probe at room temperature showed that a model involving diffusion-limited exciton annihilation provides an excellent description for the kinetics obtained. However, at shorter delay times substantial deviation from this behavior was observed. For instance, time-resolved fluorescence kinetics reported for (9,5) tube type were more consistent with time-independent annihilation rates associated with two-dimensional diffusion of excitons described by equation 10.4. The Bohr radius, however is reported to be larger than the tube diameter, negating the possibility of two-dimensional diffusion of excitons in semiconducting SWNTs. Conse-
quently, Valkunas et al. suggested that at shorter times the necessity of time-independent annihilation rate may be because the excitons involved are sufficiently delocalized along the nanotube axis, and annihilate without diffusive motion.[24] Corroborating the involvement of delocalized excitons was the observation that the $E_{11}$ pump-probe signal amplitude scales only linearly with the square root of the excitation fluence, suggesting virtually instantaneous annihilation of excitons instead of slow diffusional transport.[18] These early results suggested that the coherent properties of excitons are an important component of the overall exciton dynamics in SWNTs. To further elucidate the importance of coherent excitons, we will examine how the dynamics of exciton annihilation change at lower temperatures by analyzing the one-color pump-probe data acquired upon resonant excitation of the $E_{11}$ state of the (6,5) tube species.

10.4 Temperature dependent exciton annihilation kinetics

For many molecular and solid state systems, the population lifetime is observed to increase as temperature is lowered. The excited state relaxation of such systems often involve highly localized Frenkel type excitons,[26] that relax non-radiatively primarily by exciton-phonon scattering. The temperature dependence of such a kinetic rate ($k_{NR}$) can be approximated as,

$$k_{NR} = k_c + C \exp(-\theta_k/k_b T)$$

(10.5)

where $k_c$ is the temperature independent decay rate, $C$ is a rate coefficient, $k_b$ is the Boltzmann constant and $\theta_k$ is the energy of the coupled phonon mode.[28, 29] For semiconducting SWNTs, equation 10.5 has been used to justify the overall decrease in the fluorescence decay rate when temperature is lowered moderately from ambient conditions.[30] Below approximately 80 K, a more complex dependence of population lifetime on temperature has been reported that requires a more detailed model.[12, 30, 31, 32] Two-color, $E_{22}$ pump and $E_{11}$ probe transient absorption measurements have also been reported down to 77 K on (6,5) and (7,5) SWNTs.[14] An increasing kinetic decay rate with temperature was reported, consistent with predominately non-radiative $E_{11}$ population relaxation suggested by the earlier time-resolved fluorescence results.[12, 33]

Previous temperature-dependent studies investigated the population relaxation from the $E_{11}$ state only indirectly through resonant $E_{22}$ excitation. Here, we report a one-color pump-probe measurement of the $E_{11}$ state of the (6,5) SWNTs, and the obtained decay rates increase upon cooling to 80 K (see figure 10.4). Our measurements were conducted for at least four different pump intensities for each sample temperature. Consistent with previous results obtained at room temperature, the peak amplitude of the pump-probe signal detected at low-temperature scales linearly with the square root of pump fluence. This observation again supports that the initial population relaxation is dominated by annihilation of excitons.[24, 3] Figure 10.4a (inset) shows the normalized pump-probe kinetics measured at three different
Figure 10.3. a. One-color pump-probe data collected for the (6,5) SWNTs embedded in PVP polymer at four different temperatures. The experiment was performed at 998 nm excitation with pump fluence of 4.0 µJ/cm². All the data were normalized at peak amplitudes of the signals, and the resulting decay profiles appear largely independent of the pump fluence (see inset, units in µJ/cm²). b. Plot of the amplitude weighted decay rate for the dominant two fast decay components versus the inverse square root of temperature gives a nearly linear relaxation.
pump fluences, and the resulting decay profiles appear largely independent of the pump fluence. A similar observation was reported previously by Valkunas et al. for the data collected at room temperature and was attributed to pronounced exciton annihilation at longer delay times.[24]

We extract the population decay timescales though fitting the one-color pump-probe data to a model function consisting of three exponential terms by employing a least square deconvolution fitting algorithm. The two shorter lifetimes contain dominant contributions from exciton-exciton annihilation. From these two lifetimes, we calculate a mean decay rate \( k \) by weighting the decay times with corresponding relative amplitudes. The obtained \( k \) values increase three fold upon cooling to 80 K. The resulting change of this mean decay rates with temperature is shown in figure 10.4, and is discordant with previous results obtained from resonant excitation of the \( E_{22} \) transition.[30, 12] Further support to the observed increase of mean decay rate with decreasing temperature was obtained by pump-probe measurements on both SWNT-PVP and SWNT-gelatin composite films. Possible complications from thermal induced spectral shifts were eliminated by repeating measurements at the red side of the \( E_{11} \) absorption band where the laser pulses were detuned by 18 nm. While considerable variations in the decay rate are observed for different embedding polymers and excitation wavelengths, in all cases the decay of the pump-probe kinetics accelerates upon cooling. These results show that for direct \( E_{11} \) excitation of the (6,5) tube species in polymer environments, the exciton population relaxation accelerates upon decreasing temperature.

To understand the one-color pump-probe results reported above, we first consider the contribution of the temperature dependent radiative rate. While \( k_{NR} \) is expected to decrease (equation 10.5), an increasing \( E_{11} \) radiative rate \( (k_R) \) has been reported upon cooling to the 80 K region.[12, 34] Early theoretical treatments by Spataru et al. showed that for moderately low temperatures, the radiative rate can be approximately described by the standard temperature-dependent rate equation for one-dimensional systems,

\[
k_R = k_o \sqrt{\frac{\Delta_r}{k_b T}}
\]

where \( k_o \) is the rate coefficient, and \( \Delta_r \) represents the maximum energy an exciton can occupy in the \( E_{11} \) band and still decay radiatively according to momentum conservation restrictions.[35, 27] This radiative decay gives a \( 1/\sqrt{T} \) dependence similar to the rates extracted from our one-color pump-probe experiments (see figure 10.4b). The very low fluorescence yield however, makes it implausible that the temperature dependence of the pump-probe signal arises from changes in the radiative rate, even though Spataru et al. suggest a \( 1/\sqrt{T} \) dependence for \( k_R \).[35, 27] This is in contrast to GaAs quantum wires where the temperature dependence of the decay rate is attributed to the variation of the radiative rate.[36] In the case of SWNTs evidence suggests that exciton annihilation is the dominant relaxation pathway in ultrafast spectroscopic studies, and therefore we must consider the temperature dependence of this process.[7, 12, 33]

The strong signatures of exciton annihilation observed at all temperatures enabled us to identify annihilation as the dominant relaxation pathway for pump intensities employed in ultrafast experiments. The corresponding temperature dependence associated with the
Figure 10.4. a. Pump-probe data collected at 60 (a), 77 (b), 110 (c) and 200 K (d) are plotted as \((\Delta OD_0/\Delta OD(t) - 1)\) (left axis) and \((\Delta OD_0/\Delta OD(t) - 1)^2\) (right axis) versus delay times, respectively. The dashed lines are fits to the linear portion of the data. Note a gradual shift of the linearity towards the predominately one-dimensional diffusion-limited annihilation model is observed upon warming sample toward ambient conditions.
exciton annihilation rate ($\gamma(t, T)$) for the $E_{11}$ state has not been investigated. Approximate temperature-dependent annihilation rates can be obtained through plotting the pump-probe data by assuming either a time-dependent or a time-independent annihilation rate according to equations 10.3 and 10.4 respectively, and then fitting the linear portion of the data (see figure 10.4). The same approach is used for the results obtained at room temperature (figure 10.3). As shown in figure 10.4, for temperatures ranging from 60 to 180 K we observe a remarkably linear relationship in the plots of ($\Delta OD_0 / \Delta OD(t) - 1$) versus time, suggesting that the $E_{11}$ exciton annihilation rate at low temperatures is predominately time-independent. Upon further increase in temperature, a gradual transition toward a linear relationship in the plot of ($\Delta OD_0 / \Delta OD(t) - 1$)$^2$ versus time is found, favoring one-dimensional diffusion-limited annihilation. This temperature-activated transition is further evidenced by a progressively decreasing slope upon warming (see figure 10.4). From equation 10.4, one can see the slope ($\frac{1}{2} \Delta OD_0 \gamma_0$) is directly proportional to the time independent annihilation rate $\gamma_0$. This parameter $\Delta OD_0 \gamma_0$ is found to decrease from 5.2 ps$^{-1}$ at 60K to 3.6 ps$^{-1}$ at 150 K, in accord with the enhanced exciton-exciton annihilation accelerating the one-color pump-probe decay rate at low temperature. Since the corresponding pump-probe data in figure 10.4 exhibits better linearity applying the time-independent ($d=2$) annihilation rate model at low temperature, it implies the involvement of coherently delocalized excitons in exciton-exciton annihilation. In order to investigate the role of coherent dynamics in exciton annihilation, we will discuss femtosecond 2PE results in the following section.

10.5 Optical dephasing and exciton-exciton scattering

2PE spectroscopy provides an indirect measure of coherent exciton scattering dynamics by quantifying the dephasing time, $T_2$. Recently, dephasing times of the $E_{11}$ state at room temperature and selected low temperatures were reported through extrapolating the temporal offset of photon echo signals (peak-shift)|[11, 18], and direct determination from the 2PE signal decay (down to 77 K).[10] In figure 10.5a, 2PE profiles are plotted for resonant $E_{11}$ excitation of the (6,5) SWNTs with a total fluence of 2.0 $\mu$J/cm$^2$, and essentially mono-exponential decays are found with $T_2$ times decreasing from 280 to 135 fs as temperature is raised from 60 K to room temperature. These results are consistent with our previous data obtained for temperatures ranging from 77 and 292 K.[10] The long $T_2$ times are supportive of a weak exciton-phonon coupling at low temperature that permits longer exciton coherences.[8]

The measured dephasing rates are directly proportional to the homogeneous linewidth ($\Gamma_h = 2\hbar / T_2$), which were recently shown to vary markedly as function of total excitation fluence.[10, 11] This strong intensity effect is also observed at lower temperatures, and as an example, figure 10.5b shows the 2PE data measured at 50 K. Increasing the excitation intensity by three fold leads to a significantly faster decay. As previously found for quantum wells and wires,[38, 39, 40] and more recently SWNTs[10, 41], this intensity-induced dephasing arises from exciton-exciton scattering processes and affects not only 2PE decays but also three-pulse photon echo peak shifts as recently reported. Abramavicius et al.[41] used
a non-perturbative phase cycling approach to calculate the contribution of exciton-exciton scattering and annihilation processes to the \(E_{11}\) exciton dephasing dynamics. A qualitative agreement with experiments was obtained by the inclusion of higher than third-order polarizations, suggesting the involvement of multi-exciton states induce optical dephasing predominately through annihilation pathways.\[41\]

The homogeneous linewidth (\(\Gamma_h\)) contains contributions from the broadening induced by exciton-phonon coupling processes (\(\Gamma_{ex-ph}\)), and from dephasing induced by exciton-exciton scattering (\(\Gamma_{ex-ex}\)).\[11, 10, 42\] If separable, the two broadening mechanisms sum to give the full-width at half maximum (FWHM) of the overall homogeneous lineshape according to,

\[
\Gamma_h(N_x, T) = \Gamma_0 + \Gamma_{ex-ex}(N_x, T) + \Gamma_{ex-ph}(T),
\] (10.7)

where \(\Gamma_0\) is defect related intrinsic spectral diffusion broadening, \(\Gamma_{ex-ex}\) is a function of both temperature and the exciton density per tube (\(N_x\)) and \(\Gamma_{ex-ph}(T)\) varies with temperature only.\[11, 42\] \(N_x\) was estimated from the absorption cross-section (\(1 \times 10^{-17} \text{ cm}^2\) per carbon atom)\[23\], a mean tube length of 600 nm,\[31\] the measured \(1/e^2\) beam diameter (148 \(\mu\)m) and the total excitation intensity. The strong contribution of \(\Gamma_{ex-ex}\) to the linewidth has also been observed in the frequency domain, where the linewidths of single-tube photoluminescence spectra increase markedly at high excitation fluences. The reported \(\Gamma_h\) values from the single-tube experiment are similar to our time-domain estimates for comparable tube types.\[43\]

By incrementally lowering the excitation intensity, we can extrapolate the \(\Gamma_h(N_x, T)\) values determined at different intensities to the zero intensity limit where the contribution from exciton-exciton scattering (i.e. \(\Gamma_{ex-ex}\)) can be neglected. The \(E_{11}\) exciton dephasing rates at selected temperatures for the (6,5) tubes embedded in a gelatin matrix are plotted in figure C.3a. The overall homogeneous linewidth scales linearly with excitation density (\(N_x\)) below 220 K for the data obtained using SWNT-gelatin films, and below 180 K for the SWTN-PVP polymer films (data not shown). The ordinate intercepts of figure C.3a give the zero intensity linewidth, \(\Gamma_h(N_x = 0, T) = \Gamma_0 + \Gamma_{ex-ph}(T)\). This linear extrapolation further allows the \(\Gamma_{ex-ex}(N_x, T)\) contribution to be determined using equation 10.7. For instance, at 80 K the \(\Gamma_{ex-ex}\) contribution to \(\Gamma_h\) increases from 4 to 16 meV as the estimated mean number of \(E_{11}\) excitons per tube changes from 2 to 17. This linear dependence\[8\] on \(N_x\) has also been observed in quantum wells and wires\[44, 40, 45\] where it is fit to,

\[
\Gamma_h(N_x) = \Gamma_h(0) + \beta N_x
\] (10.8)

where \(\beta\) (units in ps\(^{-1}\)\(\mu\)m) is the exciton-exciton collisional broadening parameter. For the (6,5) SWNTs, we determine the \(\beta\) values directly from the slopes of the linear dependences shown in figure C.3a, which appear strongly temperature dependent for the SWNTs embedded in both gelatin and PVP matrices. For temperature above the 200 K region, the dephasing rates begin to deviate from linearity, indicating that equation 10.7 cannot be used because the contributions from exciton-phonon and exciton-exciton scattering to the overall linewidth are no longer separable.

There is no obvious physical meaning ascribed to the \(\beta\) parameter, however work by May et al. shows that the \(\beta\) parameter approximates the relative magnitude of the the exciton-exciton scattering potential (\(V_x(q)\)), where \(q\) is the one-dimensional momentum space
Figure 10.5. a. Temperature dependence of 2PE signals measured at 60, 110 and 292 K (top to bottom) under the lowest excitation intensity used for this experiment, which was 2 µJ/cm² in PVP polymer films. The dashed line is the autocorrelation function of the laser pulse. b. Excitation intensity dependence of the 2PE signals measured from 4 to 15 µJ/cm² for SWNT-PVP polymer film at 50 K.
scattering coordinate. An approximate relationship is derived in Boldt et al. for a two-dimensional system, which is trivially simplified here for a one-dimensional excitonic system as,

$$\Gamma_h(N_x) = \Gamma_h(0) + \left( \sum_q |V_x(q)|^2 \frac{\Gamma_h(0)}{[E_0 - E(q)]^2 + \Gamma_h(0)^2} \right) N_x,$$

(10.9)

where the energy $E(q)$ is approximated as an $E_{11}$ parabolic band dependence, and $E_0$ is the free exciton energy. Comparing equations 10.8 and 10.9, it is readily seen that $\beta$ provides the evaluation of sum over $q$. While our data does not permit extraction of $V_x(q)$, the observation that $\beta$ decreases over two-fold with temperature does imply that the strength of the $E_{11}$ exciton scattering potential must also decrease with temperature. Since the exciton kinetic energy at low temperatures is smaller, an enhancement of exciton-exciton scattering potential further suggests the effective exciton mean free path is longer either due to fewer phonon scattering events or longer coherence lengths. Further analysis including calculation of $\beta$ from the one-dimensional exciton wavefunctions is still needed to understand the precise origin of the low temperature enhancement in the exciton-exciton scattering potential.

### 10.5.1 Exciton-exciton scattering and $E_{11}$ population relaxation

In the absence of complications from annihilation of excitons, a decreasing $E_{11}$ population decay rate is expected upon cooling as bath fluctuations that induce relaxation are frozen out. However, this expectation is opposite to what we found in this work. Instead, the temperature dependent kinetics obtained are consistent with a low temperature enhancement in the exciton annihilation rate $\gamma(t)$. This is further supported by a strong correlation between the temperature-dependent $k$ and $\beta$ parameters plotted in figure C.3b. This correlation links the observed acceleration in $E_{11}$ population decay at low temperatures to an enhancement in the exciton-exciton scattering rate. Enhanced scattering among coherent excitons provides a likely pathway which enables more efficient annihilation of exciton population out of the $E_{11}$ state as the nanotube temperature is lowered.

### 10.6 Summary

Previous studies using ultrafast spectroscopy show that exciton-exciton annihilation is a dominant process governing both population relaxation and exciton dephasing of the $E_{11}$ state in semiconducting SWNTs. Through examining both processes as a function of temperature, we find a correlation between coherent exciton-exciton scattering (characterized by $\beta$ or $V_x(q)$) and population depletion by annihilation (characterized by $\gamma_0$). This correlation suggests an important contribution from coherent exciton scattering to the observed rapid population decay of the $E_{11}$ state. Further evidence is obtained by careful analysis of one-color pump-probe data which reveals a temperature-activated transition from exciton-exciton annihilation kinetics requiring a time-independent rate constant to one.
that needs a time-dependent annihilation rate. Below 180 K, the pump-probe data can be satisfactorily modeled by a time-independent rate $\gamma_0$, indicating annihilation occurs without diffusion, but instead involving extensively delocalized excitons. The extracted annihilation
rates $\gamma_0$ decreased two-fold with increasing temperature. Collectively, the marked decrease in $\gamma_0$, temperature activated transition to diffusion-limited kinetics, and the correlation between the mean population decay rate and the exciton-exciton scattering potential for the $E_{11}$ state (figure C.3), all support that a strongly temperature dependent annihilation rate is the origin of the unexpected acceleration in the population decay rate at low temperatures. The reported temperature dependence of the exciton-exciton annihilation and scattering rate also presents new challenges to understand the more commonly applied two-color $E_{22}$ pump and $E_{11}$ probe results. The starkly different $E_{22}$ pump kinetics compared with direct $E_{11}$ excitation suggests that the $E_{22} \rightarrow E_{11}$ relaxation remains a poorly understood process requiring careful investigation.
10.5 References


A room temperature $E_{11}$ optical dephasing time ($T_2$) of 205 fs is measured for aqueous (6,5) single-walled carbon nanotubes (SWNTs), which is longer than comparable molecular systems or nanostructures. $T_2$ was extracted directly from the decay rate of the femtosecond two pulse photon echo response that was measured as a function of both excitation fluence and temperature. Longer dephasing times of 320 fs were obtained at 70 K, but upon further cooling to 2.5 K the extracted $T_2$ time decreased to 265 fs. This unexpected temperature dependence is explained with the aid of transient absorption measurements, which contain a dominant fast initial $E_{11}$ population relaxation component which accelerates below 80 K. By accounting for population relaxation, the corresponding pure optical dephasing rates $1/T_2^*$ are calculated and found to increase monotonically from 225 fs at room temperature to 508 fs at 4.4 K fs. Below $\sim$180 K, $1/T_2^*$ is found to scale linearly with temperature with a slope of $6.7\pm0.6$ $\mu$eV/K, indicative dephasing arising from one-phonon scattering from acoustic modes. Corroborating measurements using three-pulse photon echo peakshift (3PEPS) independently reproduced dephasing times obtained from the 2PE decay. To better understand how long room temperature pure dephasing times are realized in view of the large dynamic disorder of the surrounding environment, the nonexponential component of the photon echo decay was fitted. The extracted 2PE curvature suggests that the actual strength of exciton-phonon coupling is mitigated by motional narrowing which effectively averages over applied nuclear fluctuations. This further suggests the occurrence of remarkable initial exciton delocalization, and makes nanotubes ideal to study many-body effects in spatially confined systems.
11.1 Introduction

Semiconducting single-walled carbon nanotubes (SWNTs) are one of the most intriguing nanomaterials due to their large aspect ratios, size tunable properties, and dominant many body interactions.[1, 2] While SWNT electrical and mechanical properties have been well studied, fundamental optical properties are continuously emerging with new synthetic and purification developments enabling advancements such as great enhancements in fluorescence yields (up to 20%) and demonstration of highly efficient carbon nanotube photodiodes.[3, 4] The photophysical properties of this quasi-one dimensional (1D) material are determined by strongly-bound Mott-Wannier type excitons, which arise from an electron-hole Coulombic interaction that is greatly enhanced from 1D confinement effects.[5, 6, 7] Since the corresponding exciton binding energy composes a large fraction of the overall band-gap ($\sim 30\%$ for (6,5) SWNTs), excitonic transitions completely determine the optical properties of semiconducting SWNTs. As a consequence, the linear absorption and photoluminescence spectra produce relatively sharp peaks from transitions directly with the bound exciton states (see Figure C.1a). Ab initio calculations show each such transition (denoted $E_{11}$, $E_{22}$, and so on) occurs within a manifold of both optically bright and dark states, the latter of which are believed to play a critical role in exciton population relaxation processes[8, 9] and in determining the overall photoluminescence yield.[10, 11]

The excitons initially possess a definite phase relationship among themselves and with the electromagnetic radiation creating them.[12] The resulting coherent excitons can be spatially delocalized on an extended scale limited in principle only by the wavelength of the laser light. For semiconducting SWNTs with a length scale of $\sim 1\ \mu m$ or shorter, this would suggest that $E_{11}$ excitons may be initially delocalized up to the length of nanotube. Subsequent scattering with phonons, defects and impurities, etc. will lead to an exponential loss of coherence within an ensemble of SWNTs, and eventually exciton localization to a finite spatial length equal to its inherent radius of $\sim 1$-$2\ nm$.[5] A quantitative measure of this timescale where exciton coherence persists is the dephasing time ($T_2$), and its determination also provides a time-domain based measurement of the homogeneous linewidth though the inverse proportionality, $\Gamma_h = 2\hbar / T_2$.[13] During the dephasing time both population and ensemble phase will decay and the remaining excitons may be extensively delocalized. Currently, available estimates for the exciton delocalization lengths vary greatly from 10 to 100$s$ of nm.[14, 10]

The homogeneous linewidths of SWNT ensembles were first measured by femtosecond three-pulse photon echo peak shift (3PEPS) spectroscopy, which provided an indirect estimation of the $T_2$ timescales.[15] Shortly after, direct determination of the dephasing timescales was preformed using a femtosecond two-pulse photon echo (2PE) technique on a sample highly enriched in the (6,5) tube species. Using 2PE, long-lived $E_{11}$ coherences with a $T_2$ of 170 fs were reported at room temperature.[16] Similar dephasing times have been also reported for other tube types using indirect two-pulse photon peak shift measurements.[17] Observation of long electronic dephasing times at room temperature is striking in comparison to molecules, molecular complexes and aggregates which typically dephase on a sub 10 fs timescale.[18, 19] Crystalline systems such as two-dimensional GaAs quantum wells have moderately longer dephasing times approaching $\sim 95$ fs at 294 K.[12, 20, 21] In addition,
Figure 11.1. (a) Simplified electronic energy diagram for a semiconducting SWNT showing only the bright strongly bound $E_{11}$ exciton state with respect to the continuum. The corresponding 1D joint density of states (JDOS) diverges at band minimum, allowing for direct excitation of multiple excitons. Subsequent relaxation pathways can be both radiative ($k_R$) and non-radiative ($k_{NR}$) and may also involve a low-lying state (not shown). (b) $E_{11}$ linear absorption (green line) and steady-state fluorescence emission (orange line) spectra of (6,5) tube embedded in PVP polymer, together with a spectrum of a 45 fs laser pulse (dotted line). The inset shows the energies of the absorption maxima plotted as a function of temperature for two polymer-SWNT composites prepared using gelatin (filled circles) and PVP (open circles) polymer SWNT composites, respectively.
previous measurements at different excitation intensities and lattice temperatures (77-292 K) showed that both exciton-exciton and exciton-phonon scattering profoundly influence the dephasing timescales and the homogeneous linewidths of the $E_{11}$ transition.\[16, 17\]

Together the 3PEPS and 2PE results independently report that the homogeneous linewidth associated with the (6,5) $E_{11}$ transition is at least 4 fold smaller than the inhomogeneous contributions.\[16, 15\] Similar homogeneous linewidths have been also obtained from frequency-domain single-tube measurements.\[22, 23, 24\] One advantage of the ensemble based approach of photon echo spectroscopy, is its inherent averaging accounts for the differences in (6,5) tube characteristics (length, defects, etc.) and local environmental disorder. While correspondence can be found between the results obtained from time-domain ensemble measurements and frequency-domain single-tube spectroscopy, direct comparison is hampered by the often highly variable linewidths obtained from single-tube measurements even for the tubes with same chirality. In addition, reported single-tube fluorescence experiments employ indirect excitation of the $E_{11}$ band through its corresponding $E_{22}$ manifold, vibronic bands or off-resonance. The ensuing relaxation to the radiative $E_{11}$ state is typically accompanied by multi-phonon emission, which can cause additional dephasing not present in time-domain photon-echo measurements employing direct $E_{11}$ excitation.\[25\]

Although both time-domain photon echo and frequency-domain single-tube approaches are powerful tools to quantify the dephasing times ($T_2$), neither of them can directly provide the pure dephasing time ($T_{2}^{\star}$), which is related to the dephasing time $T_2$ and the population lifetime ($T_1$) through the well-known relation:

$$\frac{1}{T_2} = \frac{1}{2T_1} + \frac{1}{T_{2}^{\star}}$$

(11.1)

While the $T_2$ timescales can be readily obtained from 2PE measurements, proper determination of the $T_1$ values is not straightforward owing to the general existence of complicated multieponential decays in SWNTs. The shortest component of the population relaxation can approach the corresponding $T_2$ times,\[2\] and in this case a substantial contribution to broadening from the population lifetime broadening is expected. Here simultaneous measurement of both population and exciton dephasing timescales are crucial to elucidate the pure dephasing timescale ($T_{2}^{\star}$) for $E_{11}$ exciton decoherence from exciton-phonon scattering.

In this contribution, we employ complimentary femtosecond spectroscopic techniques including pump-probe, 2PE and 3PEPS spectroscopy to determine pure optical dephasing times associated with the $E_{11}$ transition. Our experiments were conducted across a broad temperature range (2.5 to 292 K) and at various excitation intensities, and on samples highly enriched in the (6,5) tube type dispersed individually either in aqueous solution or polymer composite films. Analysis of the resulting data further permitted us to distinguish specific contributions to homogeneous linewidth from longitudinal optical and acoustic phonons, and to observe an intrinsically large linewidth in the low temperatures limit given by the environmental disorder.
11.2 Experimental

Optical spectroscopic investigations of SWNTs are often complicated by the existence of multiple structurally distinct tube species and by a variable amount of bundles being present. Central to all experiments reported in this paper is the use of a sample highly enriched in a single semiconducting tube species, the (6,5) tube. In combination with resonant excitation/dexcitation of the $E_{11}$ or $E_{22}$ excitonic bands, this allows us to access the ultrafast dynamics associated with a single tube type. A sample enriched in a single tube type was obtained using a density-gradient ultracentrifugation procedure.\cite{26} The resulting chirality enriched aqueous suspensions of individualized SWNTs were mixed with water-soluble gelatin or polyvinylpyrrolidone (PVP) polymer and then cast into thin (roughly 500 µm) polymer composite films. Use of such polymer films greatly suppress laser light scattering arising from slow tube motions occurring in aqueous solution, and enables measurements at sufficiently low excitation intensities with good signal-to-noise ratio and across a broad temperature range.

The linear absorption and steady-state fluorescence emission spectra measured for SWNTs embedded in a PVP film at room temperature are shown in Figure C.1b. Upon excitation of the $E_{22}$ transition at 572 nm, similar relative fluorescence yields are obtained compared with the starting aqueous samples. Additionally, the absence of a broad, intense emission in the 1150 nm spectral region indicates that tube bundling is insignificant.\cite{27, 28} Measurements at low temperatures were carried out by placing the SWNT-polymer composite films in direct contact with a Janis ST-100 cold finger which operates under continuous liquid helium flow. The sample temperature was continuously controlled by interfacing the cryostat with a Lakeshore temperature controller. To ensure high optical quality and resonant excitation of the (6,5) tubes at all measured temperatures, linear absorption spectra were recorded from 4.4 to 292 K, and the resulting $E_{11}$ peak positions are shown in Figure C.1b (inset). Upon cooling, the PVP composite films showed a maximum 5 nm redshift, which may be attributed to hydrostatic tube strain effects.\cite{29, 30} In contrast, gelatin films yielded a comparatively small redshift (maximum 2 nm), suggesting a somewhat weaker hydrostatic effect. Moreover, a small spectral blueshift was observed for both composite films at temperature below $\sim$70 K. Similar low temperature blue shifts have been previously reported experimentally and predicted theoretically for selected tube types.\cite{31} In addition to the measurements conducted on the composite films, we also performed experiments using the aqueous solution at room temperature. In this case, a thin quartz cell of 100 µm quartz cell was used, which helps minimize the thermal lensing effects induced by laser beams.

The experimental setups for femtosecond 2PE, 3PEPS and transient absorption spectroscopy have been described in detail previously and only a brief account will be given here.\cite{12, 32, 13} The light source was an optical parametric amplifier pumped by a 250 kHz Ti:Sapphire regenerative amplifier, which can produce 40 to 65 fs laser pulses tunable in the visible and near-infrared regions. A combination of a waveplate and a polarizer was used to control the intensity of laser pulse from 0.3 to 15 μJ/cm$^2$ for all experiments described in this paper.

The 2PE experiments were performed by directly exciting the $E_{11}$ state of the (6,5)
tube with 45 fs laser pulses centered at 998 nm for the SWNT-gelatin film, 995 nm for the SWNT-PVP film (see Figure C.1b for the laser laser pulse spectrum), and 990 nm for aqueous solution sample. Additional experiments were also performed at 1012 nm to excite the red-edge of the $E_{11}$ absorption band for the PVP-SWNT composite films. In these experiments, two nearly equal intensity laser pulses were focused to a spot of 148 $\mu$m diameter. The first pulse with wavevector $k_1$ creates a coherent macroscopic polarization of the exciton ensemble that is allowed to dephase over a variable delay time or coherence time ($\tau_{12}$). After time $\tau$, a second pulse $k_2$ arrives producing an interference grating with respect to the partially dephased coherent polarization created by $k_1$. This transient grating diffracts incident photons into phased-matched direction $2k_2-k_1$ as shown in Figure 11.2, which is detected in a time-integrated manner with an InGaAs photodiode and a lock-in amplifier. A measurement of the diffracted signal as function of positive $\tau$ delays gives a nearly monoexponential decay, and the corresponding timescale ($\tau_{\text{decay}}$) can be accurately extracted through a least squares deconvolution fitting algorithm with explicit consideration of finite pulse duration. For strongly inhomogeneously broadened systems such as semiconducting SWNTs,[15] the dephasing time $T_2$ can be obtained directly from the following relation $T_2 = 4\tau_{\text{decay}}$.[33]

![Figure 11.2.](image)

Figure 11.2. (a) The laser beam geometry of the 2PE experiment. (b) A double-sided Feynman diagram shows the temporal state evolution, laser pulse $k_1$ prepares a coherent superposition ($|g\rangle\langle e|$) between ground and the $E_{11}$ excited state, which subsequently dephases over time $\tau_{12}$. The detected 2PE scattering signal($k_s$) is stimulated by the remaining two interactions ($k_2$).

The dynamics of exciton population relaxation was monitored by femtosecond transient absorption spectroscopy. Upon excitation of the $E_{22}$ transition with 48 fs laser pulses centered at 570 nm and subsequent rapid interband relaxation[34], the dynamics of the resulting $E_{11}$ excitons is probed selectively at chosen wavelengths with a white-light continuum. The detection unit consists of a single-grating monochromator, an InGaAs photodiode and a lock-in amplifier. The polarization of the pump beam was set to the magic angle ($54.7^\circ$) with respect to probe beam, to suppress tube orientation contributions. The measurements were performed at several sample temperatures which was chosen to be same as used for our 2PE experiments. A least squares deconvolution algorithm was applied to extract the timescales of the decay kinetics employing a model function that consists of sum of multiple exponents.
To investigate both optical dephasing and spectral diffusion processes, 3PEPS was used as an extension of the 2PE approach where the laser pulse was instead divided into three replicas ($k_1, k_2, k_3$).[35] The details of this technique and its application to SWNTs at room temperature has been previously described at room temperature.[15, 33] The 3PEPS signal were simultaneously detected in two phase-matching directions ($k_1 - k_2 + k_3$ and $-k_1 + k_2 + k_3$) as a function of coherence time ($\tau_{12}$) and an additional delay between pulses 2 and 3, the population time($t_{32}$). At a given population time, the two photon echo profiles were measured and the corresponding peak-shift ($\tau^*$) is defined as half of the temporal offset of the two signal maxima. A plot of the peak shift $\tau^*$ as a function of population time allowed us to examine both optical dephasing (for $t_{32} = 0$) and spectral diffusion processes ($t_{32} > 0$) for temperatures ranging from 4.4 to 292 K.

11.3 Results and Discussion

11.3.1 Exciton-exciton scattering dynamics

The large absorption cross-section of semiconducting SWNTs facilitates the creation of multiple excitons per tube, which will experience enhanced mutual interactions because of one-dimensional confinement.[2] A quantitative estimate for the number of excitons created can be obtained using an absorption cross-section ($\sim 1 \times 10^{-17}$ cm$^2$ per SWNT carbon atom)[36], the mean tube length of 600 nm for our samples,[26] a measured beam waist (148 $\mu$m) and the total incident excitation intensity used. Varying the excitation intensity over fifty fold, corresponds to a mean exciton population of 0.8 to 42 per tube, or alternatively an exciton density($N_x$) ranging from 1.3 to 70 cm$^{-1}$. One consequence of populating many spatially confined excitons is a significant enhancement in exciton-exciton scattering events along the nanotube axis.[25] Previous work has shown that such exciton-exciton scattering and annihilation leads to additional optical dephasing in SWNTs.[37]

Figures C.2a and b show the 2PE data measured for different excitation fluences at 4.4 and 292 K respectively (semi-log scale plotted). At all temperatures, the decay follows monoexponential behavior very closely. The 2PE profile decays markedly faster with increasing excitation fluence, providing direct evidence for exciton dephasing induced by exciton-exciton scattering. While a similar intensity dependence has been recently reported[16, 17], the results obtained here extract dephasing rate directly from the echo decay profile and are reported down to temperatures as low as 2.5 K. As has been discussed previously[25, 38], the exciton dephasing rate ($1/T_2$) or equivalently, the homogeneous linewidth, contains contributions from line broadening induced by both inelastic exciton-phonon ($\Gamma_{ex-ph}(T)$) and exciton-exciton scattering ($\Gamma_{ex-ex}(N_x, T)$).[37, 15, 17] These contributions sum to give the overall effective homogeneous linewidth,

$$\Gamma_h(N_x, T) = \Gamma_0 + \Gamma_{ex-ex}(T)N_x + \Gamma_{ex-ph}(T)$$ (11.2)

where $\Gamma_0$ is the intrinsic linewidth at $T=0$ K.[38] As exciton density is increased, the expo-
Figure 11.3. 2PE decays profile showing the excitation intensity dependence for (6,5) SWNTs collected at (a) 292 K in aqueous solution and (b) 4.4 K in PVP polymer under various excitation fluences as indicated in the plots (in $\mu$J/cm$^2$) (c) Plot of the extracted dephasing rate, $1/T_2$ as a function of excitation fluence shown at four different temperatures. Dashed lines are used to extrapolate to the zero-intensity limit where contributions from exciton-exciton scattering are negligible.
nential decay rate of the 2PE signal increases by one fold across all temperatures measured (see Figure C.2, note the semilog intensity scale). Other spatially confined systems such as quantum wires[39] and CdSe quantum dots [40] also exhibit clear signatures of intensity induced dephasing. A substantial $\Gamma_{ex-ex}$ contribution to the linewidth is consistent with exciton confinement effects leading to enhanced exciton-exciton scattering. Carbon nanotubes in particular are not only strongly confined 1D systems, but have large absorption cross sections ($\sim 5.5 \times 10^{13}$ cm$^2$ per 600 nm (6,5) tube), making them an ideal systems to observe such intensity dependent contributions to the exciton dephasing rate. In order to reach a limit where scattering from multi-exciton interactions (i.e. $\Gamma_{ex-ex}$) can be safely neglected, the beam fluence was incrementally lowered, permitting extrapolation to the zero intensity limit (see Figure C.2c). The resulting intensity-independent dephasing rate (or intrinsic homogeneous linewidth) is then obtained. For the majority of temperatures measured the dephasing rate varied linearly with the exciton density($N_x$) according to equation 11.2. Below $\sim 20$ K and above $\sim 200$ K however, the dephasing rates obtained have significant curvature with excitation intensity, suggesting the exciton-exciton ($\Gamma_{ex-ex}$) and exciton-phonon ($\Gamma_{ex-ph}$) dephasing contributions may be coupled. In these cases, a polynomial expression was used to extrapolate to the zero intensity limit. The results obtained are in good accord with measurements published earlier reporting the intensity-dependent exciton dephasing rate down to 77 K.[16] Detailed studies examining the contributions from exciton-exciton scattering to exciton dephasing can be found elsewhere.[25, 37] In the following sections we instead focus on the extrapolated results in the zero intensity limit, which effectively eliminates the contributions from the $\Gamma_{ex-ex}$ term that broaden the homogeneous linewidth.

11.3.2 Temperature-dependent contributions from $E_{11}$ population relaxation

Pure optical dephasing times are often considered to be identical to the $T_2$ time obtained directly from 2PE experiments, and the contributions from population relaxation are neglected by assuming that its lifetime is significantly long (i.e., $1/2T_1 \ll 1/T_2$). The population relaxation detected for the (6,5) nanotubes by pump-probe experiments however, contains a dominant decay component with a timescale similar to the $T_2$ time. This means that explicit account of the population decay time ($T_1$) is crucial to correctly obtain the pure optical dephasing time $T_2^*$. To account for the contributions from population decay, we performed pump-probe measurements for the (6,5) tubes embedded in both PVP polymer and gelatin composites at different temperatures (see Figure C.4a). For the PVP composites, the same temperatures were chosen as used for our 2PE measurements. Extraction of the decay timescales from the pump-probe data involves use of a least-squares deconvolution algorithm and a model function consisting of multi-exponential components. We obtained satisfactory fits for a majority of our data with a model function with three exponents, but for those measured near room temperature ($T \geq 250$ K), an additional exponential component was needed. Among these three or four components, the fastest decay component is always dominant, and has
Figure 11.4. (a) Pump-probe data collected for the (6,5) tube embedded in PVP polymer matrix at four different temperatures (in K). The experiments were performed by exciting the $E_{22}$ transition at 570 nm, and probing the $E_{11}$ state at 998 nm. All the data were normalized at peak amplitudes of the pump probe signals, and the resulting decay profile appears largely independent of the pump fluence. The inset shows the three-state model used to model our data, where a radiative decay occurs from the $E_{11}$ state to ground and all other rate constants represent non-radiative pathways. (b) Temperature dependence of the extracted population decay rates (black circles) for the fastest (and dominant) decay component of a multiexponential fit. The dotted line (orange) show the simulated temperature dependence. Simulated decay kinetics (solid lines) using the three-state model captures the main components of $E_{11}$ dynamics for the temperatures shown.
an approximate relative weight of 60% of the total amplitude. The extracted lifetime for this fastest lifetime component ranged from 290 to 460 fs as temperature was lowered from room temperature to 80 K. The lifetime associated with the second decay component ranged from 2.7 to 5.6 ps over the same temperature range with a relative amplitude of 30%, and the slowest decay component has a lifetime of 140 ps with about 10% relative amplitude. It is clear from equation 11.1, that the two slower decay components will not contribute appreciably to the pure dephasing rate. Also, their significantly smaller amplitudes in combination with their relatively weak temperature dependence further reduce their influence on the obtained pure dephasing times $T_2^*$. Thus, we will instead focus primarily on modelling the initial, fast decay portion of the pump-probe data collected at various temperatures.

The inset in Figure C.4b shows the dominant population decay rates extracted from the fastest exponential relaxation component at each temperature measured. Upon cooling from 292 to 80 K, a roughly linear dependence of the population decay rate on temperature is found. Such a rate increase with temperature is normally expected for systems dominated by non-radiative decay primarily mediated by exciton-phonon scattering.[41] On cooling below the 80 K threshold, a marked increase in the $E_{11}$ population decay rate is observed, which can be seen from the kinetics shown in Figure C.4a. To model if such an acceleration in the initial decay component for (6,5) SWNTs, a phenomenological three state model previously used to describe temperature dependence of steady-state and time-resolved fluorescence kinetics of semiconducting SWNTs is adopted.[42, 43, 10] This three-state model allows for rapid thermalization of the optically bright $E_{11}$ state with a third state state low-lying state (labeled $D$, see the energy level diagram in the inset of Figure C.4a). At sufficiently low temperatures, the acoustic phonon modes mediating the $E_{11} \leftrightarrow D$ thermalization are no longer excited, which will effectively halt the uphill energy transfer from $D$ to $E_{11}$. This consideration suggests that an enhancement in exciton population decay will occur when temperature approaches a certain value, which is qualitatively in line with the accelerated decay of the fastest decay component observed below 80 K in our pump-probe measurements (see Figure C.4a,b).

To quantitatively simulate the population relaxation dynamics, we begin with the following coupled differential rate laws that describe the $n_{E_{11}}$ and $n_D$ state populations (refer to Figure C.4a(inset)).

$$\frac{dn_{E_{11}}}{dt} = k_{E22} n_{E22} - (k_{E11} + k_D) n_{E11} + k_{\uparrow} n_D - \gamma_0 t^{-1/2} [n_{E11}]^2 \quad (11.3)$$

$$\frac{dn_D}{dt} = -(k_D + k_{\uparrow}) n_D + k_{\downarrow} n_{E11} \quad (11.4)$$

Since, $E_{22} \rightarrow E_{11}$ relaxation is known to be fast (roughly 40 fs)[34] compared to our pulse width, we assume that the $E_{11}$ band is impulsively populated (i.e., $k_{E22} = 0$). A major distinction of our model from the previous work is the explicit inclusion of an exciton-exciton annihilation process allowing for an additional population depletion pathway out of the $E_{11}$ state. The corresponding annihilation rate is assumed to be $\gamma(t) = \gamma_0 t^{-(1-d/2)}$ using $d = 1$ for diffusion-controlled annihilation in the nanotubes.[44, 41] Using equations 11.3 and 11.4 we were able to satisfactorily show that such a three-state model can roughly reproduce the
temperature dependent rate coefficients shown in Figure C.4b (inset, compare with orange dotted line).

For the above simulation, we assumed that that $E_{11}$ exciton band is parabolic and band thermalization occurs according to Boltzmann statistics. In order to explicitly include the temperature dependence, a phonon assisted scattering process between the $E_{11}$ and the low lying state $D$ was included in equations 11.3 and 11.4, along with radiative decay ($k_{E_{11}}$) from the optically bright $E_{11}$ state and non-radiative relaxation ($k_{NR}$) from $D$ to ground state. Owing to momentum conservation, the radiative relaxation can occur only from excitons located within a region $\Delta \approx 0.37 \mu$eV above the band minimum, which is accessible by a photon’s momentum.[43, 45] According to Spataru et al.,[46] for an infinite length tube, the $E_{11}$ radiative decay rate at finite temperatures can be approximated as,

$$k_{E_{11}} = k^0 \sqrt{\frac{\Delta}{k_b T}}$$

(11.5)

where $k^0$ is an intrinsic radiative decay parameter (at $K_{cm} = 0$) and $k_b$ is the Boltzmann constant. A corresponding intrinsic radiative lifetime of 2.5 ps was used. The actual effective radiative lifetime measured ($k_{E_{11}}$) will be orders of magnitude larger at all temperatures because of the exciton momentum distribution, and potential thermalization with the low-lying state, $D$. This intrinsic lifetime value is somewhat shorter than the $\sim$10 ps $ab$ initio result predicted for the (8,0) tube type.[46] Above $\sim$80 K, excitation of acoustic phonons enables a constant thermal exchange between the $E_{11}$ and the lower lying state $D$. The corresponding uphill and downhill rates ($k^\uparrow$ and $k^\downarrow$) can be approximately related by detailed balance as follows,

$$k^\uparrow = k^\downarrow \exp(-\Delta E_D/k_b T)$$

(11.6)

where $\Delta E_D$ is the energy difference from $E_{11}$ to $D$, which our model suggests is approximately 9 meV. Recent measurements have identified low lying electronic states under high magnetic fields that have similar energy separations (5-8 meV) to the one we extracted.[11] The potential involvement of this low-lying state $D$, has been shown to further increase the effective radiative lifetime, particularly in $T <\sim$80 K region.[43, 47]

The downhill rate ($k^\downarrow$) and subsequent decay from the low lying $D$ state ($k_D$) are assumed to be non-radiative. The corresponding temperature-dependence associated with non-radiative rates is approximated as,[48, 49]

$$k_{NR} = k_c + C \exp(-\theta_k/k_b T)$$

(11.7)

where $k - c$, $C$ and $\theta_k$ are fitted constants determined to be 0.06 $ps^{-1}$, 0.6 $ps^{-1}$ and 90 K for the $k^\downarrow$ phonon-mediated transition. For the relaxation from $k_D$, 0.15 $ps^{-1}$ was used with no temperature dependence required for our temperature range. If we assume the exciton annihilation rate is largely temperature independent we can set $\gamma_0 = 0$ to get the initial rate dependence on temperature; our analysis then follows one presented by Scholes et al. applied to temperature dependent photoluminescence rates.[43] Using the fitted parameters to compute the initial decay rate, the three-state model reproduces the temperature-dependent trend observed for the dominant $E_{11}$ kinetic relaxation rate (see Figure C.4b, inset dashed line)).
The above model (with $\gamma_0 = 0$) gives a biexponential decay for $E_{11}$ kinetics, whereas at least three exponential decay components were required to numerically approximate our pump-probe measurements. Inclusion of exciton-exciton annihilation introduces a nonexponential component which allows us to roughly model the temperature-dependent kinetic decay. Using $\gamma_0$ values ranging from 0.2 to 0.8 ps$^{-1/2}$, we solved the differential system of equation 11.3 and 11.4 numerically for temperatures ranging from 4 to 290 K. At most temperatures, the resulting simulated decay curves (solid lines) could reproduce the experimental decay well (see Figure C.4b).

The involvement of low-lying states such as the phenomenological D state included here, has also been used extensively to model temperature dependent SWNT quantum yields. These studies report a precipitous decrease in quantum yield below 80 K, and suggests that any radiative decay out of low-lying state must be comparatively small.[42, 47, 50] Accompanying this marked decrease in yield, a significant decrease in total effective radiative rate has been reported.[47] In many works, low-lying states such as the D state has been commonly ascribed to the $1g$ state originally proposed from calculations using a 1D hydrogenic model exciton wavefunction.[5, 43] The $1g$ state is expected to be optically dark from parity selection rules for a one-dimensional SWNT.[10] However for intra-excitonic transitions from the optically bright $E_{11}$ $1u$ state to $1g$, rapid scattering and thermalization between states of different parity is allowed.[51, 52, 50]

Previous pump probe measurements on individually separated SWNTs have been reported down to 77 K only, and the measured $E_{11}$ population lifetimes also increased in a roughly linear fashion upon cooling.[53] A linearly decreasing decay rate is reported down to \(\sim 80\) K in the time-resolved photoluminescence (PL) studies by Hagen et al. and Berger et al. on (9,4) and (6,4) SWNTs.[47, 54] In the $T < \sim 80$ K region, the overall PL decay rate was reported to plateau, and remained roughly constant down to 4 K. In contrast to the pump probe measurements reported here, the previously reported PL single photon counting measurements have intrinsically lower (ps) time resolution.[47, 43] As a result, a rate acceleration occurring on the $\sim 100$ fs timescale may not be detected.

Modeling of the temperature dependent pump-probe decay curves, suggests the low temperature rate acceleration is physically consistent with involvement of a low-lying state. While a similar temperature-dependent trend was also observed for (6,5) SWNTs in a gelatin composite environment (data not shown), we nonetheless cannot completely rule out unforeseen environmental considerations as an alternate explanation. Regardless of the precise physical origin of the observed acceleration in $E_{11}$ population decay rate at low temperatures, we can use the dominant initial decay rates plotted in Figure C.4b (inset) to effectively remove the contributions of population relaxation from our 2PE results, allowing us to determine $T^*_2$ directly.

### 11.3.3 Pure optical dephasing timescales

Semiconducting SWNTs generally have weak exciton-phonon coupling, an observation that was first suspected from both the associated small Stokes shift (e.g. $\sim 4$ nm in Figure
Figure 11.5. (a) Temperature-dependent 2PE collected at 6.0 µJ/cm² total excitation fluence for (6,5) SWNTs in a PVP polymer composite. Below ~80 K, $T_2$ decreases. (b) Population decay rates ($1/T_1$) are used to calculate pure dephasing times, revealing a predominately linear slope (dotted line) consistent with optical dephasing from one-phonon processes.
C.1a) and from \textit{ab initio} calculations.\cite{55} A 205 fs dephasing time (low intensity limit) is extracted for (6,5) SWNTs in aqueous solution at 294 K (Figure C.2a). Such long dephasing times at room temperature are indicative of weak exciton-phonon coupling strength. To better understand the physical origin of this weak coupling, 2PE traces were measured as a function of excitation fluence at fixed temperature increments down to temperature of 2.5 K. Consistent with previous $T_2$ times reported down to 77 K,\cite{16} the extracted dephasing times increase only moderately (to 320 fs) upon cooling to 70 K. Extending the experiment to lower temperatures revealed an unexpected marked increase in the 2PE decay rate (see Figures C.5a and b). Since lowering temperature necessarily decreases the phonon population, the observed increase in dephasing rate for $T \lesssim 80$ K plotted in Figure C.5b is not consistent with line-broadening associated with exciton-phonon interactions (i.e., $\Gamma_{ex-ph}(T)$).

For all temperatures examined, we find the population dynamics are sufficiently fast to significantly broaden the corresponding homogeneous linewidths. Using equation 11.1, the contributions from population relaxation ($T_1$) are removed to estimate the pure dephasing rate ($1/T^*_2$). The $1/T^*_2$ rate is plotted in Figure C.5b (open circles), and has a distinctly different temperature dependence than the $1/T_2$ rate owing to an acceleration in the initial $E_{11}$ population decay rate ($1/T_1$) for $T \lesssim 80$ K. In particular, the resulting pure dephasing rate increases linearly for $T \lesssim 180$ K. Such linear rate dependence on temperature is a strong indicator of dephasing induced by one-phonon interactions.\cite{12}

To fit the pure dephasing rates obtained, the following line-broadening function is used to determine what exciton-phonon scattering processes contribute to optical dephasing of the $E_{11}$ excitation for (6,5) SWNTs,

$$\Gamma_h(T) = \Gamma_0 + aT + \frac{b}{e^{(h\omega_{LO}/k_BT)} - 1} \quad (11.8)$$

which is shown in Figure C.5b as the fitted solid line.\cite{12} The first term $\Gamma_0$, represents the finite homogeneous linewidth at $T = 0$ K, which is $2.45 \pm 0.05$ meV (or $T^*_2 \approx 535$ fs). The second parameter is the linear temperature-dependent line-broadening rate $a = 6.7 \pm 0.6 \mu$ev/K, and corresponds to one-phonon scattering processes commonly from acoustic phonons. For $T \lesssim 180$ K, we find such one-phonon acoustic scattering processes are the dominant contribution inducing pure optical dephasing (shown by dotted linear fit in Figure C.5b). Remarkably similar linear line-broadening rates ($a$) have also been reported in GaAs quantum wells using a similar 2PE analysis.\cite{21,20} The last term in equation 11.8, provides contributions from optical phonon scattering which scale with the Bose optical phonon occupation factor. The corresponding fit suggests an intrinsic optical phonon energy of $h\omega = 1028 \pm 231$ cm$^{-1}$ with $b = 250 \pm 180$ meV. However, the sparsity of points collected in this $T > 180$ K region previously investigated in detail by Ma \textit{et al}.\cite{16} prevents accurate assignment of the optical modes involved. Nonetheless, within the error calculated, the previously implicated traverse optical (TO) mode at 860 cm$^{-1}$,\cite{16} or the longitudinal acoustic + TO mode present at 960 cm$^{-1}$ are potential candidates.\cite{56}

Reasonable correspondence is found between our time-domain on an ensemble of (6,5) SWNTs and recently reported single nanotube photoluminescence work on (9,8) tubes. Both measurements reported a nearly identical low temperature linewidth of $\sim 2.5$ meV.\cite{23} This

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particular single-tube measurement also produced a linewidth which scaled linearly with temperature (below ∼160 K), although the reported slope was almost three times as steep as the values we extracted for (6,5) SWNTs.\[23\] A more meaningful comparison however would require information on the lifetimes associated with the (9,8) SWNTs investigated in this single-nanotube study.

The observation of a significant homogeneous linewidth ($\Gamma_0 = 2.45$ meV) as $T \rightarrow 0$, suggests the presence of a large intrinsic environmental disorder that should be highly sample dependent. Calculations by Perebeinos et al. suggest that even a small amount of spectral diffusion from the surrounding environment can give rise to a significant homogeneous linewidth as $T \rightarrow 0$.\[10\] To investigate the the origin of this low-temperature disorder, the role of the local environment on dephasing processes will be examined in section E.

### 11.3.4 Spectral diffusion contribution; a 3PEPS measurement

In order to investigate the timescales extracted from 2PE and transient absorption results, a room temperature pure dephasing time of 285 fs is determined for aqueous (6,5) SWNTs. In order to investigate this apparently weak exciton-phonon coupling in the $E_{11}$ band, we next investigate the role of spectral diffusion processes for $t_{23} > 0$, using temperature-dependent 3PEPS spectroscopy. Using 3PEPS, the photon echo signal is simultaneously collected in the $k_1 - k_2 + k_3$ and $-k_1 + k_2 + k_3$ phase matching directions, allowing access to the time delay between the second and third pulses corresponding to the population time (i.e., $t_{23}$). Here we report a measurement of the temperature-dependent 3PEPS, full details on SWNT 3PEPS measurements at room temperature have been reported elsewhere.\[15\]

When the time delay $t_{23}=0$, the 3PEPS ($\tau^*$) measurement provides an indirect measurement optical dephasing time. While there is no analytic relation between the peak shift and $T_2$, both quantities scale with the mean square of $E_{11}$ state frequency fluctuations ($\Delta_{m}^2$) that are modulated by the phonon bath.\[33\] After an established scaling ratio is used to correct for the 45 fs pulse duration employed, the numerically converted initial peak shift values agree remarkably well with the corresponding dephasing rates obtained directly from 2PE experiments collected under the same excitation fluence (see Figure C.3a).\[57, 17\] Such high correspondence with peak-shift measurements provides independent support of the dephasing times obtained directly from 2PE measurements.

Examining the peak shift dependence as a function population times, the 3PEPS decay profile provides information about spectral diffusion processes in the $E_{11}$ band. The 3PEPS decay profiles shown in Figure C.3b were collected under a low excitation fluence of 4.3 $\mu$J/cm$^2$ at various temperature increments. The room temperature 3PEPS decay profiles have been previously analyzed to obtain spectral lineshapes and estimation of exciton-phonon coupling strengths.\[15\] Since the low temperature band thermalization processes are not yet well understood in SWNTs, we instead analyze the temperature-dependent 3PEPS profiles qualitatively. Upon cooling, the peak shift decays at a markedly slower rate toward a constant long-time peak shift value of ∼22 fs. This long-time offset is largely temperature-independent, and suggests a fixed inhomogeneous linewidth contribution arising from static
Figure 11.6. (a) The initial ($t_{23}=0$) peak shift provides an alternative measure of exciton dephasing. It yields complimentary results to 2PE measurements after proportionality is applied to account for pulse duration. (b) With decreasing temperature, the peak shift increases non-uniformly (shown for a 4.3 $\mu$J/cm$^2$ excitation fluence in PVP polymer composites). For long population times, all 3PEPS curves decay to a similar asymptotic value which is indicative of inhomogeneous spectral broadening. (c) A plot of the photon echo peak shift decay at 292 K shown as function of excitation fluence. The observed intensity dependence at a given population time is qualitatively similar to what is observed from 2PE experiments.
environmental interactions. As the temperature is lowered, the decay rate of the peak shift profile slows considerably (Figure C.3b). A slower 3PEPS decay rate at lower temperatures is physically consistent with a smaller thermal phonon population, resulting in a statistically longer time for spectral diffusion to effectively erase the system memory associated with the $E_{11}$ band transition.[35]

In Figure C.3c, the intensity dependence of the 3EPES profiles is plotted for room temperature. Their exists a strong correlation between the excitation fluence dependence of the initial peak shift values, and those of the 2PE decay rates extracted section in IIIc. When normalized to a specified $t_{23}$ time the peak-shift profile measured at various excitation fluences can be approximately superimposed (data not shown). Similar to the 2PE echo results, we attribute the origin of the intensity-induced spectral diffusion contribution to exciton-exciton scattering processes. Recently Abramavicius et al.

modeled this intensity dependence using a non-perturbative phase cycling approach that explicitly accounts for the contribution of exciton-exciton scattering and annihilation processes to the measured photon echo signal. Using this theoretical construct, it was shown that by inclusion of higher than third-order polarization terms, that the observed intensity dependent peak-shift and 2PE profiles can be simulated. The necessary inclusion of higher than third-order terms necessitates the involvement of coherent multiple-exciton states that induce optical dephasing primarily through annihilation pathways.[37] The requirement for multi-exciton states to model SWNT photon echo spectroscopy highlights the importance of analyzing photon echo spectroscopy in the regime of low excitation fluence, where such complicating contributions are greatly reduced.

11.3.5 Temperature-dependent dephasing and the local environment

Below 60 K, the existence of a $\sim$4 nm spectral blue-shift in the $E_{11}$ absorption peak of SWNT-PVP polymer composite films (Figure C.1b inset), suggests possible hydrostatic effects from the local environment may provide an alternative explanation for the acceleration in dephasing rates ($1/T_2$) plotted in Figure C.3a. To investigate, select 2PE measurements were repeated with a central excitation wavelength tuned resonantly with the $E_{11}$ spectral red edge at 1012 nm. For a given temperature and photon fluence, the dephasing times obtained were moderately shorter for excitation at the red edge, but the overall temperature-dependent trend observed (data not shown) was identical to the original resonant excitation case plotted in Figure C.3a.

Selected for its comparatively small ($\sim$2 nm) temperature-dependent $E_{11}$ spectral shift, a gelatin-SWNT composite was used as a model system to investigate how surrounding polymer matrix effects the optical dephasing rates extracted. In Figure 11.7a, the corresponding room temperature dephasing rates are plotted for resonantly excited (6,5) SWNTs in aqueous solution, PVP polymer and gelatin composite environments. Nanotubes in all three local environments produce long room temperature optical dephasing times ($T_2 = 120$ to 205 fs, see table I).
The temperature-dependent 2PE and 3PEPS measurements previously presented were repeated on resonantly excited (6,5) SWNTs embedded in gelatin composite films. Comparing the 2PE decay profiles obtained for gelatin composites in Figures 11.7b to PVP polymer composite films shown in C.5b, the optical dephasing rate is found to have a similar temperature dependence in the two host environments. The corresponding dephasing rates for gelatin composites are plotted in Figure 11.7c alongside the initial peak shift values. All data presented has been extrapolated to the zero-intensity limit. As with PVP composites, the initial peak shift values measured in gelatin composites show a parallel temperature dependence to the dephasing rates obtained directly from the 2PE decay profile.

The pure dephasing time for gelatin-SWNT composites was determined for select temperatures only (see table I below). Compared to SWNT aqueous suspensions, moderately faster pure dephasing rates are obtained after incorporating aqueous (6,5) SWNTs into the different polymer environments such as PVP and gelatin. This environmental dependence suggests bath fluctuations from the surrounding polymer are moderately coupled to the $E_{11}$ exciton transition, however under ambient conditions exciton-phonon scattering intrinsic to the SWNT remains the dominant contribution to optical dephasing. As $T \to 0$, the predicted pure dephasing time for the gelatin composite is $\sim 30\%$ smaller than the PVP case, suggesting that changes in environmental static disorder and spectral diffusion also contribute substantially to the homogeneous broadening. The timescales of $E_{11}$ exciton dynamics for (6,5) carbon nanotubes are summarized in Table 11.3.5:

<table>
<thead>
<tr>
<th></th>
<th>$T$(K)</th>
<th>$T_1$</th>
<th>$T_2$</th>
<th>$T_{2,m}$</th>
<th>$\tau^*$</th>
<th>$T^*_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>PVP polymer</td>
<td>292</td>
<td>295</td>
<td>162</td>
<td>132</td>
<td>53</td>
<td>223</td>
</tr>
<tr>
<td></td>
<td>80</td>
<td>460</td>
<td>311</td>
<td>275</td>
<td>–</td>
<td>470</td>
</tr>
<tr>
<td></td>
<td>4.4</td>
<td>289</td>
<td>269</td>
<td>242</td>
<td>–</td>
<td>508</td>
</tr>
<tr>
<td>Gelatin</td>
<td>292</td>
<td>302</td>
<td>124</td>
<td>121</td>
<td>48</td>
<td>155</td>
</tr>
<tr>
<td></td>
<td>110</td>
<td>683</td>
<td>228</td>
<td>170</td>
<td>68</td>
<td>274</td>
</tr>
<tr>
<td></td>
<td>4.4</td>
<td>146</td>
<td>158</td>
<td>130</td>
<td>55</td>
<td>344</td>
</tr>
<tr>
<td>Aqueous</td>
<td>292</td>
<td>372</td>
<td>205</td>
<td>184</td>
<td>52</td>
<td>283</td>
</tr>
</tbody>
</table>

Table 11.1. Extracted values (in fs) that characterize the various timescales of $E_{11}$ exciton dynamics for (6,5) SWNTs. With the exception of the dephasing time measured at lowest excitation intensity (denoted $T_{2,m}$), all decay times and peak shifts ($\tau^*$) have been extrapolated to the zero intensity limit.

For gelatin-SWNT composites, an oscillatory feature consistent with vibrational beating was also apparent in the 2PE decay during the pulse overlap region. Using singular value decomposition a dominant beat frequency of 1770 cm$^{-1}$ is extracted which is similar to the 1610 cm$^{-1}$ ground state tangential Raman mode (G-band) for the (6,5) SWNT.[58] Such oscillatory behavior has been previously observed in transient absorption measurements using pulse widths shorter than the G-band vibrational period ($\sim 21$ fs).[59] Interestingly, for the 2PE measurements this oscillatory component diminishes almost entirely in amplitude for temperatures corresponding to the longest dephasing times. One potential explanation is at low temperature the exciton wavepacket may be sufficiently delocalized to effectively ”average
Figure 11.7. (a) Extracted room temperature optical dephasing rates for (6,5) SWNTs in different local environments. (b) Temperature-dependent 2PE collected at 6.0 µJ/cm² in a gelatin matrix. Below 100 K, $T_2$ decreases markedly. A weak oscillatory frequency closely matching the G-band period is apparent for $T \sim 130$ K. (c) Corresponding peak shift measurements were collected concurrently with 2PE decays for (6,5) SWNTs in gelatin. The peaks shifts were extrapolated to the zero intensity limit, yielding complimentary results.
over the coupled G-band tangential mode. This phenomenon of motional narrowing that has been extensively described in other quasi 1-D systems such as molecular aggregates.[18, 60] If present in SWNTs, motional narrowing may help explain why long pure dephasing times are realized under ambient conditions.

11.3.6 Motional Narrowing and Exciton-Phonon Coupling Strength

Considering the well-defined nanotube vibrational modes, and large surface area exposure to the surrounding environment, the observation of weak exciton-phonon coupling at room temperature is perhaps surprising. We explore the role of motional narrowing by fitting the non-exponential behavior in the 2PE decay profile across a range of temperatures. Using the model discussed below, the shape of 2PE decay profiles suggests the corresponding $E_{11}$ homogeneous linewidths are motionally narrowed for all temperatures measured.

The non-exponential component of the 2PE decay is extracted using a model function derived out of the stochastic Kubo line-shape theory for a system coupled to a fluctuating reservoir of phonons, and full details can be found elsewhere.[19, 32, 61] In short, an ensemble of $E_{11}$ optical transitions is described by a frequency correlation function ($M(t)$) that we assume decays at an exponential rate, $M(t) = e^{-t/\tau_m}$, as the result of exciton coupling to the phonon bath.[32] Here, $\tau_m$ is the frequency modulation time that provides the timescale of the phonon frequency perturbations which induce electronic dephasing. The expected profile of a given 2PE curve ($S_E(\tau)$) can then be obtained analytically from $M(t)$,[32]

$$S_E(\tau) = \exp \left\{ -4 (\Delta_m \tau_m)^2 \left[ 2 \exp \left( \frac{-\tau}{\tau_m} \right) - \frac{1}{2} \exp \left( \frac{-2\tau}{\tau_m} \right) + \frac{\tau}{\tau_m} - \frac{3}{2} \right] \right\}.$$  \hspace{1cm} (11.9)

$\Delta_m \tau_m$ is a dimensionless product of $\tau_m$ and the amplitude of the frequency fluctuation ($\Delta_m$). $1/\Delta_m$ represents the minimum time required by the uncertainty principle for an exciton to couple to a phonon mode.[62] If $\tau_m > 1/\Delta_m$, the exciton wavepacket is propagating too fast to fully experience the applied fluctuation.[32, 62] Hence when $\Delta_m \tau_m \ll 1$, the exciton-phonon coupling process is said to be strongly motionally narrowed. The presence of motional narrowing weakens the effective exciton-phonon coupling strength, resulting in narrower homogeneous linewidth with a characteristic Lorentzian spectral shape.[18, 62]

Across all temperatures investigated, the 2PE decay profile suggests our corresponding homogeneous linewidth is motionally narrowed with an average $\Delta_m \tau_m = 0.28 \pm 0.04$ (see Figure 11.8). Thus, $E_{11}$ excitons in (6,5) SWNTs may not couple effectively to many phonon modes, because nuclear fluctuations from the phonon bath are averaged over from the spatial extent of the exciton along the tube.[18] Certain modes (e.g. the TO optical mode), may invariably couple stronger than others depending upon the geometry and strength the applied nuclear fluctuation. When modes involved in motional narrowing are no longer populated at lower temperature, no net effect on the dephasing time is expected. This observation is
Figure 11.8. Modeling the non-exponential component of the decay for the 2-pulse echo signal \( S_{PE} \) for (6,5) SWNTs in PVP polymer suggests we are in a motionally narrowed regime for all temperatures measured.

in accord with the weak overall temperature dependence associated with the pure optical dephasing rate shown in Figure C.5b.

In site basis, motional narrowing can be modeled as a form of ballistic exciton transport along the nanotube axis (during \( T_2^* \)). Ballistic transport implies the exciton is moving faster than it can be thermalized by exciton phonon-coupling. For metallic SWNTs, ballistic transport is a well-established physical property.[63] To check if such a transport process is reasonable for semiconducting SWNTs, we can approximate the kinetic energy of ballistic excitons by 

\[
E_{ball} = \frac{1}{2} m_{ex}^* \left( \frac{d}{T_2^*} \right)^2,
\]

where \( m_{ex}^* \) is the exciton effective mass and \( d \) is the exciton delocalization length.[64] In this classical approximation we find 

\[
E_{ball} \approx 3.5d^2 \mu eV/nm^2,
\]

which exceeds the room temperature thermalization energy (given by \( E_k = \frac{1}{2} k_B T \)) for initial exciton delocalization lengths on the order 50 nm. With literature values for \( d \) ranging from 10 to 100s of nm,[14, 10] this simple classical model suggests the exciton kinetic energy \( (E_{ball}) \) may exceed the thermalization energy even at room temperature. Since this model suggests \( E_{ball} > E_k \) for temperatures ranging from 4.4 to 292 K, it is reasonable that \( E_{11} \) excitons may experience ballistic transport during the period \( T_2^* \). The presence of ballistic transport further implies that exciton band thermalization may not occur appreciably until after the corresponding \( T_2^* \) time has elapsed.[65]

These \textit{ad hoc} calculations for ballistic transport in (6,5) SWNTs, lend support to our 2PE results which suggest a motionally narrowed exciton dephasing process at all temperature measured. As previously reported for quasi 1D molecular aggregates,[18] motional narrowing in SWNTs effectively averages over large dynamic disorder, suggests the presence of considerable exciton delocalization upon optical excitation. This averaging effect reduces the effective exciton-phonon coupling strength, and provides a possible explanation for the realization of long 285 fs \( E_{11} \) pure optical dephasing times at room temperature.
11.4 Conclusions

We find that motional narrowing is a significant process that modulates the phonon bath fluctuations coupled to the $E_{11}$ exciton state for (6,5) SWNTs. This process effectively weakens the exciton-phonon interaction and suggests a physical explanation for the unusually long 285 fs $T^*_2$ times realized at room temperature. Below $\sim$80 K in PVP polymer, and $\sim$100 K in gelatin-SWNT composites, a marked increase in dephasing rate was attributed to a corresponding acceleration in the $E_{11}$ pump-probe decay rate. Applying a three state model previously developed for SWNT PL kinetics[43], this acceleration in population decay was attributed to exciton thermalization with a low-lying state, found to be $\sim$9 meV below the $E_{11}$ state. By combining the resulting pump probe decay components and extracted 2PE decay times in the low excitation intensity limit, the pure dephasing times ($T^*_2$) are determined. Cooling from ambient conditions to 4.4 K, the overall pure dephasing rate decreases just under three fold, and has a linear rate below $\sim$180 K consistent with optical dephasing induced by acoustic phonon processes. Such a moderate $T^*_2$ temperature dependence may be expected for ensemble measurements of (6,5) SWNTs because of motional narrowing effects and the presence of a large, environmentally induced homogeneous linewidth as $T \to 0$. Collectively, this study highlights the important contributions of coherent excitons to the overall $E_{11}$ spectral dynamics of (6,5) SWNTs, and suggests an important interplay between exciton-phonon coupling and the exciton delocalization length motivating further investigation.
11.5 References


Chapter 12

Two-Dimensional Electronic Spectroscopy of Carbon Nanotubes

Application of 2D Fourier transform electronic spectroscopy to semiconducting SWNTs is demonstrated to decongest complex exciton dynamics. Analysis provides the $E_{22}$ homogeneous linewidth, and elucidates the roles of vibrational and multi-exciton states in population relaxation.

12.1 Introduction

In contrast to the established electrical and mechanical properties the optical properties of semiconducting single-walled carbon nanotubes (SWNTs) are only just emerging with greatly enhanced fluorescence yields (up to 20%) and development of efficient nanotube photodiodes [1] The scope of optoelectronic applications for SWNTs depends critically on a detailed understanding of their highly congested absorption features consisting of excitonic ($E_{11}$, $E_{22}$, etc.), vibrational and partially dark transitions. While ultrafast techniques such as transient absorption and fluorescence up-conversion provide the general timescales of population relaxation substantial inhomogeneous broadening (four times the homogeneous linewidth), pronounced exciton-exciton scattering, and contribution of minor tubes types prevent unambiguous determination of the relaxation pathways associated with the most basic optical excitations [2-4]. Providing clarity amongst congestion, we demonstrate how 2D Fourier transform (2DFT) electronic spectroscopy gives an incisive time and frequency domain map of exciton dynamics in SWNTs. In contrast to other nanosystems studied using 2DFT spectroscopy (such as GaAs quantum wells), semiconducting SWNTs are char-
characterized by remarkably large exciton binding energies (0.4 to 1.0 eV) quasi one-dimensional confinement and long room temperature optical dephasing times ($T_2 ≈ 200$ fs) [3,4].

Dominating SWNT optical absorption are two bright exciton states, the lower $E_{11}$ and its counterpart in the next brillouin zone, the $E_{22}$. Associated with each bright exciton state is a manifold of continuum and low oscillator strength states which are believed to play a critical role in processes like non-radiative emission [4]. Using 2DFT spectroscopy, such states of low oscillator strength will be inherently brightened with heterodyne enhancement of cross-peaks that are linked to optically bright states of the same tube chirality. In this contribution, we demonstrate the utility of 2DFT electronic spectroscopy to uncover new photophysics in strongly confined excitonic systems such as semiconducting SWNTs.

12.2 Experimental Details

Until recently, carbon nanotube samples were highly inhomogeneous mixtures of many tube types, making advanced spectroscopic studies intractable. The sample used in this study is highly enriched in the (6,5) semiconducting tube type, through a density-gradient ultracentrifugation process [5]. Such high sample purity allowed for (6,5) specific excitation of the $E_{22}$ manifold of states using a 90 nm FWHM broadband pulse centered at 550 nm generated from a non-collinear optical parametric amplifier (NOPA) pumped by home-built 3.4 kHz Ti:sapphire/regenerative amplifier system. The 2DFT technique used is described in detail elsewhere [6]. Briefly, three 20 fs laser pulses were focused on the sample in a box geometry to generate the third order signal. In order to suppress laser light scattering, an aqueous solution enriched in (6,5) individualized tubes was used to fabricate a thin SWNT-polymer composite film using water soluble polyvinyl-pyrrolidone polymer. A heterodyne detection scheme on CCD camera was accomplished by passing a fourth pulse through the sample to serve as the local oscillator. This enabled us to spectrally resolve the SWNT four-wave mixing signal in both amplitude and phase while scanning the coherence time, $\tau$ (between pulses 1 and 2) at various population times, $T$ (between pulses 2 and 3), from -25 to 500 fs. The coherence time was scanned from 0 to ±300 fs, allowing the pulse ordering to select rephasing (+$\tau$) and non-rephasing (-$\tau$) signals.

12.3 Results and Discussion

The collected absolute-value signal ($S(\Omega_\tau, \Omega_t, T)$) is plotted in figures 12.3a and b at $T=0$ and 50 fs as function of the absorption or coherence energy ($\Omega_\tau$) and emission or rephasing energy ($\Omega_t$). For $T=0$, the salient diagonal features correspond to linear absorption for the $E_{22}$ transition (2.17 eV) and a phonon-sideband peak (upshifted 220 meV or 1780 cm$^{-1}$) consistent with vibrational exchange with the G-band mode (tangential tube stretching). This assignment is supported by the vibrational beat period and weak cross-peaks linking
Figure 12.1. Preliminary 2D-electronic relaxation (left) and non-rephasing (NR, right) spectra shown for (a) \( T = 0 \) and (b) \( T = 50 \) fs. Dashed orange lines identify the linear absorption peak energies (far right) of the (6,5) \( E_{22} \) and phonon sideband. (c) \( E_{22} \) transient pump probe signal (open circles) decays biexponentially (black line), each exponential component can be assigned to the arrowed spectral features shown in 1a and 1b. \( E_{22} \) pump, \( E_{11} \) probe relaxation kinetics (filled circles) has a slower non-exponential decay from exciton-exciton annihilation contributions [4].

the diagonal \( E_{22} \) and G-band peaks (recovered in an arcsinh scaling to amplify the noise-floor, not shown).

Since the \( E_{22} \) population relaxation is fast and non-radiative, the homogeneous linewidth cannot be estimated by common methods such as single-tube photo emission [4]. 2DFT spectroscopy enables direct extraction of the \( E_{22} \) anti-diagonal (homogeneous) linewidth that is fivefold smaller than the diagonal (homogeneous + inhomogeneous) linewidth. This (6,5) SWNT \( E_{22} \) linewidth estimate agrees with recently reported photon echo measurements providing the \( E_{11} \) absorption lineshape [2,3]. Such similarity in linewidth is expected because the \( E_{22} \) and \( E_{11} \) states should possess near-identical exciton band structures and associated environmental disorders.

Further decongestion of the (6,5) SWNT \( E_{22} \) lineshape is obtained by plotting the corresponding non-rephasing spectra (fig. 12.3a and b). We find that while the diagonal \( E_{22} \) peak decays rapidly, an unexpected feature shifted 50 meV off the diagonal persists for times longer than 500 fs (orange arrow). Subsequent 2DFT measurements also identify a similar feature associated with \( E_{22} \) excitation for the (7,6) tube using 650 nm excitation. To bet-
characterize this new feature, a one-color pump probe measurement (fig. 12.3c, open circles) spectrally tuned to the (6,5) $E_{22}$ resonance was carried out. Fitting using a least-squares deconvolution algorithm (black line), we conclude the decay is biexponential with lifetimes of 120 fs (88%) and 1.3 ps (12%). The timescales and relative amplitudes assign these two exponential components to the arrowed spectral features (fig. 12.3a and b). The 120 fs lifetime corresponds to the expected exponential relaxation of the diagonal $E_{22}$ peak (pink arrow) towards the longer lived $E_{11}$ state (fig. 12.3c, filled circles) \cite{7}. To explain the origin of the 1.3 ps decay and associated spectral feature (orange arrow), comparison of relative peak positions with 2DFT studies on GaAs quantum wells leads us to suspect involvement of multiple excitonic resonances \cite{8}. As further support, we observe strong multiexciton contributions from exciton-exciton annihilation evidenced by an $E_{22}$ pump probe amplitude dependence which increases only with the square root pump intensity. Biexciton contributions in particular, have been calculated with binding energies of $\sim$40 meV for (6,5) SWNTs, but experimental evidence has not yet proven their existence \cite{9}. To investigate such potential peak assignments, future experiments will compare the beat frequency with known Raman modes and exploit the fact that biexciton formation can be suppressed by use of established polarization schemes \cite{8}.

### 12.4 Conclusions

We demonstrate successful application 2DFT spectroscopy to semiconducting SWNTs, and show how it simplifies complex exciton dynamics, such as explaining the origin of the biexponential $E_{22}$ pump probe decay. 2DFT on SWNTs can further provide quantitative information such as the $E_{22}$ homogeneous linewidths and vibrational coupling strengths; information not readily accessible by other spectroscopic means.

### 12.5 References


Appendix A

Determination of Nonlinear Optical Susceptibility for (6,5) SWNTs

A.1 Introduction

Figure A.1. Camera image of 2PE signals (in the $2k_1 - k_3$ direction), and signals emerging in the 5th order directions of $3k_1 - 2k_3$ and $2k_1 - 2k_2 + k_3$, from $E_{11}$ resonant excitation of (6,5) SWNTs embedded in gelatin.

Until recently, SWNT samples were poly-disperse in many tube chiralities and were often highly bundled. As a consequence, the nonlinear properties (i.e. $\chi^{(3)}$) have not been well characterized for highly pure samples of individually separated SWNTs, such as the highly (6,5) enriched nanotubes used for the majority of work presented in this manuscript.[31] In the photograph shown in figure 1.1, resonantly excitation of (6,5) SWNTs produce intense, macroscopic scattered third order polarizations signals, suggestive of an inherently large nonlinearity. The remarkable nonlinear properties of SWNTs were best captured using a high resolution camera near the laser beam focal waist, where distinct signals emerging in the third and fifth-order phased matched direction are apparent (see figure A.1). To roughly
quantify the intrinsic nonlinearity, optical Kerr effect (OKE) measurements are preformed on resonance with the \((6,5)\) \(E_{11}\) optical transition.

\section*{A.2 Hyperpolarizability}

It can be shown that at sufficiently high intensities that both the refractive index \((n)\) and absorption coefficient \((\alpha)\) can be expanded in a power series of the applied intensity.\cite{2}

\begin{align}
    n(I) &= n_o + \gamma I + ... \\
    \alpha(I) &= \alpha_o + \beta^{2\omega} I + ...
\end{align}

(A.1)

The lowest order intensity-dependent terms are the hyperpolarizibility \((\gamma)\) and the two-photon absorption coefficient \((\beta^{2\omega})\) respectively. By measuring the macroscopic observables \(n(I)\) and \(\alpha(I)\), we can relate them back to their corresponding linear and non-linear susceptibilities. To demonstrate this, the polarization expansion for first and third order processes can be truncated to give

\[ P(\omega) = \chi^{(1)} \omega + \chi^{(3)} \omega |E(\omega)|^2 E(\omega) \equiv \chi_{eff} E(\omega). \]

By inserting \(\chi_{eff}\) into the definition of the refractive index \(n\) we obtain the third-order correction given by,

\[ n^2 = 1 + 4\pi \chi_{eff} \Rightarrow (n_o + \gamma |E(\omega)|^2)^2 = 1 + 4\pi \chi^{(1)} + 12\pi \chi^{(3)} |E(\omega)|^2. \]

(A.2)

When the terms up to second order in \(E\) are retained, the first and third order susceptibilities are proportional to the corresponding linear and nonlinear refractive indexes.

\section*{A.3 Optical Kerr Effect (OKE) Measure of Nonlinearity}

Under intense \(E\)-fields many materials exhibit nonlinear phenomena such as high harmonic generation, four wave mixing and self focusing which are all hallmarks of a large intrinsic nonlinear susceptibility.\cite{2} One common approach to quantify material nonlinearity is to perform a \(Z\)-scan. Here a material is slowly translated through the beam waist of a focused laser. As the intensity peaks near the beam waist, induced nonlinear effects from the sample will cause a phase shift in the emerging beam, leading to a small shift in the refractive index. The resulting change in beam direction is measured through the angular shift in beam intensity. Finally the corresponding \(\chi^{(2)}(\omega = \omega - \omega)\) or \(\chi^{(3)}(\omega = \omega + \omega - \omega)\) tensorial components can be calculated from plots of the signal response vs. sample translation position.\cite{3, 2}
Here, the SWNT $\chi^{(3)}$ value is estimated using a four wave-mixing optical kerr experiment by comparison against a reference signal from CS$_2$ where the $\chi^{(3)}$ value has been well characterized. A schematic of the OKE experimental setup used is shown in figure A.2. Full experimental details are available in the literature.[4, 3]

\[ I_{tot} = (E_S + E_{LO})(E_S + E_{LO})^* = C(I_{LO} + I_S + I_b + \text{Re}[E_S E_{LO} + E_S E_{LO}^*]) \]  

(A.3)

where $I_s$ and $E_s$ are proportional to the selected $\chi^{(3)}$ element. To establish this proportionality under the given experiment conditions, a reference sample (commonly CS$_2$) of known nonlinearity $\chi^{(3)}_{\text{ref}}$ is employed. By additionally measuring the first-order order observables ($n_{SWNT}$ and $\alpha$) and $\chi^{(3)}_{\text{ref}}$ for CS$_2$, the third order susceptibility of carbon nanotubes ($\chi^{(3)}_{SWNT}$) was estimated using the relation,

\[ \chi^{(3)}_{SWNT} = \chi^{(3)}_{\text{ref}} \sqrt{\frac{I_{SWNT}}{I_{CS_2}}} \left( \frac{n_{SWNT}}{n_{CS_2}} \right)^2 \left( \frac{l_{CS_2}}{l_S} \right) \left( \frac{\alpha l}{(1 - e^{\alpha l}) e^{-\alpha l/2}} \right) \]

The magnitude of the nonlinear susceptibility $\chi^{(3)}$ was calculated using the linear refraction index ($n_{SWNT} \approx n_{H_2O} = 1.33$ and $n_{CS_2} = 1.66$), the measured linear SWNT $E_{11}$ extinction coefficient ($\alpha = 5.60$ cm$^{-1}$) and a literature CS$_2$ value for $\chi^{(3)}_{CS_2}$ of $5.87 \times 10^{-13}$ esu at 1050 nm. Combining these established values with the experimental measurements for $I_{CS_2}$ and $I_{SWNT}$ shown in figure A.3, we report a $\chi^{(3)}$ value of $1.30 \times 10^{-11}$ esu for (6,5) SWNTs at $\sim$990 nm. Since SWNTs differ in composition between various samples, a more useful
measure of nonlinearity is the hyperpolarizability ($\gamma$) per carbon nanotube which is given by,

$$\gamma_{SWNT} = \frac{\chi^{(3)}}{NL}$$

where $N$ is the number density of carbon atoms in our sample and $L$ is the local field correction factor. The resulting hyperpolarizability is estimated to be $2.4 \times 10^{-26}$ esu per (6,5) carbon nanotube. This value is very similar to other nanostructures such as semiconducting CdSe quantum dots where values of $1.6 \times 10^{-26}$ esu have been reported.\[5\]

![Figure A.3. OKE measurements on CS\textsubscript{2} (top) and resonantly excited (6,5) SWNTs (bottom). Each shows the time-dependent heterodyne leak for positive ($V_+$) and negative ($V_-$) phase, and the resulting pure-heterodyne signal ($I_{SWNT}$) used to estimate $\chi^{(3)}_{SWNT}$.](image)

**A.4 References**


Appendix B

Nanotube Polymer Composites; fabrication and optical properties

B.1 Introduction

In order to be individually separated, SWNTs in solutions must be stabilized by aqueous surfactants. Unfortunately, both surfactant and water absorb highly in these regions of interest. As a consequence, the ability to obtain SWNT samples that have sufficient transparency for spectroscopic study in the mid-IR and terahertz region is challenging, requiring new synthetic preparations. Careful analysis suggest only a SWNT-polyethylene polymer composite the broad spectral window required for such detailed measurements.

B.2 Phase transfer procedure for SWNT-polyethylene polymer films

Special acknowledgment and thanks to Dr. Sergei Bachilo of Rice University for providing the technical guidelines needed for the method developed (below) for the fabrication CoMoCAT synthesized polyethylene composite films.

The starting sample in this procedure is CoMoCAT synthesized SWNTs from SouthWest Nanotechnologies that have been individually dispersed in sodium dodecylbenzene sulfonate (NaDDBS) surfactants. This suspension contains over one critical micelle concentration...
Figure B.1. Aqueous and polymer based (e.g. polymethylmethacrylate, PMMA) composites of individually separated SWNTs all absorb strongly in the mid-IR regions. The SWNT-polyethylene composites fabricated by the method outlined below provides a sufficiently large background in the mid-IR region to preform spectroscopic experiments (see chapters 5 and 6).

for long term stability. Excess surfactants in solution make achieve good phase separation difficult. Excess surfactants in CoMoCAT NaDDBS suspensions are removed, by adding small amount of decalin, followed briefly sonication (with a cell disruptor or cup-horn arrangement). Centrifugation brings the foamy excess surfactant to the surface. Discard and repeat.

Dissolve polyethylene (PE) powder (Sigma Aldrich, spectra grade) in decalin at 70°C. Add 20% by volume CoMoCat suspension and immediately sonicate (using a Misonix cell disrupter, 8W max) until all aqueous components have evaporated and the suspension is clear. Additional decalin may need to added. A vacuum line was operated continuously over the sample (to prevent H₂O vapor from refluxing) and it was thermally insulated to prevent the PE from cooling and precipitating.

Once all aqueous component has been removed the colloidal suspension instantly becomes a transparent gray color, signaling the end of the phase transfer process. The clear solution is transferred to vacuum oven at 80°C, where the solution was cast into various molds and left to dry at elevated temperature overnight.

The procedure developed works on a wide variety of organic solvents (decalins, xylenes and toluene) and can be adapted to make SWNT-polymer composites in a wide variety of media (including polyethylene, polypropylene, polymethylmethacrylate (PMMA) and polystyrene). Original demonstration of a similar technique was carried out by Dr. Sergei Bachilo (Rice University) who fabricated HiPCO PMMA films.
Figure B.2. (a) Linear absorption and fluorescence spectrum of individually separated SWNTs in a polyethylene. (b) Photograph of the SWNT-polyethylene composite films fabricated. (c) Photograph of various SWNT-polymer composites fabricated.

B.3 Characterization in visible and mid-IR regions

To characterize the resulting SWNT-polyethylene composites absorption, fluorescence and pump-probe spectroscopy are used. In figure B.1 a broad spectral window in the mid-infrared region is confirmed. In figure B.2a, relatively strong $E_{11}$ fluorescence upon $E_{22}$ optical excitation, confirm the majority of the (6,5) and (7,5) types tubes remain individually separated after being incorporated in polyethylene.

Various other CoMoCAT SWNT-polymer composites were fabricated including; PMAA, PAA = poly acrylic-acid, CMC = carbocymethylcellulose, PVP = polyvinylpyrrolidone, PE = polyethylene, PVA = poly vinly alcohol polymers (see figure B.2c). The overall $E_{11}$ spectral shifts induced by different local environments are summarized below in table B.1.
Table B.1. Linear absorption and fluorescence peak energies (in nm) for the $E_{11}$ transition, in different surfactant micelles and/or surrounding polymer media. All samples contain approximately one critical micelle surfactant concentration (C.M.C.) unless otherwise noted. *Contributions from (6,5) and (7,5) SWNT peaks could not be deconvoluted.

<table>
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<tr>
<th>Polymer</th>
<th>Surfactant</th>
<th>Original Solvent</th>
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<th>Fluor (7,5)</th>
<th>Abs Max (6,5)</th>
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<td>1000*</td>
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<td>1006*</td>
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<td>1021</td>
<td>1032</td>
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</tr>
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<td>1004</td>
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Electronic two-dimensional Fourier transform (2D-FT) spectroscopy is applied to semi-conducting single-walled carbon nanotubes (SWNTs) and provides a spectral and time-domain map of exciton-phonon assisted excitations. Using 12 fs long pulses, we resolve side-bands above the $E_{22}$ transition that correspond with the $RBM$, $G$, $G'$, $2G$ and other multi-phonon modes. 2D-FT spectral cross-peaks explicitly resolve the population transfer process of excited phonon side-bands that we show are bound to the $E_{22}$ exciton, often through second-order exciton-phonon coupling. All 2D-FT peaks exhibit strong peak amplitude modulation at the $G$-band period (21 fs) which we show originates from an impulsive
stimulated Raman process that populates a ground-state G-band vibrational coherence with a 1.3 ps phonon lifetime.*

* post-submission addendum

C.1 Introduction

The photophysics of semiconducting single-walled carbon nanotubes (SWNTs) are governed by quasi one-dimensional (1D) excitons whose confinement along the circumferential direction produces a sharp set of optical transitions ($E_{11}$, $E_{22}$, etc.) that scale inversely with tube diameter.[1, 2, 3] Each optically bright exciton transition is further composed of a manifold of dark excitonic sub-states and bright phonon assisted transitions. The resulting photoluminescence (PL) spectrum for even a single tube type (shown in figure 1 for the (6, 5) tube) can be remarkably complex containing multi-phonon, multi-exciton and dark-state mediated transitions that are often obscured by strong excitation features.[4, 5] Contributions from such many body effects can produce very rapid relaxation over large energetic separations, making the determination of the overall optical relaxation pathways challenging. To provide the appropriate level of spectral and temporal resolution, we apply broadband 2D Fourier transform (2D-FT) electronic spectroscopy to semiconducting SWNTs.

Steady-state 2D photoluminescence (PL) maps have been the predominant spectroscopic tool used in assigning SWNT chirality and surveying nanotube photophysics.[6, 5] As such, the ability to bring time-resolution to 2D spectral maps should provide new insight. In figure 1a, the PL emitted from the (6, 5) $E_{11}$ state is collected from an aqueous suspension of SWNTs as a 2D-PL map. Along the excitation axis, peaks correspond to the $E_{22}$ transition and a series of weaker $E_{22}$ side-band states.[7] The energetic spacing of the side-band peaks relative to the $E_{22}$ transition match the ground state Raman modes indicated (white dotted lines) and are consistent with optical absorption via phonon side-bands.[8, 9, 4, 10] In particular, the $E_{11}$ and $E_{22}$ exciton states couple with several prominent phonon modes; including the tangential (G-band, 1590 cm$^{-1}$) and radial breathing mode (RBM for (6, 5), 296 cm$^{-1}$) motions along the carbon nanotube circumference (shown in figure 2, top right).[6, 11, 7]

Unlike bulk semiconductors, phonon assisted absorption in SWNTs is greatly restricted by strongly correlated electron-hole ($e-h$) motions created from the powerful Coulombic attraction ($0.4 - 1$ eV >> $k_B T$) caused by strong steric and screening constraints unique to this quasi-1D system.[1, 5] Consequently, each transition must conserve the center of mass momentum of the $e-h$ pair (i.e. $\Delta K_{cm} \cong 0$), resulting in sharp excitonic peaks instead of the broad sloping phonon spectrum common to bulk semiconductors.[7] For purely optical transitions such as $E_{11}$, $E_{22}$, etc., $\Delta K_{cm} \cong 0$ is satisfied by absorption near the $\Gamma$ symmetry point of the SWNT Brillouin zone. The phonon side-band denoted “+G” above the $E_{22}$ state is a one-phonon assisted optical excitation, and as such can involve only zone-center phonons (i.e. $q_{\text{phonon}} \cong 0$) that return the exciton to the band edge.[4] Alternatively, we can satisfy the $\Delta K_{cm} \cong 0$ restriction by the emission of two phonons of opposite momentum.
Figure C.1. (a) 2D-PL map of the $E_{11}$ PL emission from the (6, 5) tube type after excitation of the $E_{22}$ region. The dotted lines indicate $E_{22}$ side-bands peaks that match the labeled Raman modes (white) or strong excitation peaks (orange). (b) Frequency resolved pump-probe spectrum on the same sample reveals an oscillatory component with a $\sim$21 fs period (vertical dashed black lines). Dashed horizontal lines along the induced absorption peaks (dark blue) show correspondence to the $E_{22}$ side-band peaks labeled in (a) when an energetic offset of 1600 cm$^{-1}$ (0.2 eV) is applied.
For example, in figure 1a we observe a distinct +2G phonon side-band peak at 2.57 eV (or at $E_{22} + 2 \times 1590 \text{ cm}^{-1}$).

Two further prominent $E_{22}$ side-band peaks are indicated by orange dotted lines in figure 1a. Possessing energies upshifted by $\sim 1930 \text{ cm}^{-1}$ (labeled $+X$ at 2.4 eV) and $\sim 3800 \text{ cm}^{-1}$ (labeled $+2X$ at 2.63 eV) they deviate significantly in frequency from their neighboring $+G$ and $+2G$ phonon side-band peaks. Proposed excitation mechanisms of the $+X$ side-band requires a two-phonon process that becomes favorable through involvement of two degenerate dark exciton states that possess center of mass momentum near the graphite $K$ and $K'$ symmetry points.[7, 9] Numerous 2D-PL studies have supported the involvement of these “so called” $K$-point states in the formation of phonon side-bands.[4, 7, 12]

Phonon side-band peaks from SWNTs excitation spectra are conventionally assigned by their energetic displacement for the bright exciton. This presents two challenges; (a) the ground state and exciton state Raman frequencies may not be identical,[8, 11, 13] and (b) spectral congestion often results in overlapping contributions. For instance, in figure 1a the strongest side-band peak at 2.4 eV has a bandwidth roughly twice that of neighboring peaks. In this spectrum, we cannot clearly distinguish between one ($+G$) and multi-phonon ($+X$) excitation pathways. Moreover, the energy spacing of both the $+X$ and $+2X$ peaks deviates significantly from known ground state Raman modes. To explain this result second order exciton-phonon coupling mechanisms involving the dark $K$-point exciton state have been invoked.[14, 7, 15]

Ambiguity in peak assignment is further compounded by the intrinsically low PL yield for SWNTs and are insensitive to excitations that decay only through non-radiative pathways. To move beyond these limitations, and resolve complex phonon assisted excitations in SWNTs, 2D-FT electronic spectroscopy offers a distinct advantage. Specifically it provides an excitation ($\Omega_x$) and emission ($\Omega_t$) axis energy map of how an optical excitation distributes among allowed transitions over the course of electronic relaxation. For SWNTs, 2D-FT spectroscopy combines the advantages of dual-axis spectral resolution like in 2D-PL maps with the femtosecond time resolution of pump-probe spectroscopy.

### C.2 Results

Our time-domain analysis of SWNT phonon side-bands begins by reporting a frequency resolved pump-probe spectrum (figure 1b) on the same (6, 5) enriched SWNT sample used for the 2D-PL map. The prominent feature is the population relaxation of the $E_{22}$ peak shown by positive (red) transient bleach decay. Our primary interest is the series of negative (dark blue) induced absorption peaks that appear at time intervals of roughly $\sim 21 \text{ fs}$ in figure 1b. A similar pump-probe spectrum is reported by Luer et al. that resolves two broad induced absorption features adjacent to the $E_{22}$ peak carefully assigned to phonon assisted absorptions.[16] Using novel pulse compression techniques (see experimental), our broadband 12 fs long pulses instead resolve a series of distinct induced absorption peaks. Strikingly, we find good correspondence between the $E_{22}$ side-band peaks from the 2D-PL map in figure
1a, and the spectrum of induced absorption peaks seen in the pump-probe spectrum (figure 1b) when the two spectra are vertically offset by 1600 cm$^{-1}$ ($\sim$0.2 eV). This spectral offset and the 21 fs amplitude modulation observed correspond to the energy and period of the SWNT $G$-band Raman mode.[17] Using 2D-FT electronic spectroscopy we will establish the mechanism relating figures 1a and b, and elucidate the formation and subsequent relaxation of the $E_{22}$ phonon sidebands for (6,5) chiral enriched SWNTs.

![Figure C.2](image_url)

Figure C.2. Real (6, 5) SWNT 2D FT relaxation spectra $S(\Omega_T, \Omega_t, T)$ for (a) $T = 0$ fs, (b) $T = 100$ fs and (c) $T = 500$ fs. (d) $T = 20$ fs (showing both 2.3 and 2.0 eV excitation regions). Population transfer processes are indicated by the dashed arrows that link diagonal population states via their off-diagonal cross-peaks. Prominent phonon side-band peaks are labeled. Upper left inset in 2c shows pulse ordering of three 12 fs pulses plus local oscillator (L.O.).

Our 2D-FT spectroscopy study uses $\sim$ 85 nm FWHM spectral dispersion corrected pulses centered at 2.3 or 2.0 eV to probe the $E_{22}$ manifold of states for the dominant (6, 5) SWNT tube type. Using a nonlinear four-wave mixing process, three temporally delayed pulses excite the $E_{22}$ region producing a stimulated photon echo response that has been previously observed in (6, 5) SWNTs at the $E_{11}$ transition.[18] For 2D-FT spectroscopy, the stimulated photon echo is collected as an interferogram using spectrally resolved heterodyne detection
that preserves all amplitude and phase information. This interferogram is measured as a function of coherence time, $\tau$ (delay between pulses 1 and 2) and waiting times, $T$ (delay between pulses 2 and 3, see figure 2c inset). After a FT along the $\tau$ axis, the obtained real 2D spectra gives a sequence of maps showing differential absorption plotted as a function of excitation ($\Omega_\tau$) and emission ($\Omega_t$) energy at each waiting time ($T$) collected.[19]

Previous SWNT ultrafast time-resolved studies typically use narrow band excitation, and can resolve only the projection of a 2D-FT spectrum onto the $\Omega_t$ axis. In addition to this enhanced spectral resolution, 2D maps produce “off-diagonal” cross-peaks that link two exciton states located along the “diagonal” line defined by $\Omega_\tau = \Omega_t$.[20] Cross-peaks unambiguously show dynamic coupling or active population transfer between populated electronic states of the same tube chirality. We capture the temporal evolution of all peaks and cross-peaks using 12 fs pulses. Such ultrafast precision resolves the exciton-phonon interaction directly as modulations in 2D-FT peak amplitudes that match the vibrational periods of the $G$-band ($T_G=21$ fs) and (6, 5) RBM ($T_{RBM}=110$ fs).

Representative real value 2D-FT spectra ($S(\Omega_\tau, \Omega_t, T)$) are plotted in figure 2 for $T=0, 100, 500$ and 20 fs respectively. Positive (red) features correspond to transient bleaching or stimulated emission, while negative (dark blue) features are induced absorptions. The dominant 2D-FT peak at $\Omega_\tau = \Omega_t=2.16$ eV in figure 2 is a strong transient bleach signal assigned to population relaxation from the $E_{22}$ exciton state to the $E_{11}$ state and other low lying states.[16, 21, 22] In figure 3a, the relaxation time ($T_{E_{22}}$) is obtained from both broadband (green circles, $\tau_{\text{pulse}}=12$ fs), and narrow band (open orange circles, $\tau_{\text{pulse}}=55$ fs) measurements that are resonant with the (6, 5) $E_{22}$ transition. Using a least squares deconvolution algorithm, the $E_{22}$ bleach decays biexponentially (black line fit), giving a 120 fs (88%) $E_{22}$ lifetime followed by a slower 1.25 ps (12%) component. While $E_{22}$ relaxation times have been reported to be as short as 40 fs,[23, 24] our aqueous (6,5) sample gives a slightly longer decay ($\sim 120$ fs) in accord with recent pump-probe simulations on this sample.[22]

Along the diagonal line in figures 2a and d we can identify the positive (6, 5) SWNT $E_{22}$ peak at $\Omega_\tau = \Omega_t=2.16$ eV, and two positive side-band peaks labeled $+G$ and $+X$ located $\sim 1590$ cm$^{-1}$ and $\sim 1930$ cm$^{-1}$ above $E_{22}$. These diagonal peaks match the steady-state linear absorption spectrum shown to the right of figure 2b. In the $T=0$ spectra, we believe the negative (purple) diagonal peak is largely an artifact of non-resonant contributions that can occur within the pulse overlap regions. Off-diagonal, cross-peaks show population transfer from the diagonal side-band peaks to the $E_{22}$ exciton state (e.g see figure 2d).

For waiting times ($T$) far outside the pulse overlap region (e.g. figures 2b-c) the positive diagonal side-band peaks seen for $T=0$ and 20 fs are replaced by negative induced absorptions (dark blue). A broad multi-peaked induced absorption feature covering the diagonal region from $\sim 2.2$ to 2.3 eV is also resolved. Similar to the pump-probe spectrum in figure 1b, we find the 2D-FT induced absorption peaks along the diagonal line also match the 2D-PL excitation spectrum when a spectral offset of $\sim 1600$ cm$^{-1}$ is applied. This persistent offset suggests the negative (dark blue) peaks arise from an induced absorption from the ground state $G$-band mode as depicted in figure 3b.
Figure C.3. (a) Pump-probe time trace of kinetic relaxation of the (6, 5) $E_{22}$ peak fitted to biexponential decay (black line). (b) Energy level diagram depicting induced absorption pathways from the ground-state $G$ vibrational coherence populated by an impulsive stimulated Raman process. Excitation to the phonon side-band states (dashed lines) is accompanied by impulsive phonon emission (wavy lines) and transfer to the $E_{22}$ state.

To show the time evolution of 2D-FT cross-peaks alongside the $E_{22}$ diagonal peaks, we take vertical (emission axis, figures 4a-b) and horizontal (excitation axis, figures 4c-d) cuts through the real 2D-FT spectra, and plot these cuts as a function of $T$. Vertical dashed lines placed at 21 fs ($T_G$) intervals highlight strong amplitude modulations, whose period closely corresponds to the $G$-band mode. A secondary amplitude (every $\sim 110$ fs) and frequency modulation ($\pm 280$ cm$^{-1}$) are highlighted by dotted sinusoidal lines in figures 4a-b, and closely correspond to the (6, 5) $RBM$ mode of 296 cm$^{-1}$.[17] Such oscillatory behavior indicates an impulsive wave-packet excitation with an ultrashort pulse creating a vibrational superposition between the $E_{22}$ and a RBM phonon side-band.[25, 26, 27]

Below $E_{22}$, we find a symmetric RBM oscillation is prominent when we instead plot just the non-rephasing ($NR$) component of the real 2D-FT spectra (figure 4b). The $NR$ spectrum uses data acquired from $\tau = -200$ to 0 fs only. This effectively swaps the pulse ordering shown in figure 2c($inset$) and provides an enhanced resolution of antidiagonal (inhomogeneous) spectral broadening contributions.[20, 28] The resulting $NR$ spectral line cuts shows a second $RBM$ oscillation one $\Omega_{RBM}$ below the $E_{22}$ transition. We also detect signatures of a $RBM$ overtone mode at $\Omega_i = 2.21$ eV or $E_{22} + 2 \times RBM$ in figures 4a and b. The guiding sinusoidal lines further show a relative $\pi$ phase shift in the vibrational coherence of the $\pm RBM$ phonon side-bands. A similar $E_{22}$ $RBM$ $\pi$ phase shift has been previously extracted from optical pump-probe spectra.[16]

Figures 4c-d and 5a highlight the time-dependent behavior of select 2D-FT cross-peaks.
Figure C.4.  (a) Time($T$) evolution of emission axis (vertical) line-cuts taken from the 2D-FT relaxation spectra at $\Omega_T=2.17$ eV. A sinusoidal oscillation one $\Omega_{RBM}$ frequency above $E_{22}$ is indicated. (b) Line-cuts for the corresponding $NR$ spectra at $\Omega_T=2.25$ eV show an oscillatory component located one $\Omega_{RBM}$ frequency below $E_{22}$. (c) Time-evolution of (horizontal) line-cuts along the excitation axis for $\Omega_t=2.16$ eV. (d) Corresponding $NR$ spectrum. The labeled $+X \rightarrow E_{22}$ feature is a cross-peak showing the population transfer from a $+X$ (or $+2X$) phonon side-band to $E_{22}$. Dotted lines guide the eye to frequency modulations at the $RBM$ ($\pm 0.035$ eV) and amplitude modulations at $G$-band period (21 fs).
We plot the evolution of the $+X \rightarrow E_{22}$ cross-peak alongside the diagonal $E_{22}$ peak through cuts taken along the (horizontal) excitation axis at $\Omega_t = 2.16$ eV. While the cross-peak feature shown in figure 4c appears weak, we find it is markedly enhanced when the $NR (\tau < 0$, figure 4d) and rephasing ($R, \tau > 0$, figure 5a) contributions of total real 2D-FT signal are plotted separately.

C.3 Discussion

All resolvable 2D-FT peaks exhibit persistent amplitude modulations at 21 fs ($T_G$) for the first 200 fs (see figures 4 and 5), after which the time points were too sparsely sampled. Such an amplitude modulation pattern is consistent with a vibrationally coherent wavepacket on the ground state created by an impulsive stimulated Raman process involving the $G$-band (see figure 3b).[25] In figure 5b, we plot the peak amplitude modulations of the $R$ and $NR$ excitation pathways and show they are anti-correlated outside the pulse overlap region. Existing time resolved measurements can resolve only the summation of $R + NR$ contributions. Figure 5b clearly illustrates how the separation of the two excitation pathways provide an enhanced resolution to phonon-mediated excitations in SWNT; this enables identification of exciton side-bands peaks that arise from second-order exciton-phonon coupling.

Spectral cross-peaks explicitly show impulsive population transfer from phonon side-bands to the singlet $E_{22}$ exciton. As such, cross-peaks resolved in figures 2, 4 and 5 imply the dominant $(6, 5)$ SWNT phonon side-bands (e.g. $+X, +2X$) are bound $E_{22}$ exciton state. Comparing figures 4d and 5a, we further see that both diagonal and cross peaks exhibit a secondary frequency oscillation along the $\Omega_t$ axis at $\sim 290$ cm$^{-1}$ ($\Omega_{RBM}$) over a $\sim 110$ fs ($T_{RBM}$) period. In figure 5b, this modulation pattern is numerically extracted by plotting the maximum real 2DFT amplitudes of the $E_{22}$ peak and it strongest cross-peak. Fitting using singular value decomposition (solid lines) we obtain frequencies (and % amplitudes) that closely match the phonon modes indicated at $1580 \pm 22$ cm$^{-1}$ ($G$, 63%), $290 \pm 44$ cm$^{-1}$ ($RBM$, 25%) and $1176 \pm 30$ cm$^{-1}$ (12%). We find the $+X \rightarrow E_{22}$ cross-peak is modulated along the excitation axis at both the $G$ band and $RBM$ frequencies showing that multiple phonon modes are used to satisfy the $\Delta K_{cm} \approx 0$ restriction for exciton formation.

2D-FT spectroscopy on semiconducting SWNTs provides a time-domain mapping of excitation and relaxation pathways involving the phonon side-bands of the $(6, 5) E_{22}$ exciton. We find the $E_{22}$ side-band peaks seen in our pump-probe, 2D-FT and 2D-PL map all show good agreement after an offset matching the $G$-band frequency is applied (figures 1a, 1b and 2). Our strongest side-band peaks denoted $+X$ and $+2X$, deviate from the expected $+G$ and $+2G$ phonon-side bands by 23 and 45 meV respectively. Such deviations have been previously seen in steady-state measurements [7, 12, 14] and explained through emission of two phonons which satisfy $\Delta K_{cm} \approx 0$ rule for bright exciton creation (e.g. the two wavy arrows in figure 3b). This second-order exciton-phonon coupling process is enhanced by strong phonon scattering processes expected at the $K$-point.[8, 4, 7] Our time-resolved results support that multi-phonon assisted excitations can be stronger than other one-phonon
Figure C.5.  
(a) A line-cut along the excitation axis of 2D-FT rephasing spectra at $\Omega_t=2.19$ eV($E_{22}$ peak) shows the time evolution of the $E_{22}$ peak and its corresponding $+X \rightarrow E_{22}$ cross-peak. (b) The maximum 2D-FT peak amplitude in region of the $E_{22}$ transition and cross-peak is plotted as function of waiting time. The $R$ and $NR$ contributions are anti-correlated outside the pulse overlap region. (c) Feynman pathways for a stimulated Raman process that creates a $G$-band vibrational coherence that give non-equivalent induced absorption pathways for the $R$ (black) and $NR$ (orange) excitation pathways.
processes observed (e.g. $+G$ and $+G'$). However, we can only infer the potential involvement of the $K$-point state by noting the energetic displacement of the $+X$ and $+2X$ peaks. This would place the dark $K$-point state 23 meV above $E_{22}$. Previous values for the $E_{11} K$-point state have been reported, ranging from 12 to 50 meV.[7, 29]

The $+X$ (and $+2X$) $\rightarrow E_{22}$ cross peak decays with a lifetime of 1.3 ps, similar to the recently reported $1.1\pm0.2$ ps ground state $G$ phonon lifetime.[27, 30] The cross-peak lifetime and its strong 21 fs beat period ($T_G$) further coincide with the mechanism outlined in figure 3b whereby the induced absorption peaks in figure 1b and 2 originate from a vibrational coherence with ground state $G$-band produced by a stimulated Raman process. This impulsive stimulated Raman excitation mechanism is made explicit in figure 5c with representative double-sided Feynman diagrams for the $R$ and $NR$ 2D-FT spectral contributions. These diagrams depict the time evolution of the density matrix for a four-wave mixing process involving a stimulated Raman process and a subsequent induced absorption to either a $+X$ (or $+2X$) phonon-side band state. The first two arrowed interactions ($\pm\omega_{E_{22}}$) impulsively stimulate a vibrational superposition (i.e. $|g\rangle\langle g+G|$) that beats every 21 fs ($T_G$ period). After the waiting time $T$, the third pulse produces the induced absorption peaks seen throughout our 2D-FT spectra.

The Feynman diagram description of the stimulated Raman process is also helpful to explain why the $R$ and $NR$ pathways result in a clear $\pi$ phase shift in peak amplitude (figures 4d and 5a-b). The third pulse interaction (see figure 5c) only excites see population in $G$ band state in the $NR$ pathway. In the $R$ pathway, the corresponding interaction occurs with ground state. However, as time ($T$) evolves the $G$-band vibrational superposition beats. Every period $T = nT_G/2$, the $G$ population will effectively swap whether the indicated induced absorption occurs in the $R$ or $NR$ 2D-FT pathway. Consequently, we observe the peak and cross-peak modulations in figure 5b are anti-correlated (or $\pi$ phase shifted) for both $G$-band and $RBM$ periods.

### C.4 Conclusions

We demonstrate the application of 2D-FT electronic spectroscopy to (6, 5) enriched SWNTs and obtain a time-dependent spectral map showing exciton-phonon assisted processes. Broadband excitation with 12 fs pulses populates $G$-band mode via impulsive stimulated Raman emission from the $E_{22}$ phonon side-bands. A resulting ground state vibrational coherence is observed through induced absorption peaks that match the 2D-PL spectrum of phonon side-bands, but are downshifted by the $G$-band frequency. We find strong modulations in peak amplitude at the 21 fs $G$-band period originate from the stimulated Raman process described. Through induced absorption from the ground state $G$-band vibrational coherence, we continue to re-populate the $E_{22}$ state over the 1.3 ps $G$-band lifetime.

2D-FT spectroscopy on SWNTs uniquely enables the resolution of cross-peaks. Cross-peaks clearly show population transfer $+X \rightarrow E_{22}$ and $+2X \rightarrow E_{22}$ via phonon emission, and demonstrate that such phonon side-band states are indeed bound to the singlet $E_{22}$ exciton.
of the (6, 5) tube. Examining the spectral cross peak modulate at both the amplitude and frequency of the G-band and RBM, we show the strongest $E_{22}$ phonon side-bands involve multiple-phonon emission. We agree with previous predictions that such second-order exciton-phonon coupling process could be made favorable from enhanced coupling involving a $K$-point state[4, 14] that in our case would lie $\sim 23$ meV above the $E_{22}$ transition. Similar population exchange processes are also expected for the $E_{11}$ transition, and future 2D-FT maps of the $E_{11}$ manifold of states could provide a complete dynamic map of the still nebulous non-radiative decay pathways for semiconducting SWNTs.

### C.5 Experimental Methods

The SWNT sample was synthesized through the cobalt molybdenum catalyst (CoMo-CAT) technique, dispersed in surfactants and then greatly enriched in the (6, 5) semiconducting tube type through a density-gradient ultracentrifugation process.[31, 32] The resulting aqueous suspension of individually separated SWNTs, enabled resonant excitation of predominately the (6,5) tube type. In order to suppress laser light scattering, a thin 100 $\mu$m pathlength quartz cell was used with a sample optical density of 0.12 at 571 nm. PL absorption measurements were taken on aJobin-Yvon Fluorolog using 150 W xenon arc lamp excitation and a Li-N$_2$ cooled CCD camera and InGaAs photodiode. Measurements were conducted under ambient conditions since the absorption lineshape is dominated by inhomogeneous broadening[33], meaning low temperature measurements only modestly reduce spectral congestion.

Broadband (80 nm FWHM) pulses centered at 2.3 or 2.0 eV were generated from a non-collinear optical parametric amplifier (NOPA) pumped by home-built 3.4 kHz Ti:sapphire/regenerative amplifier system. The 2D-FT technique used is described in detail elsewhere.[19, 20, 34] Briefly, the beam was split into two paths and temporally offset with a mechanical delay stage (Newport, UTS series) to control the waiting time ($T$). A diffractive optic further splits each path to produce the requisite phase-locked pulse pairs (see figure 2c, inset). The coherence time ($\tau$) delay was introduced through fused silica glass wedges on delay stages (Nanomovers, Melles-Girot), that were temporally calibrated using spectral interferometry. The laser pulses were compressed to 12 fs with a prism pair to correct for the quadratic-order spectral phase and spatial light-modulator (SLM) line to correct for high-order spectral phase contributions. Transient-grating frequency resolved optical gating (TG-FROG) was preformed on fused silica at the sample position to extract the phase necessary to create a compressed, virtually unchirped pulse.

The pulse-pairs were focused on the SWNT sample in a box geometry with a total incident fluence of $2.3 \times 10^{14}$ and $3.4 \times 10^{14}$ photons/cm$^2$ for the 2.0 and 2.3 eV centered experiments respectively. A heterodyne detection scheme on CCD camera (Princeton Instruments) was accomplished by passing the fourth L.O. pulse collinear with the emitted signal ($k_s$). This enabled us to spectrally resolve the SWNT signal collected in the $k_s = -k_1 + k_2 + k_3$ phase matched direction in both amplitude and phase. The data were collected at waiting times.
from 0 to 5000 fs. For each waiting time, the coherence time was scanned from -200 to 200 fs at 5 fs increments. A Fourier transform over the $\tau$ axis generates the absorption energy axis ($\Omega_\tau$). Spectrally resolved pump-probe taken immediately after was used to phase the absolute values 2D spectra obtained. These spectra are plotted in figure 1b.

To exclude potential contributions from local heating and sample degradation the 2D-FT experiment were repeated by flowing the aqueous tube suspension or using a thin SWNT-polymer composite of polyvinylpyrrolidone(PVP) polymer. While the signal to noise deteriorated from scattering, the same 2D-FT features were still prominent. Similar 2D-FT spectral features were observed at all excitation fluences examined (0.6 - 6.2 $\times 10^{14}$ photons/cm$^2$).

C.6 References


